



Design Example Report

| | |
|------------------------|--|
| Title | <i>35 W High Power Factor Isolated Flyback with Switched Valley Fill PFC Power Supply Using LYTSwitch™-6 LYT6068C</i> |
| Specification | 140 VAC – 320 VAC Input; 12 V, 2.92 A Output |
| Application | Emergency Light with Battery Charging |
| Author | Applications Engineering Department |
| Document Number | DER-637 |
| Date | April 23, 2018 |
| Revision | 1.4 |

Summary and Features

- Accurate constant voltage regulation
- High power factor, >0.9 at 230 V and 277 V inputs
- Fast transient load response
- Highly energy efficient, >88 % at 230 V and 277 V inputs
- Integrated protection and reliability features
 - Output short-circuit protection
 - Line and output OVP
 - Thermal foldback and over-temperature shutdown with hysteretic automatic power recovery
- No damage during line brown-out or brown-in conditions
- Meets IEC 2.5 kV ring wave, 1 kV differential surge
- Meets EN55015 conducted EMI

PATENT INFORMATION

The products and applications illustrated herein (including transformer construction and circuits external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com. Power Integrations grants its customers a license under certain patent rights as set forth at <http://www.powerint.com/ip.htm>.

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Important Note: Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.

1 Introduction

This engineering report describes a constant voltage (CV) output 35 W isolated flyback power supply with a single-stage power factor correction circuit for LED lighting application. The power supply is designed to provide a 12 V constant voltage across 0 A to 2.92 A output current load. It's also capable of providing 2.98 A constant current output for LED lighting applications. The board is optimized to operate from an input voltage range of 140 VAC to 320 VAC.

The LYTSwitch-6 IC combines primary, secondary and feedback circuits in a single surface mounted off-line flyback switcher IC. It incorporates the primary FET, the primary-side controller and a secondary-side synchronous rectification controller. The device also includes an innovative new technology, FluxLink™, which safely bridges the isolation barrier and eliminates the need for an optocoupler.

A switched valley-fill PFC circuit is added to meet the high PF requirement in lighting applications. The energy stored across the PFC inductor is delivered to the load via direct energy transfer reducing the power loss.

DER-637, using a LYTSwitch-6 IC, offers an accurate, fast transient response, constant voltage supply with a high power factor throughout the input range. The key design goals were high efficiency and high power factor throughout the input voltage range.

This document contains the power supply specification, schematic diagram, bill of materials, transformer documentation, printed circuit board layout, and performance data.

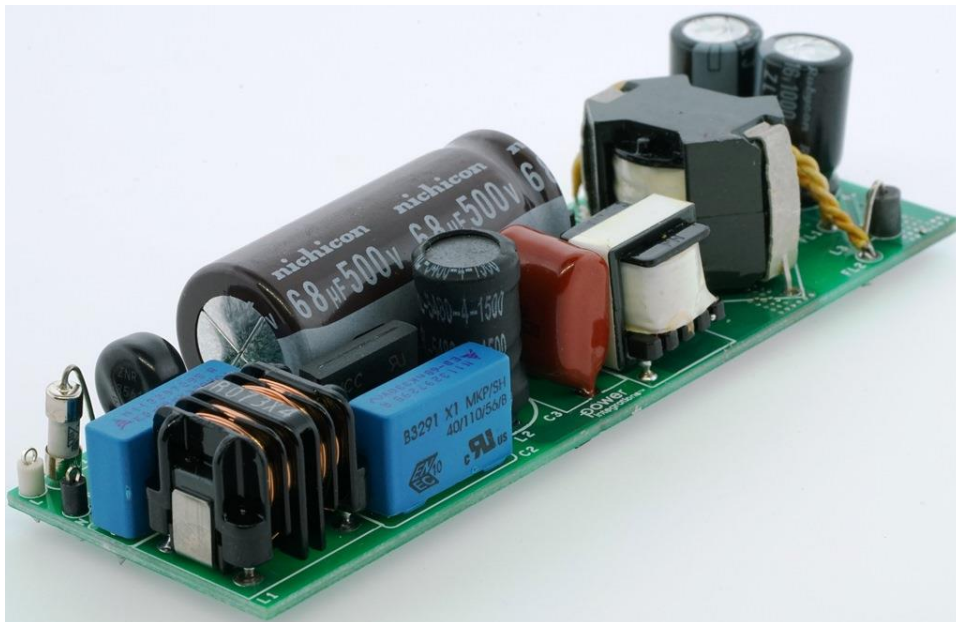


Figure 1 – Populated Circuit Board.

2 Power Supply Specification

The table below represents the minimum acceptable performance of the design. Actual performance is listed in the results section.

| Description | Symbol | Min | Typ | Max | Units | Comment |
|---|-------------------------------------|-----|----------------------------------|------|-------------|---|
| Input Voltage Frequency | V_{IN} f_{LINE} | 140 | 230/277 50 | 320 | Vac/Hz | 2 Wire – no P.E. |
| Output Output Voltage Output Current Total Output Power Continuous Output Power | V_{OUT} I_{OUT} P_{OUT} | 0 | 12 | 2.92 | V A W | CC Threshold: 2.98 A. |
| Efficiency Full Load Average Efficiency 25%, 50%, 75%, and 100% Load | η | | 88 | | % % | At 230 VAC / 50 Hz and 277 VAC / 50 Hz. 25 °C Ambient Temperature. Meets DOE Level VI. |
| Environmental Conducted EMI Safety Ring Wave (100 kHz) Differential Mode (L1-L2) | | | | | | |
| | | | CISPR 15B / EN55015B Isolated | | | |
| | | | 2.5 | | kV | |
| | | | 1 | | kV | |
| Power Factor | | | 0.9 | | | Measured at 230 VAC / 50 Hz and 277 VAC / 50 Hz. |
| Ambient Temperature | T_{AMB} | | | 60 | °C | Free Air Convection, Sea Level. |

4 Circuit Description

The LYTSwitch-6 device (LYT6068C) incorporates the primary MOSFET, the primary-side controller and a secondary-side synchronous rectification controller in a single inSOP-24D package. This IC also includes an innovative new technology, FluxLink™, which safely bridges the isolation barrier and eliminates the need for an optocoupler. The LYTSwitch-6 IC is configured to drive a 35 W flyback power supply with a switched valley fill PFC providing a high power factor 12 V constant voltage supply throughout the input range of 140 VAC to 320 VAC.

4.1 *Input EMI Filter and Rectifier*

The input fuse F1 provides safety protection from component failures. Varistor RV1 acts as a voltage clamp that limits the voltage spike on the primary during line transient voltage surge events. A 350 V rated part was selected, being slightly above the maximum specified operating input voltage (320 V). The AC input voltage is full wave rectified by BR1 to achieve good power factor and low THD.

The bulk capacitor (C4) provides input line ripple voltage filtering for a stable flyback DC supply voltage and helps reduce EMI noise. It also stores excess energy generated by the PFC during the power switch turn off time.

Capacitor C1, L1, C2, L2, and C3 forms a 2 stage LC EMI filter to suppress differential mode noise caused by the PFC and flyback switching action. Common mode noise is suppressed by Y capacitor C8.

Rectifier diode (D2) provides a bypass charging current to the bulk capacitor (C4) from the input rectified voltage. Diode D2 also serves as a blocking diode during the power MOSFET turn OFF to isolate the flyback DC supply from the PFC supply maintaining the functionality of the added PFC circuit.

4.2 *LYTSwitch-6 Primary Side Control*

The isolated flyback power supply is controlled by the LYTSwitch-6 IC LYT6068C. One side of the transformer (T1) primary is connected to the positive output terminal of the bulk capacitor (C4) while the other side is connected to the drain of the integrated 650 V power MOSFET inside the LYTSwitch-6 IC (U1). A low cost RCDZ snubber clamp formed by D4, R2, R15, C7, R3, and VR1 limits the peak Drain voltage spike due to the effects of transformer leakage inductance.

The VOLTAGE MONITOR (V) pin of the LYTSwitch-6 IC is connected to the positive of the bulk capacitor (C4) to provide input voltage information. The voltage across the bulk capacitor (C4) is sensed and converted into current through V pin resistors R4, R12, and R5 to provide detection of overvoltage. The I_{OV} determines the input overvoltage threshold.



During the initial power-up, the internal high-voltage current source charges the BPP pin capacitor (C6). Before switching, the primary will pause for around 80 ms to listen for secondary request signals. When the primary starts switching after initial power-up, it will initially assume control and require a handshake to pass the control to the secondary side. The LYTSwitch-6 IC is at normal operation when switching with the secondary in control. During normal operation the primary-side block is powered by the auxiliary winding of the transformer. The output of this is configured as a flyback winding, rectified and filtered (D3 and C5) and fed to the BPP pin via a current limiting resistor R1. The value of the BPP pin capacitor C6 sets the current limit of the LYTSwitch-6 IC. The 0.47 μF capacitance value for C6 corresponds to STANDARD current limit mode.

The thermal shutdown circuitry senses the primary MOSFET die temperature. The threshold (T_{SD}) is typically set to 142 $^{\circ}\text{C}$ with 70 $^{\circ}\text{C}$ hysteresis $T_{SD(H)}$. When the die temperature rises above this threshold the power MOSFET is disabled and remains disabled until the die temperature falls by $T_{SD(H)}$ at which point it is re-enabled. A large hysteresis of 70 $^{\circ}\text{C}$ is provided to prevent over-heating of the PCB due to continuous fault condition.

4.3 ***LYTSwitch-6 Secondary-Side Control***

The secondary-side control of the LYTSwitch-6 IC provides output voltage and output current sensing. The secondary of the transformer is rectified by a synchronous rectifier MOSFET (Q1), driven by the Synchronous Rectifier Drive (SR) pin of LYTSwitch-6 IC. This is then filtered by the output capacitors C10 and C16. Adding an RC snubber (R7 and C9) across the SR FET reduces voltage stress across its drain-to-source. An LC filter (L3 and C17) in series with the secondary winding of the transformer helps to further reduce the voltage spike across the drain-to-source of the SR FET, if a simple RC snubber is not enough, with little to no effect on system efficiency. Component L3 is a single-turn ferrite bead that, in conjunction with a parallel ceramic capacitor C17, suppresses high frequency spike present on the secondary of the transformer especially during start-up.

The secondary side of the IC is self-powered from either the secondary bias winding forward voltage or the 12 V regulated output. During normal operation the regulated output voltage powers the device, through the OUTPUT VOLTAGE (VOU) pin. During start-up operation, when the output voltage is still building-up, the device will power itself from the secondary winding directly. During the ON-time of the primary-side MOSFET the forward voltage that appears across the secondary winding is used to charge the (BPS) capacitor C12 via the FORWARD (FWD) pin through resistor R6 and an internal regulator.

During constant voltage mode operation, output voltage regulation is achieved through sensing the output voltage via divider resistors R8 and R9. The voltage across R9 is fed into the FB pin with an internal reference voltage threshold of 1.265 V. Filter capacitor

C11 is added across R9 to eliminate unwanted noise that might trigger the OVP function or increase the output ripple voltage. The feedforward network composed of C14 and R14 across R8 helps reduce output voltage ripple and achieve better output voltage regulation. Capacitor C13 filters out any unwanted noise that may enter the VOUT pin, and also helps reduce output voltage ripple. During constant current operation, the output current is set by the sense resistor (R18) across the IS pin and the GND pin. The internal reference threshold for the IS pin is 35.8 mV. Diode D6 in parallel with the current sense resistor serves as protection during output short-circuit conditions.

The thermal foldback is activated when the secondary controller die temperature reaches 124 °C, the output power is reduced by reducing the constant current reference threshold.

4.4 ***PFC Circuit Operation***

Without the added PFC circuit, the power factor of the flyback power supply is normally around 0.5 to 0.6 at full load condition. The input of the flyback power supply circuit usually consists of the full wave bridge rectifier (BR1) followed by a storage bulk capacitor (C4) capable of maintaining a voltage approximately equal to the peak voltage of the input sine wave until the next peak comes to recharge the capacitor. The input charging pulse current must be high enough to sustain the load until the next peak. This means that the charging pulse current is around 5-10 times higher than the average current with a high phase angle difference from the voltage waveform; hence, the expected PF from this standard configuration is low and THD is high.

The added PFC circuit is called "Switched Valley-Fill Single Stage PFC" (SVF S²PFC). It is comprised of an inductor (T2) and diodes (D1 and D5) connected directly to the DRAIN pin of the LYTSwitch-6 IC. The LYTSwitch-6 flyback switching action is able to draw a high frequency pulse current from the full wave rectified input. This will reduce the rms input current and the phase angle difference from the input line voltage will be lower; hence, power factor will increase and will improve THD.

The PFC inductor T2 operates in DCM mode. During the LYTSwitch-6 turn ON time, current drawn from the rectified input ramps through the PFC inductor (T2) storing energy. The stored energy on T2 is then delivered to the load via direct energy transfer between the primary and secondary winding of the flyback transformer T1. Any excess energy from the PFC inductor that is not delivered to the load is being stored to the bulk capacitor. During no-load and light load conditions (i.e, less than 250 mA output load current), the secondary requires less energy from the primary; therefore, more excess energy from the PFC inductor is stored on the bulk capacitor causing the voltage to rise gradually. The expected voltage stress across the bulk capacitor C4 will be higher than the peak input voltage. To limit the bulk voltage below the bulk capacitor rating, especially at high input voltage, a Zener-resistor clamp circuit is used (VR2, VR3, and



R19). The Zener voltage is set at 480 V; when the bulk voltage goes beyond this, the Zener diodes conduct and bleed current from the bulk capacitor through resistor R19. This prevents the bulk capacitor voltage to rise above 480 V. The power dissipation of this Zener-resistor clamp should be considered at the worst-case creeping of the bulk voltage – happens usually at light load condition. Diodes D1 and D5 are connected in series to withstand voltage stress caused by the resonance ringing during the FET turn off. The variability of the PFC inductor peak current will be compensated by LYTSwitch-6 primary and secondary side control maintaining the voltage regulation at all conditions.

A low cost RCD clamp circuit across the Drain-to-Source pins of the LYTSwitch-6 IC will also limit the bulk voltage from rising at light load, but the additional dissipation will cause a decrease in overall system efficiency and increase no-load input power consumption.

5 PCB Layout

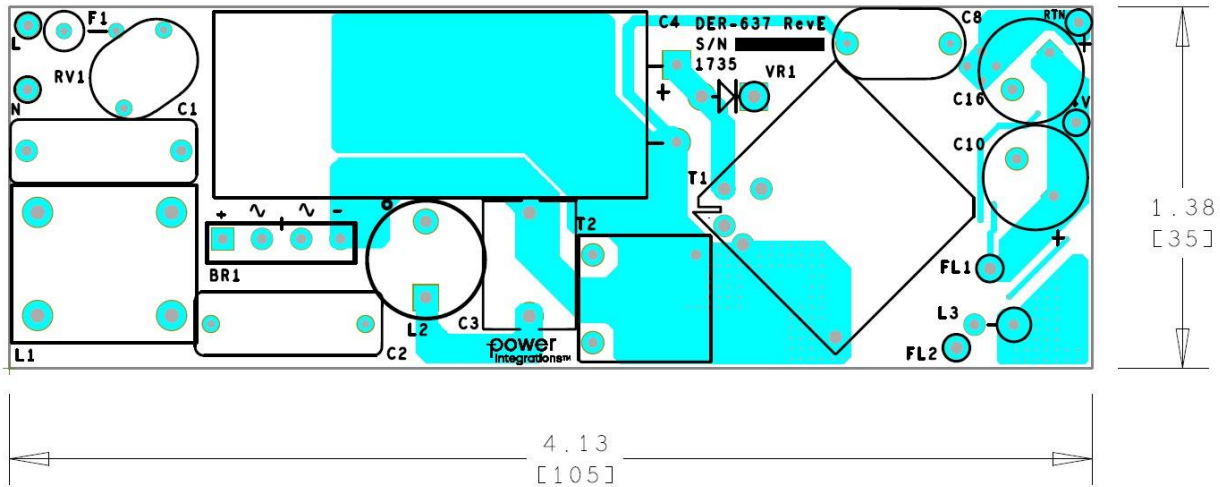


Figure 5 – Top Side.

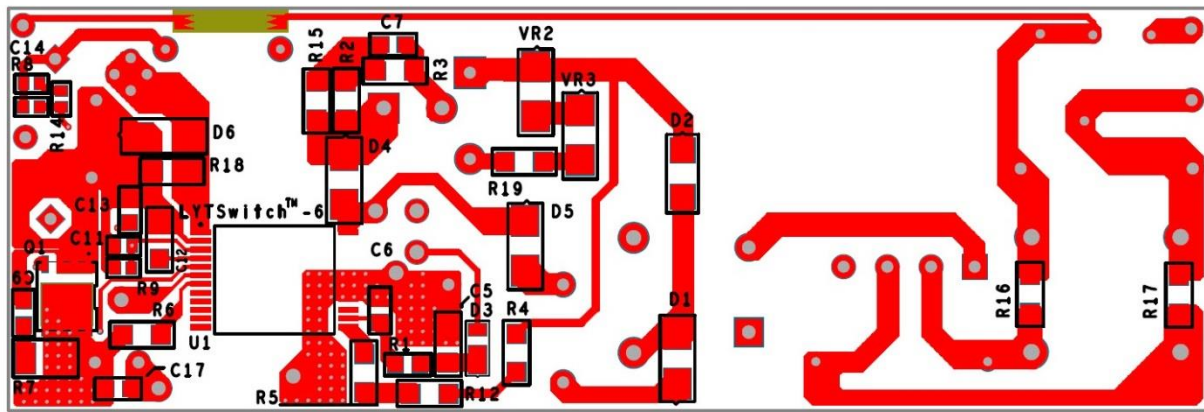


Figure 6 – Bottom Side.

6 Bill of Materials

6.1 Main Bill of Material

| Item | Qty | Ref Des | Description | Mfg Part Number | Mfg |
|------|-----|---------|--|---------------------|--------------------|
| 1 | 1 | BR1 | Bridge Rectifier, 1000 V, 4 A, 4-ESIP, D3K, -55°C ~ 150 °C (TJ), Vf=1 V @ 7.5 A | UD4KB100-BP | Micro Commercial |
| 2 | 1 | C1 | 68 nF, ±10%, 330 VAC, 760 VDC, X1 Safety Rated, Metallized Polypropylene Film, RAD | B32912A3683K000 | Epcos |
| 3 | 1 | C2 | 68 nF, ±10%, 330 VAC, 760 VDC, X1 Safety Rated, Metallized Polypropylene Film, RAD | B32912A3683K000 | Epcos |
| 4 | 1 | C3 | 220 nF, ±5%, 630 VDC, 250 VAC, Film, 12.5 mm L x 15.8 mm H x 9.0 mm T, 10 mm LS | MEXPF3220JJ | Duratech |
| 5 | 1 | C4 | 68 uF, 500 V, Electrolytic, (18 x 41.5), LS 0.295" (7.50 mm) | UCY2H680MHD | Nichicon |
| 6 | 1 | C5 | 22 µF, 35 V, Ceramic, X5R, 1206 | C3216X5R1V226M160AC | TDK |
| 7 | 1 | C6 | 470 nF, 50 V, Ceramic, X7R, 0805 | GRM21BR71H474KA88L | Murata |
| 8 | 1 | C7 | 3.3 nF, 200 V, Ceramic, X7R, 0805 | 08052C332KAT2A | AVX |
| 9 | 1 | C8 | CAP Ceramic 2.2nF 500 VAC | VY1222M47Y5UQ63V0 | Vishay |
| 10 | 1 | C9 | 470 pF, 200 V, Ceramic, X7R, 0805 | C0805C471K2RACTU | Kemet |
| 11 | 1 | C10 | 1000 µF, 16 V, Electrolytic, Gen. Purpose, (10 x 17.5) | 16ZLJ1000M10X16 | Rubycon |
| 12 | 1 | C11 | 330 pF 50 V, Ceramic, X7R, 0603 | CC0603KRX7R9BB331 | Yageo |
| 13 | 1 | C12 | 2.2 µF, 25 V, Ceramic, X7R, 1206 | TMK316B7225KL-T | Taiyo Yuden |
| 14 | 1 | C13 | 10 µF, ±10%, 16V, X7R, Ceramic Capacitor, -55°C ~ 125°C, Surface Mount, MLCC 0805 | CL21B106KOQNNNE | Samsung |
| 15 | 1 | C14 | 100 nF 50 V, Ceramic, X7R, 0603 | C1608X7R1H104K | TDK |
| 16 | 1 | C16 | 1000 µF, 16 V, Electrolytic, Gen. Purpose, (10 x 17.5) | 16ZLJ1000M10X16 | Rubycon |
| 17 | 1 | C17 | 3.3 nF, 200 V, Ceramic, X7R, 0805 | 08052C332KAT2A | AVX |
| 18 | 1 | D1 | 600 V, 2 A, Superfast, 35 ns, DO-214AC, SMA | ES2J-LTP | Micro Commercial |
| 19 | 1 | D2 | 600 V, 1 A, Standard Recovery, SMA | S1J-13-F | Diodes, Inc. |
| 20 | 1 | D3 | Diode, Ultrafast, 200 V, 1 A, POWERDI123 | DFLU1200-7 | Diodes, Inc. |
| 21 | 1 | D4 | 1000 V, 1 A, DO-214AC | GS1M-LTP | Micro Commercial |
| 22 | 1 | D5 | 600 V, 2 A, Superfast, 35 ns, DO-214AC, SMA | ES2J-LTP | Micro Commercial |
| 23 | 1 | D6 | Diode, SCHOTTKY, 40 V, 3 A, SMA, DO-214AA | B340A-13-F | Diodes, Inc. |
| 24 | 1 | F1 | 3.15 A, 250 V, Slow, 3.6 mm x 10 mm, Axial | 08773.15MXEP | Littlefuse |
| 25 | 1 | L1 | 8.8 mH, 0.7 mA, AC Filter T/H Common Mode Choke | SU10VFC-R07088 | Kemet |
| 26 | 1 | L2 | 1.5 mH, 0.8 A, 20% | RL-5480-4-1500 | Renco |
| 27 | 1 | L3 | 3.5 mm x 4.45 mm, 56 Ω at 100 MHz, 22 AWG hole, Ferrite Bead | 2761001112 | Fair-Rite |
| 28 | 1 | Q1 | MOSFET, N-CH, 150 V, 52 A, 8DFN | AON6250 | Alpha & Omega Semi |
| 29 | 1 | R1 | RES, 10 kΩ, 1%, 1/8 W, Thick Film, 0805 | ERJ-6ENF1002V | Panasonic |
| 30 | 1 | R2 | RES, 20 Ω, 1%, 1/2 W, Thin Film, 1206 | RNCP1206FTD20R0 | Stackpole |
| 31 | 1 | R3 | RES, 120 kΩ, 5%, 1/4 W, Thick Film, 1206 | ERJ-8GEYJ124V | Panasonic |
| 32 | 1 | R4 | RES, 1.60 MΩ, 1%, 1/4 W, Thick Film, 1206 | ERJ-8ENF1604V | Panasonic |
| 33 | 1 | R5 | RES, 1.30 MΩ, 1%, 1/4 W, Thick Film, 1206 | ERJ-8ENF1304V | Panasonic |
| 34 | 1 | R6 | RES, 47 Ω, 5%, 1/4 W, Thick Film, 1206 | ERJ-8GEYJ470V | Panasonic |
| 35 | 1 | R7 | RES, 15 Ω, ±1%, 0.75W, 3/4W, 1210, Thick Film | CRCW121015R0FKEAHP | Vishay Dale |
| 36 | 1 | R8 | RES, 102 kΩ, 1%, 1/16 W, Thick Film, 0603 | ERJ-3EKF1023V | Panasonic |
| 37 | 1 | R9 | RES, 11.8 kΩ, 1%, 1/16 W, Thick Film, 0603 | ERJ-3EKF1182V | Panasonic |
| 38 | 1 | R12 | RES, 1.33 MΩ, 1%, 1/4 W, Thick Film, 1206 | RC1206FR-071M33L | Yageo |
| 39 | 1 | R14 | RES, 20 kΩ, 1%, 1/16 W, Thick Film, 0603 | ERJ-3EKF2002V | Panasonic |
| 40 | 1 | R15 | RES, 20 Ω, 1%, 1/2 W, Thin Film, 1206 | RNCP1206FTD20R0 | Stackpole |
| 41 | 1 | R16 | RES, 36 kΩ, 5%, 1/4 W, Thick Film, 1206 | ERJ-8GEYJ363V | Panasonic |
| 42 | 1 | R17 | RES, 36 kΩ, 5%, 1/4 W, Thick Film, 1206 | ERJ-8GEYJ363V | Panasonic |
| 43 | 1 | R18 | 0.012 Ω, ±1%, ±100ppm/°C, 1 W, 1206 (3216 Metric), Current Sense, Thick Film | RUK3216FR012CS | Samsung |

| | | | | | |
|----|---|-----|---|---------------------|--------------------|
| 44 | 1 | R19 | RES, 1 k, 5%, 1/4 W, Thick Film, 1206 | ERJ-8GEYJ102V | Panasonic |
| 45 | 1 | RV1 | Varistor, 350 VAC, 3.5K A, 10.5 mm, Bulk ZNR, ERZ-E, Surge Absorber | ERZ-E08A561 | Panasonic |
| 46 | 1 | T1 | Bobbin, RM8, Vertical, 12 pins | BRM08-1112CP-W-P5.0 | MH&W |
| 47 | 1 | T2 | Bobbin, EE13, Vertical, 10 pins | P-1302-2 | Pin Shine |
| 48 | 1 | VR1 | DIODE, ZENER, 140 V, $\pm 5\%$, 1.5 W, DO204AL, DO-204AL (DO-41) | Z4KE140A-E3/54 | Vishay |
| 49 | 1 | VR2 | 240 V, 1.25 W, 600 W (Peak, non-repetitive), 5%, DO214AC (SMA) | BZG03C240TR | Vishay |
| 50 | 1 | VR3 | 240 V, 1.25 W, 600 W (Peak, non-repetitive), 5%, DO214AC (SMA) | BZG03C240TR | Vishay |
| 51 | 1 | U1 | LYTSwitch-6, InSOP24D | LYT6068C | Power Integrations |

6.2 *Miscellaneous Parts*

| Item | Qty | Ref Des | Description | Mfg Part Number | Mfg |
|------|-----|---------|--|-----------------|----------|
| 1 | 1 | +V | Test Point, RED, Miniature THRU-HOLE MOUNT | 5000 | Keystone |
| 2 | 1 | RTN | Test Point, BLK, Miniature THRU-HOLE MOUNT | 5001 | Keystone |
| 3 | 1 | L | Test Point, WHT, Miniature THRU-HOLE MOUNT | 5002 | Keystone |
| 4 | 1 | N | Test Point, BLK, THRU-HOLE MOUNT | 5011 | Keystone |
| 5 | 1 | FL1 | Flying Lead, Hole size 50mils | N/A | N/A |
| 6 | 1 | FL2 | Flying Lead, Hole size 50mils | N/A | N/A |



7 Flyback Transformer (T1) Specification

7.1 Electrical Diagram

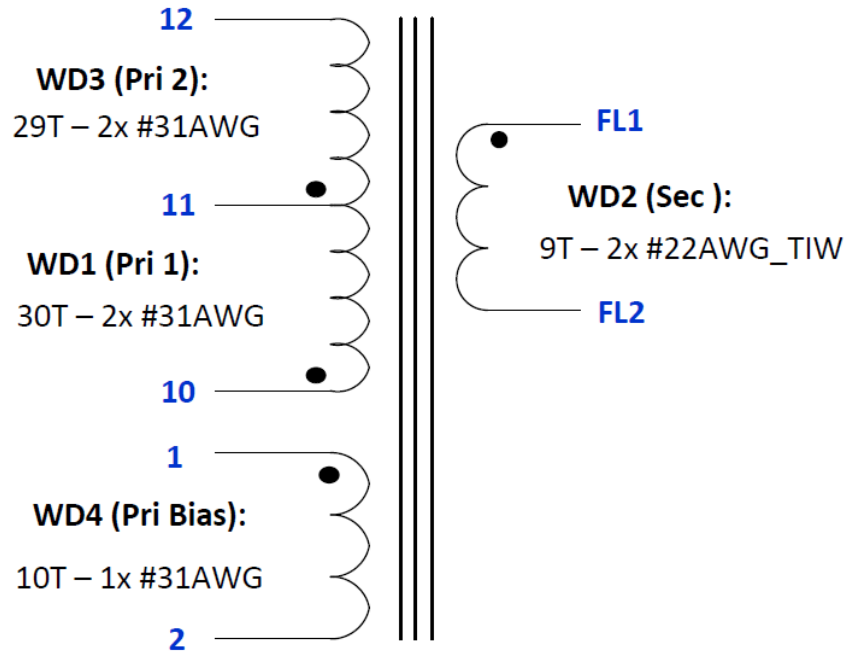


Figure 7 – Transformer Electrical Diagram.

7.2 Electrical Specifications

| Parameter | Condition | Spec. |
|----------------------------|---|-------------|
| Nominal Primary Inductance | Measured at 1 V _{PK-PK} , 100 kHz switching frequency, between pin 10 and pin 12 with all other windings open. | 720 μ H |
| Tolerance | Tolerance of Primary Inductance. | \pm 5% |
| Leakage Inductance | Measured across primary winding with all other windings shorted. | <6 μ H |

7.3 Material List

| Item | Description |
|------|---|
| [1] | Core: RM8 PC95. |
| [2] | Bobbin: Bobbin, RM8, Vertical, 12 pins; Part No. : 25-01084-00. |
| [3] | Magnet Wire: #31 AWG. |
| [4] | TIW: # 22 AWG. |
| [5] | Polyester Tape: 9 mm. |
| [6] | RM8 Core Clip with Terminal. |

7.4 Transformer Build Diagram

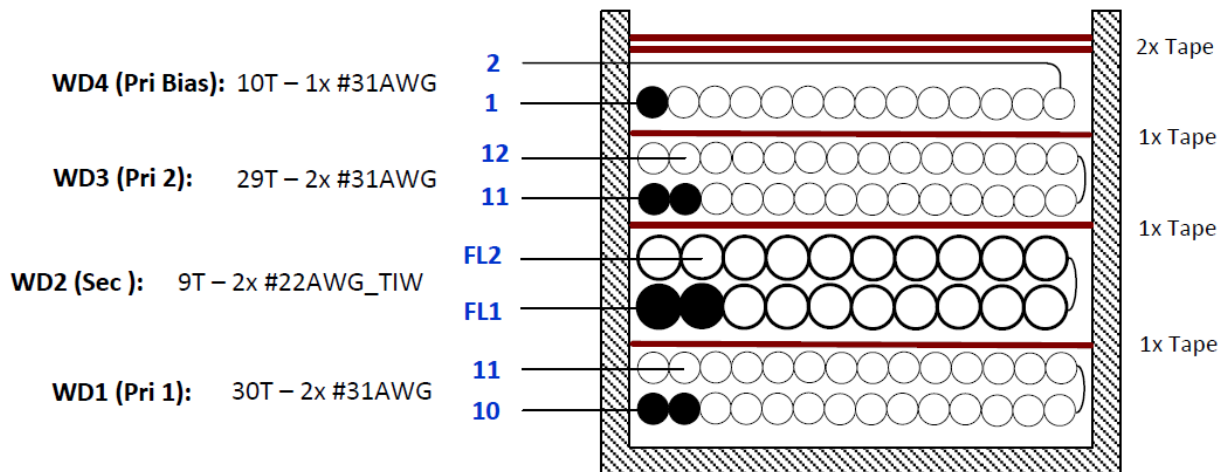


Figure 8 – Transformer Build Diagram.

7.5 Transformer Construction

| | |
|---------------------------|--|
| Winding Directions | Bobbin is oriented on winder jig such that terminal pin 10-12 is in the right side. The winding direction is clockwise. |
| Winding 1 | Use bifilar magnetic wire, Item [3]. Start at pin 10 and wind 30 turns evenly in 2 layers. Finish the winding on pin 11. |
| Insulation | Apply 1 layer of polyester tape, Item [5] for insulation |
| Winding 2 | Use bifilar triple insulated wire, Item [4]. Start at the other side of the bobbin (pin 4 – pin 9 side) and wind 9 turns evenly in 2 layers. Finished the winding on the same side of the bobbin. Do not terminate the winding on any pin of the bobbin; Just leave them as fly-leads. |
| Insulation | Apply 1 layer of polyester tape, Item [5] for insulation. |
| Winding 3 | Use bifilar magnetic wire, Item [3]. Start at pin 11 and wind 29 turns evenly in 2 layers. Finished the winding on pin 12. |
| Insulation | Apply 1 layer of polyester tape, Item [5] for insulation. |
| Winding 4 | Use magnetic wire, Item [3]. Start at pin 1 and wind 10 turns. Finish the winding on pin 2. |
| Insulation | Apply 2 layers of polyester tape, Item [5] for insulation. |
| Core Grinding | Grind the center leg of the ferrite core to meet the nominal inductance specification of 720 μ H. |
| Assemble Core | Use RM8 core clips with terminals, Item [6] to fix the 2 cores into the bobbin. Cut the terminal of the clip on the left side of the bobbin, looking at the bottom side facing the fly leads of the secondary winding. |
| Pins | Cut any excess pins of the bobbin (pins without wire terminations). Trim pin 11 as short as possible. |
| Finish | Dip the transformer in a 2:1 varnish and thinner solution |

7.6 Transformer Winding Illustrations

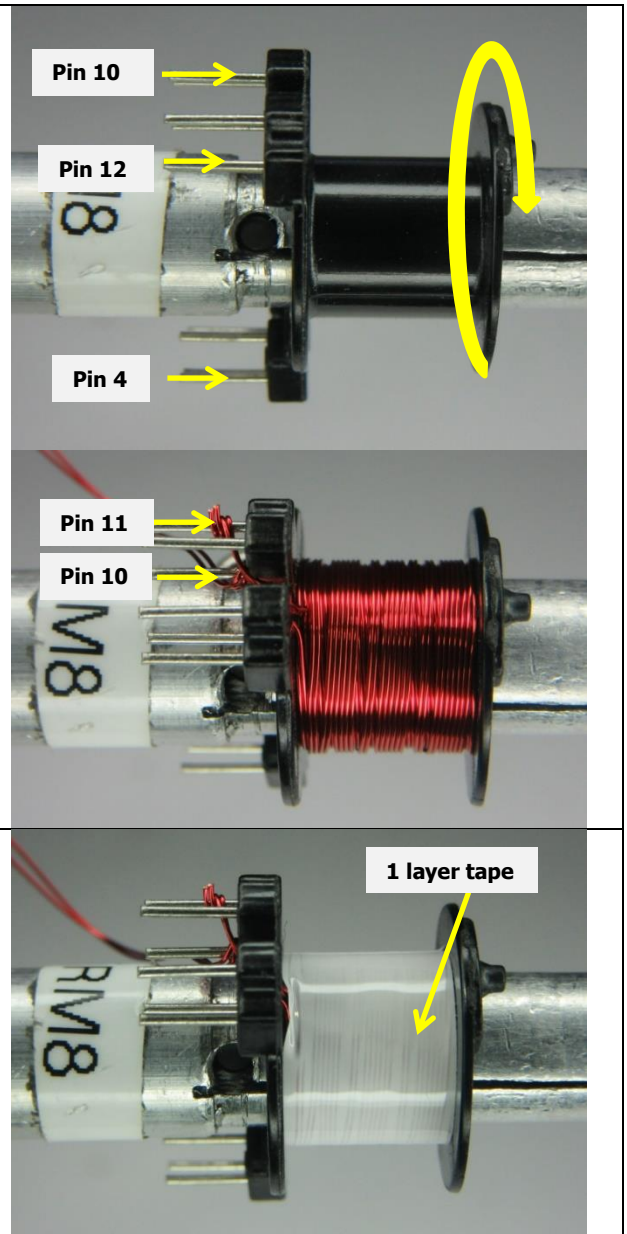
Winding Directions

Bobbin is oriented on winder jig such that terminal pin 10-12 is in the right side. The winding direction is clockwise.

Winding 1

Use bifilar magnetic wire, Item [3]. Start at pin 10 and wind 30 turns evenly in 2 layers.

Finish the winding on pin 11.



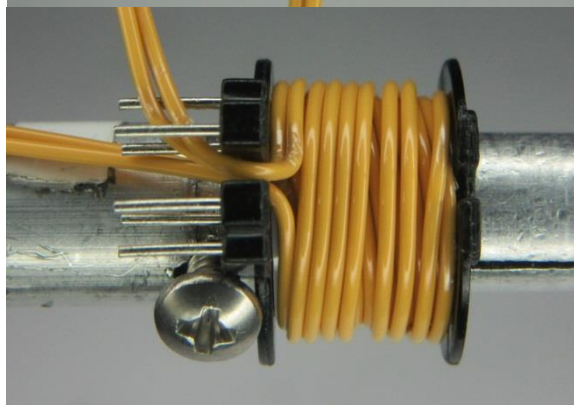
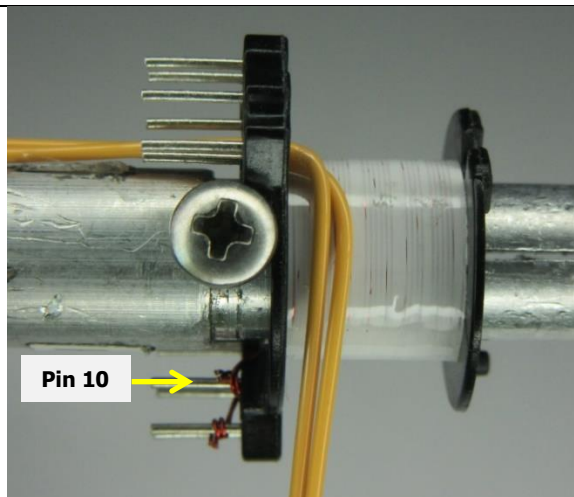
Insulation

Apply 1 layer of polyester tape, Item [5] for insulation.

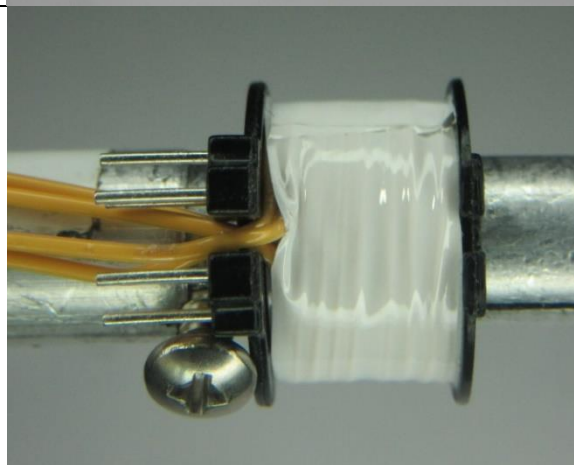
Winding 2

Use bifilar triple insulated wire, Item [4]. Start at the other side of the bobbin (pin 4 – pin 9 side) and wind 9 turns evenly in 2 layers.

Finished the winding on the same side of the bobbin. Do not terminate the winding on any pin of the bobbin; Just leave them as fly-leads.

**Insulation**

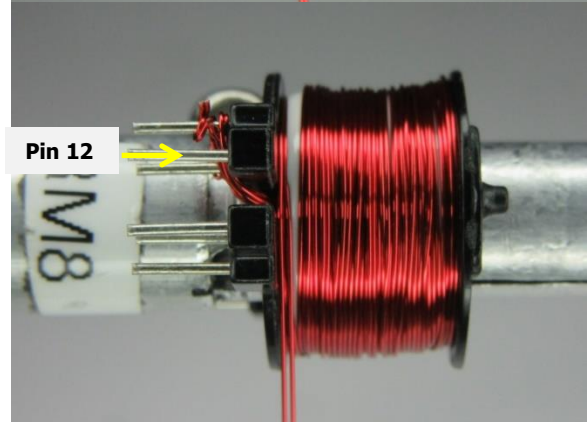
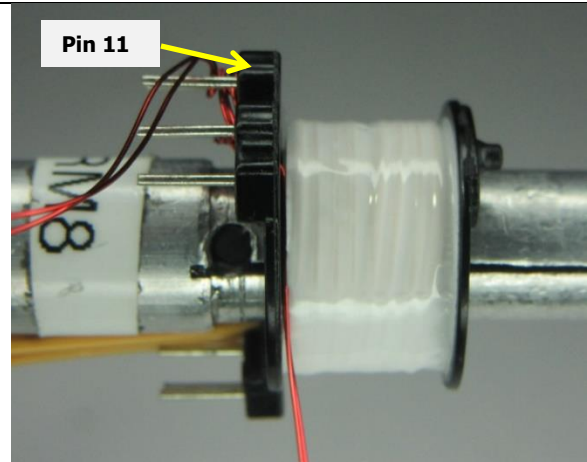
Apply 1 layer of polyester tape, Item [5] for insulation.



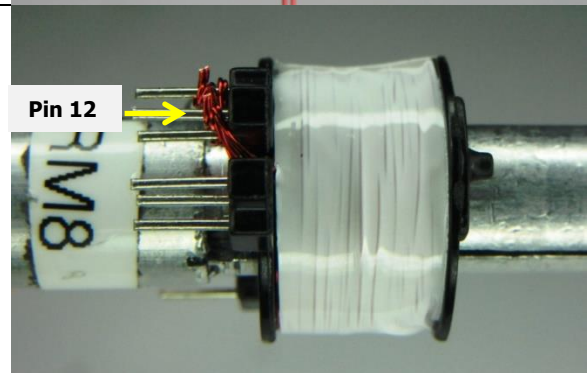
Winding 3

Use bifilar magnetic wire, Item [3]. Start at pin 11 and wind 29 turns evenly in 2 layers.

Finished the winding on pin 12.

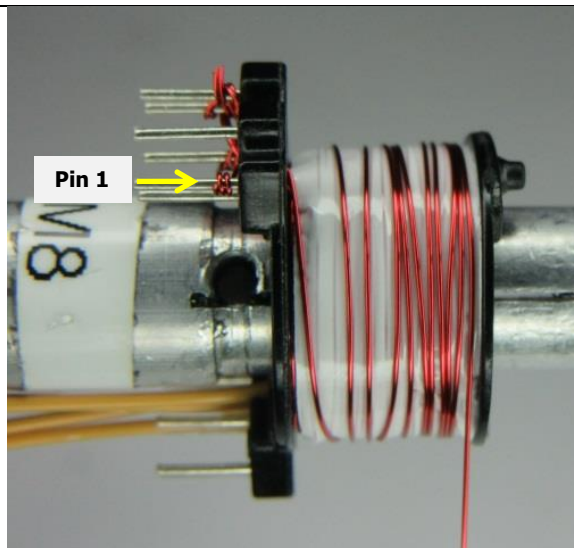
**Insulation**

Apply 1 layer of polyester tape, Item [5] for insulation.

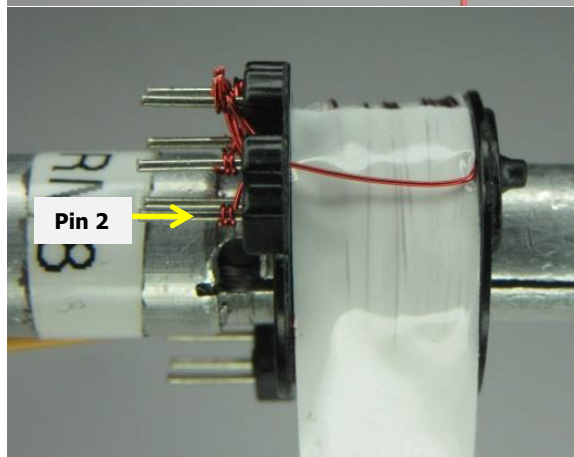


Winding 4

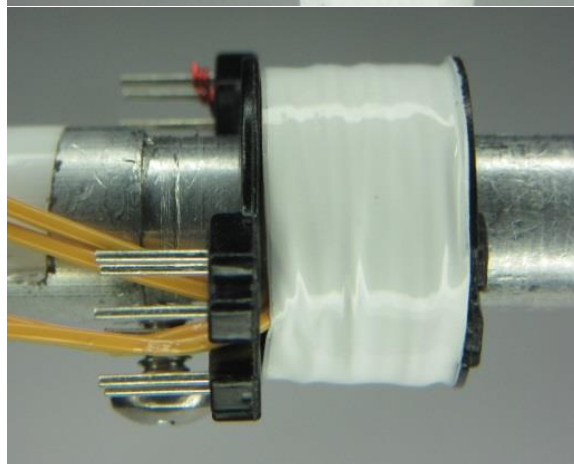
Use magnetic wire, Item [3]. Start at pin 1 and wind 10 turns.



Finish the winding on pin 2.

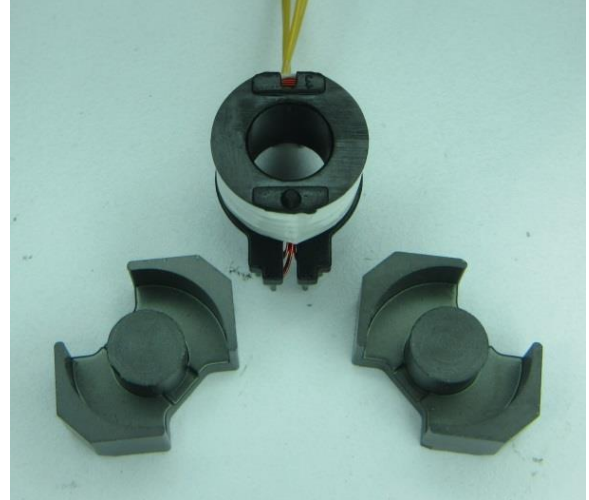
**Insulation**

Apply 2 layers of polyester tape, Item [5] for insulation.



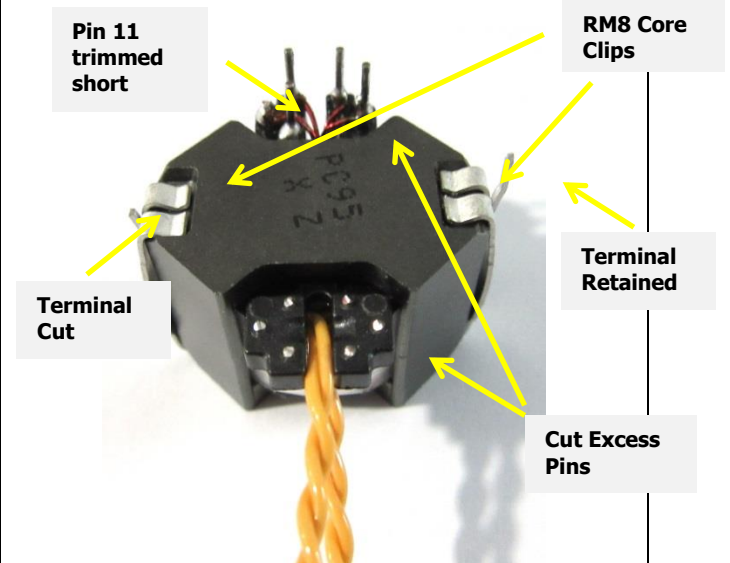
Core Termination

Use two PC95 RM8 cores, Item [1] and assemble them with the wounded bobbin.



Core Clips

Use RM8 Core Clips with Terminals, Item [6] to fix the 2 cores into the bobbin. Cut the terminal of the clip on the left side of the bobbin, looking at the bottom side facing the fly leads of the secondary winding.



Pins

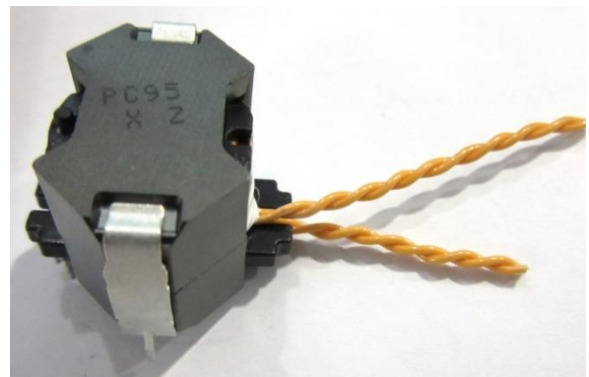
Cut any excess pins of the bobbin (pins without wire terminations). Trim pin 11 as short as possible.

Fly Leads

Twist the fly leads for easier termination on the PCB.

Varnishing

Dip the transformer in a 2:1 varnish and thinner solution



8 PFC Inductor (T2) Specifications

8.1 *Electrical Diagram*

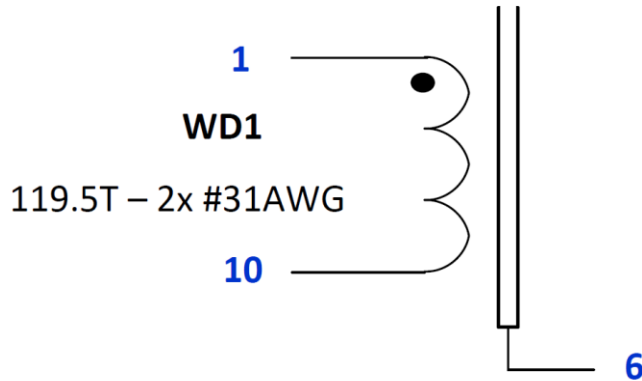


Figure 9 – Inductor Electrical Diagram.

8.2 *Electrical Specifications*

| Parameter | Condition | Spec. |
|----------------------------|---|--------|
| Nominal Primary Inductance | Measured at 1 V _{PK-PK} , 100 kHz switching frequency, between pin 1 and pin 10. | 760 μH |
| Tolerance | Tolerance of Primary Inductance. | ±5% |

8.3 *Material List*

| Item | Description |
|------|--|
| [1] | Core: EE13. |
| [2] | Bobbin: Bobbin, EE13, Vertical, 10 pins; Part no. 25-01023-00. |
| [3] | Magnet Wire: #31 AWG. |
| [4] | Transformer tape: 7.7 mm. |
| [5] | Transformer tape: 6 mm. |

8.4 Inductor Build Diagram

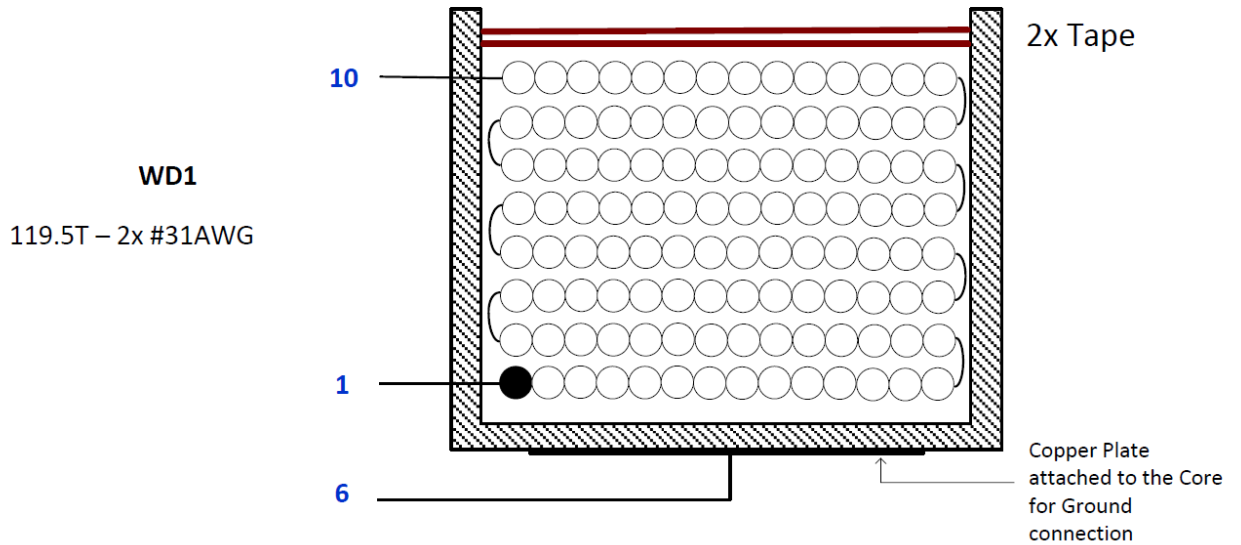


Figure 10 – Transformer Build Diagram.

8.5 Inductor Construction

| | |
|---------------------------|--|
| Winding Directions | Bobbin is oriented on winder jig such that terminal pin 1 – 5 is in the left side. The winding direction is clockwise. |
| Winding 1 | Prepare the magnetic wire Item [3] for bifilar-wound type winding. Start at pin 1 and wind 119.5 turns bifilar in 9 layers. Finish the winding on pin 10. |
| Insulation | Add 2 layers of tape, Item [4] for insulation. |
| Core Grinding | Grind the center leg of the ferrite core evenly until it meets the nominal inductance of 760 μ H. Inductance is measured across pin 1 and pin 10. |
| Assemble Core | Assemble the 2 cores on the bobbin. |
| Core Termination | Prepare a copper strip with a soldered magnetic wire, Item [3], at the middle as shown in the picture. Apply copper strip at the bottom part of the core and terminate the magnetic wire on pin 6. |
| Core Tape | Add 2 layers of tape, Item [5], around the core to fix the 2 cores into the bobbin. |
| Pins | Pull out or cut terminal pin no. 2, 3, 4, 5, 7, 8, and pin 9. |
| Finish | Dip the transformer assembly in 2:1 varnish and thinner solution. |

8.6 Inductor Winding Illustrations

Winding Directions

Bobbin is oriented on winder jig such that terminal pin 1 – 5 is in the left side. The winding direction is clockwise.

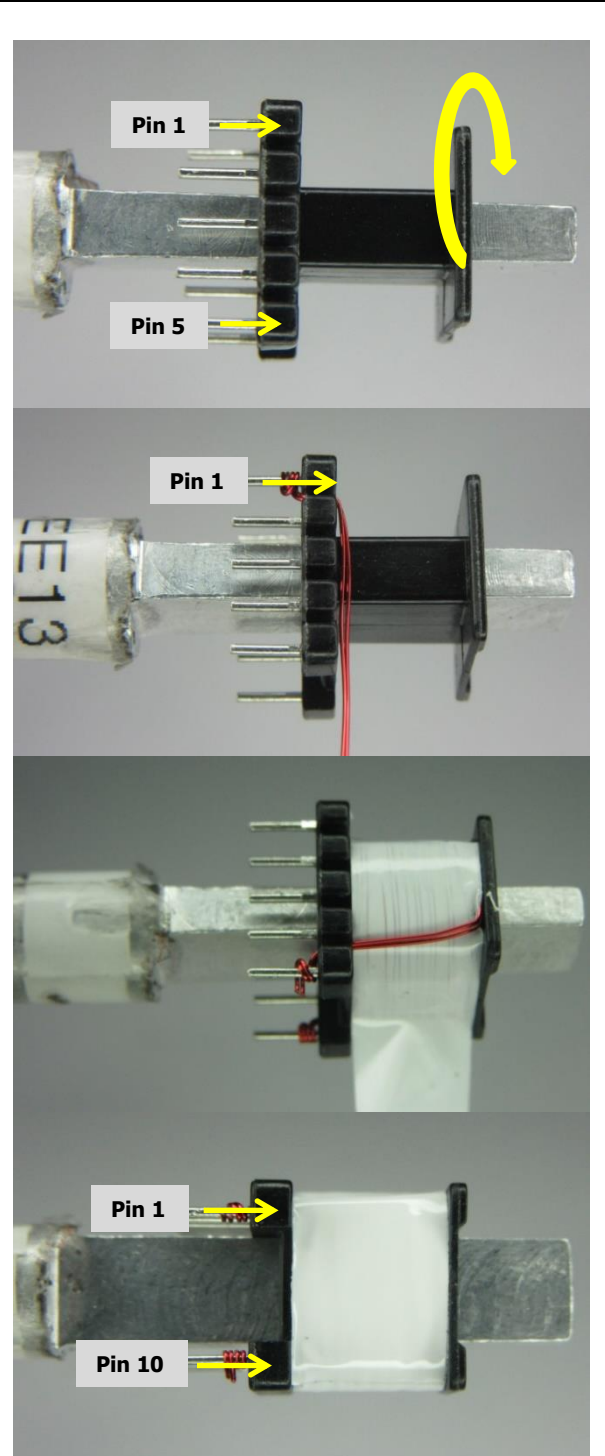
Winding 1

Prepare the magnetic wire Item [3] for bifilar-wound type winding. Start at pin 1 and wind 119.5 turns bifilar in 9 layers.

Finish the winding on pin 10.

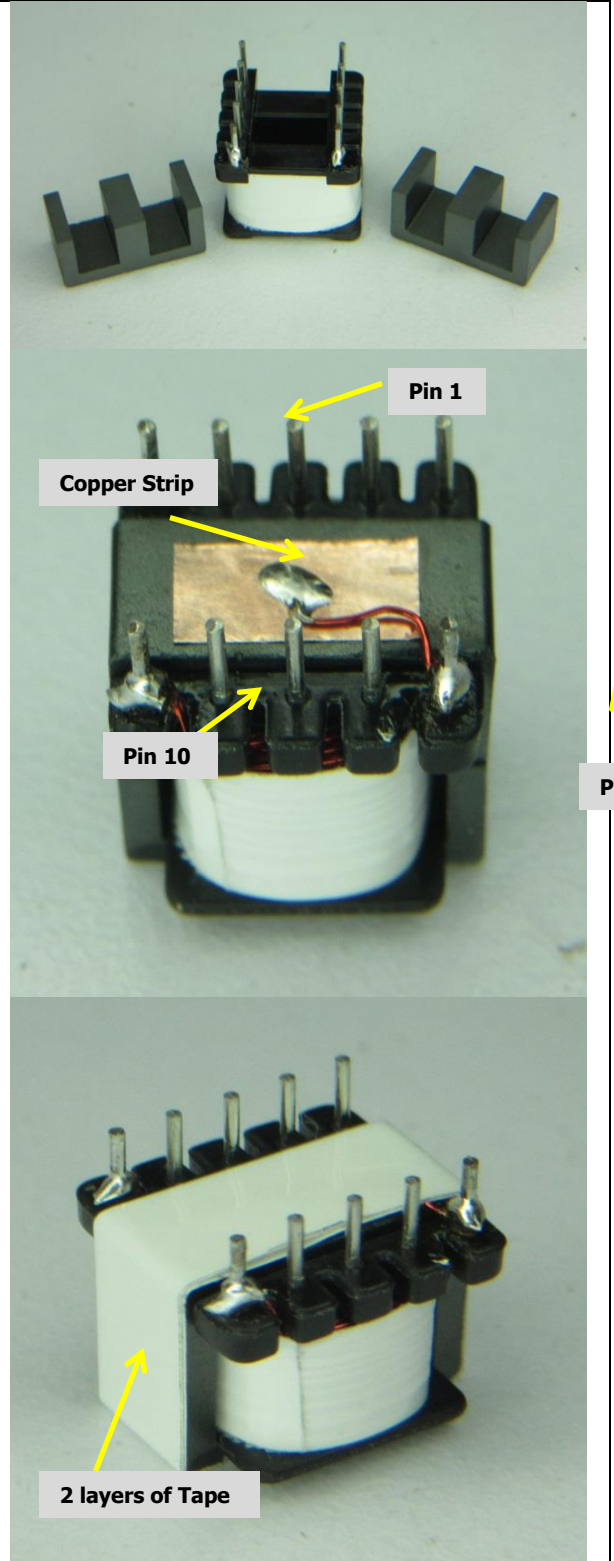
Insulation

Add 2 layers of tape, Item [4] for insulation



Core Termination

Prepare a copper strip with a soldered magnetic wire, Item [3], at the middle as shown in the picture. Apply copper strip at the bottom part of the core and terminate the magnetic wire on pin 6.



Core Tape

Add 2 layers of tape Item [5] around the core to fix the 2 cores into the bobbin.

PINS

Pull out or cut Terminal pin no. 2,3, 4, 5, 7, 8, and pin 9

Finish

Dip the transformer assembly in 2:1 varnish and thinner solution.

9 Design Spreadsheet

| 1 | ACDC_Flyback_PF_LYT Switch-6_020318; Rev.1.2; Copyright Power Integrations 2018 | INPUT | INFO | OUTPUT | UNITS | Switched Valley-Fill Single Stage PFC (SVF S ² PFC) |
|----|---|------------|------|------------|-------|--|
| 2 | Application Variables | | | | | |
| 3 | VACMIN | 140 | | 140 | V | Minimum Input AC Voltage |
| 4 | VACNOM | 230 | | 230 | V | Nominal AC Voltage (For universal designs low line nominal voltage is displayed) |
| 5 | VACMAX | 320 | | 320 | V | Maximum Input AC Voltage |
| 6 | VACRANGE | | | UNIVERSAL | | Input Voltage Range |
| 7 | FL | | | 50 | Hz | Line Frequency |
| 8 | CIN | 68.0000 | | 68.0000 | µF | Minimum Input Capacitance |
| 9 | V_CIN | | | 500 | V | Input Capacitance Recommended Voltage Rating |
| 10 | VO | 12.00 | | 12.00 | V | Output Voltage |
| 11 | IO | 2.92 | | 2.92 | A | Output Current |
| 12 | PO | | | 35.04 | W | Total Output Power |
| 13 | N | | | 88.00 | | Estimated Efficiency |
| 14 | Z | | | 0.50 | | Loss Allocation Factor |
| 15 | Parametric Calculations Basis | | | | | |
| 16 | ILIMcalcBASIS | Nom | | Nom | | ILIM Calculations Basis - NOM,MAX or MIN only |
| 17 | PARcalcBASIS | Worst_Case | | Worst_Case | | Calculated Results Based on Selected VAC - VACNOM,VACMAX,VACMIN or Worst Case only |
| 18 | Primary Controller Section | | | | | |
| 19 | DEVICE_MODE | Standard | | Standard | | Device Current Limit Mode |
| 20 | DEVNAME | LYT6068C | | LYT6068C | | PI Device Name |
| 21 | RDSON | | | 1.53 | ohms | Device RDSON at 100degC |
| 22 | ILIMITMIN | | | 1.534 | A | Minimum Current Limit |
| 23 | ILIMITTYP | | | 1.650 | A | Typical Current Limit |
| 24 | ILIMITMAX | | | 1.766 | A | Maximum Current Limit |
| 25 | BVDSS | | | 650 | V | Drain-Source Breakdown Voltage |
| 26 | VDS | | | 2.00 | V | On state Drain to Source Voltage |
| 27 | VDRAIN | | | 600.55 | V | Peak Drain to Source Voltage during Fet turn off |
| 28 | Worst Case Electrical Parameters | | | | | |
| 29 | Boost Converter | | | | | |
| 30 | IBOOSTRMS | | | 296.90 | mA | Boost RMS current |
| 31 | IBOOSTMAX | | | 788.21 | mA | Boost PEAK current |
| 32 | IBOOSTAVG | | | 190.53 | mA | Boost AVG current |
| 33 | IINRMS | | | 313.49 | mA | Input RMS current |
| 34 | PF_est | | | 0.8258 | | Estimated Power Factor |
| 35 | Flyback Converter | | | | | |
| 36 | FSMIN | 47700 | | 47700 | Hz | Minimum Switching Frequency in a Line Period |
| 37 | FSMAX | | | 97880.19 | Hz | Maximum Switching Frequency in a Line Period |
| 38 | KPmin | | | 0.8528 | | Minimum KP in a Line Period for VAC specified by PARcalcBASIS |
| 39 | IFETRMS | | | 498.46 | mA | Fet RMS current |
| 40 | IFETMAX | | | 1647.13 | mA | Fet PEAK current |
| 41 | IPRIRMS | | | 0.4040 | A | Primary Winding RMS current |
| 42 | IPRIMAX | | | 1.4870 | A | Primary Winding PEAK current |
| 43 | IPRIAVG | | | 0.0704 | A | Primary Winding AVG current |
| 44 | IPRIMIN | | | 885.63 | mA | Primary Winding Minimum current |
| 45 | ISECRMS | | | 4.19 | A | Secondary RMS current |



| | | | | | | |
|-----------|--|--------|--|------------|-----------------------|---|
| 46 | ISECMAX | | | 10.11 | A | Secondary PEAK current |
| 47 | Boost Choke Construction Parameters | | | | | |
| 48 | RATIO_LBST_LFB | 1.0555 | | 1.0555 | | Boost Inductance and Flyback Primary Inductance Ratio |
| 49 | LBOOSTMIN | | | 720.89 | μH | Minimum Boost Inductance |
| 50 | LBOOSTNOM | | | 758.83 | μH | Nominal Boost Inductance |
| 51 | LBOOSTMAX | | | 796.77 | μH | Maximum Boost Inductance |
| 52 | LBOOSTTOL | 5.00 | | 5.00 | % | Boost Inductance Tolerance |
| 53 | Boost Core and Bobbin Selection | | | | | |
| 54 | CR_TYPE_BOOST | EE13 | | EE13 | | Boost Core |
| 55 | CR_PN_BOOST | | | PC40EE13-Z | | Boost Core Code |
| 56 | AE_BOOST | | | 17.10 | mm ² | Boost Core Cross Sectional Area |
| 57 | LE_BOOST | | | 30.20 | mm | Boost Core Magnetic Path Length |
| 58 | AL_BOOST | | | 1130.00 | nH/turns ² | Boost Core Ungapped Core Effective Inductance |
| 59 | VE_BOOST | | | 517.00 | mm ³ | Boost Core Volume |
| 60 | BOBBINID_BOOST | | | 548 | | Bobbin |
| 61 | AW_BOOST | | | 22.20 | mm ² | Window Area of Bobbin |
| 62 | BW_BOOST | | | 7.40 | mm | Bobbin Width |
| 63 | MARGIN_BOOST | | | 0.00 | mm | Safety Margin Width |
| 64 | BOBFILLFACTOR_Boost | | | 40.32 | % | Boost Bobbin Fill Factor |
| 65 | Boost Winding Details | | | | | |
| 66 | NBOOST | 119.50 | | 119.50 | | Boost Choke Turns |
| 67 | BP_BOOST | | | 3057.81 | Gauss | Boost Peak Flux Density |
| 68 | ALG_BOOST | | | 53.14 | nH/turns ² | Boost Core Ungapped Core Effective Inductance |
| 69 | LG_BOOST | | | 0.39 | mm | Boost Core Gap Length |
| 70 | L_BOOST | 4.00 | | 4.00 | | Number of Boost Layers |
| 71 | AWG_BOOST | | | 31.00 | | Boost Winding Wire AWG |
| 72 | OD_BOOST_INSULATED | | | 0.27 | mm | Boost Winding Wire Output Diameter with Insulation |
| 73 | OD_BOOST_BARE | | | 0.23 | mm | Boost Winding Wire Output Diameter without Insulation |
| 74 | CMA_BOOST | | | 269.68 | Circular Mils/A | Boost Winding Wire CMA |
| 75 | Flyback Transformer Construction Parameters | | | | | |
| 76 | VOR | 78 | | 78 | V | Secondary Voltage Reflected in the Primary Winding |
| 77 | LP_MIN | | | 682.98 | μH | Minimum Flyback Inductance |
| 78 | LP_NOM | | | 718.93 | μH | Nominal Flyback Inductance |
| 79 | LP_MAX | | | 754.88 | μH | Maximum Flyback Inductance |
| 80 | LP_TOL | 5.00 | | 5.00 | % | Flyback Inductance Tolerance |
| 81 | Flyback Core and Bobbin Selection | | | | | |
| 82 | CR_TYPE | RM8/I | | RM8/I | | Flyback Core |
| 83 | CR_PN | | | RM8/I-3F3 | | Flyback Core Code |
| 84 | AE | | | 63.00 | mm ² | Flyback Core Cross Sectional Area |
| 85 | LE | | | 38.40 | mm | Flyback Core Magnetic Path Length |
| 86 | AL | | | 3000.00 | nH/turns ² | Flyback Core Ungapped Core Effective Inductance |
| 87 | VE | | | 2440.00 | mm ³ | Flyback Core Volume |
| 88 | BOBBINID | | | Ferroxcube | | Flyback Bobbin |
| 89 | BB_ORIENTATION | | | H | | Flyback Bobbin Orientation H - Horizontal and V -Vertical |
| 90 | AW | | | 30.90 | mm ² | Flyback Window Area of Bobbin |
| 91 | BW | | | 8.60 | mm | Flyback Bobbin Width |
| 92 | MARGIN | | | 0.00 | mm | Safety Margin Width |
| 93 | Flyback Winding Details | | | | | |
| 94 | NP | | | 59.00 | | Primary Turns |
| 95 | BP | | | 3670.89 | Gauss | Flyback Peak Flux Density |
| 96 | BM | | | 3533.33 | Gauss | Flyback Maximum Flux Density |
| 97 | BAC | | | 1487.83 | Gauss | Flyback AC Flux Density |
| 98 | ALG | | | 206.53 | nH/turns ² | Flyback Core Ungapped Core Effective |

| | | | | | | |
|------------|---|-------|--|---------|-----------------|---|
| | | | | | | Inductance |
| 99 | LG | | | 0.36 | mm | Flyback Core Gap Length |
| 100 | L | | | 2.00 | | Number of Flyback Layers |
| 101 | AWG | | | 30.00 | | Primary Winding Wire AWG |
| 102 | OD | | | 0.30 | mm | Primary Winding Wire Output Diameter with Insulation |
| 103 | DIA | | | 0.26 | mm | Primary Winding Wire Output Diameter without Insulation |
| 104 | CMA | | | 249.81 | Circular Mils/A | Primary Winding Wire CMA |
| 105 | NB | | | 10.00 | | Bias Turns |
| 106 | L_BIAS | | | 1.00 | | Number of Flyback Bias Winding Layers |
| 107 | AWGpBias | | | 36.00 | | Bias Wire AWG |
| 108 | NS | 9 | | 9 | | Secondary Turns |
| 109 | AWGS | | | 20.00 | | Secondary Winding Wire AWG |
| 110 | ODS | | | 0.81 | mm | Secondary Winding Wire Output Diameter with Insulation |
| 111 | DIAS | | | 1.12 | mm | Secondary Winding Wire Output Diameter without Insulation |
| 112 | CMAS | | | 244.62 | Circular Mils/A | Secondary Winding Wire CMA |
| 113 | Primary Components Selection | | | | | |
| 114 | Line Undervoltage | | | | | |
| 115 | BROWN_IN_REQUIRED | 85.00 | | 85.00 | V | Required AC RMS line voltage brown-in threshold |
| 116 | RLS | | | 2.10 | MOhm | Two Resistors of this Value in Series to the V-pin |
| 117 | BROWN_IN_ACTUAL | | | 84.15 | V | Actual AC RMS brown-in threshold |
| 118 | Line Overvoltage | | | | | |
| 119 | OVERVOLTAGE_LINE | | | 350.90 | V | Actual AC RMS line over-voltage threshold |
| 120 | Bias Voltage | | | | | |
| 121 | VBIAS | 13.0 | | 13.0 | V | Rectified Bias Voltage |
| 122 | VF_BIASDIODE | | | 0.70 | V | Bias Winding Diode Forward Drop |
| 123 | VRRM_BIASDIODE | | | 89.70 | V | Bias diode reverse voltage |
| 124 | CBIAS | | | 22.0 | µF | Bias winding rectification capacitor |
| 125 | CBPP | | | 0.47 | µF | BPP pin capacitor |
| 126 | Bulk Capacitor Zener Clamp | | | | | |
| 127 | Use_Clamp | | | Yes | | Bulk Capacitor Clamp Needed? Yes, No or N/A |
| 128 | VZ1_V | | | 240.00 | V | Zener 1 Voltage Rating (In Series with Zener 2) |
| 129 | PZ1_W | | | 1.25 | W | Zener 1 Minimum Power Rating |
| 130 | VZ2_V | | | 240.00 | V | Zener 2 Voltage Rating |
| 131 | PZ2_W | | | 1.25 | W | Zener 2 Minimum Power Rating |
| 132 | RZ | | | 1000.00 | ohms | Resistor in series with Zener 1 and Zener 2 |
| 133 | Secondary Components Selection | | | | | |
| 134 | Feedback Components | | | | | |
| 135 | RFB_UPPER | | | 102.00 | kOhm | Upper feedback 1% resistor |
| 136 | RFB_LOWER | | | 12.10 | kOhm | Lower feedback 1% resistor |
| 137 | CFB_LOWER | | | 330.0 | pF | Lower feedback resistor decoupling at least 5V-rating capacitor |
| 138 | CBPS | | | 2.2 | µF | BPS pin capacitor |
| 139 | Secondary Auxiliary Section - For VO > 24V ONLY | | | | | |
| 140 | Sec Aux Diode | | | | | |
| 141 | VAUX | | | 12.00 | V | Rectified auxiliary voltage |
| 142 | VF_AUX | | | 0.70 | V | Auxiliary winding diode forward drop |
| 143 | VRRM_AUXDIODE | | | 82.03 | V | Auxiliary diode reverse voltage |
| 144 | CAUX | | | 22.00 | µF | Auxiliary winding rectification capacitor |
| 145 | NAUX_SEC | | | 9.00 | | Secondary Aux Turns |



| | | | | | | |
|------------|--------------------------------------|--|--|-------------------------|-------|--|
| 146 | L_AUX | | | 1.00 | | Number of Flyback Aux Winding Layers |
| 147 | AWGSAUX | | | 38 | | Secondary Aux Winding AWG |
| 148 | Output Parameters | | | | | |
| 149 | VOUT_ACTUAL | | | 12.00 | V | Actual Output Voltage |
| 150 | IOUT_ACTUAL | | | 2.92 | A | Actual Output Current |
| 151 | ISECRMS | | | 4.19 | A | Secondary RMS current for output |
| 152 | Output Components | | | | | |
| 153 | VF | | | 0.70 | V | Output diode forward drop |
| 154 | VRRM | | | 81.03 | V | Output diode reverse voltage |
| 155 | COUT | | | 2040.53 | μF | Output Capacitor - Capacitance |
| 156 | COUT_VOpercentRip | | | 2.50 | % | Output Capacitor Ripple % of VOUT |
| 157 | ICOUTrms | | | 3.00 | A | Output Capacitor Estimated Ripple Current |
| 158 | ESRmax | | | 29.69 | mohms | Output Capacitor Maximum Recommended ESR |
| 159 | Errors, Warnings, Information | | | | | |
| 160 | Information | | | VDRAIN,OVERVOLTAGE_LINE | | Although the design has passed the user should validate functionality on the bench. Please check the variables listed. |
| 161 | Design Warnings | | | | | Design variables whose values exceed electrical/datasheet specifications. |
| 162 | Design Errors | | | | | The list of design variables which result in an infeasible design. |

Notes: Row 160 – Actual drain voltage stress does not exceed the absolute maximum V_{DS} rating of LYTSwitch-6 IC. Actual line overvoltage protection is below the absolute maximum V_{DS} rating of LYTSwitch-6 IC.

10 Performance Data

All measurements were performed at room temperature.

10.1 Output Voltage Regulation

Set-up: Open frame unit
Load: 2.92 A CC load
Ambient Temperature: 25 °C
Soak time: 180 seconds

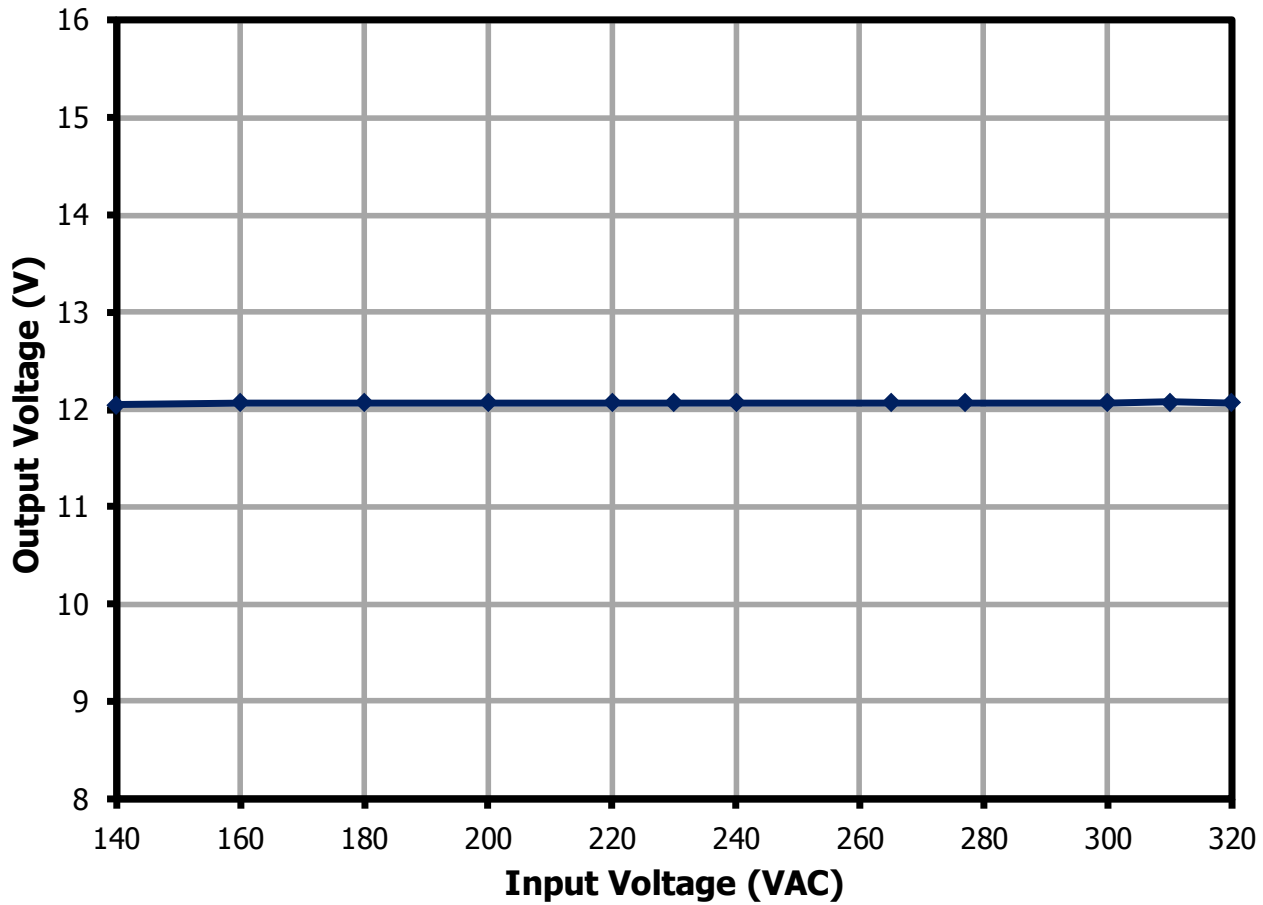


Figure 11 – Output Voltage Regulation vs. Input Line Voltage.

10.2 System Efficiency

Set-up: Open frame unit
Load: 2.92 A CC load
Ambient Temperature: 25 °C
Soak time: 180 seconds

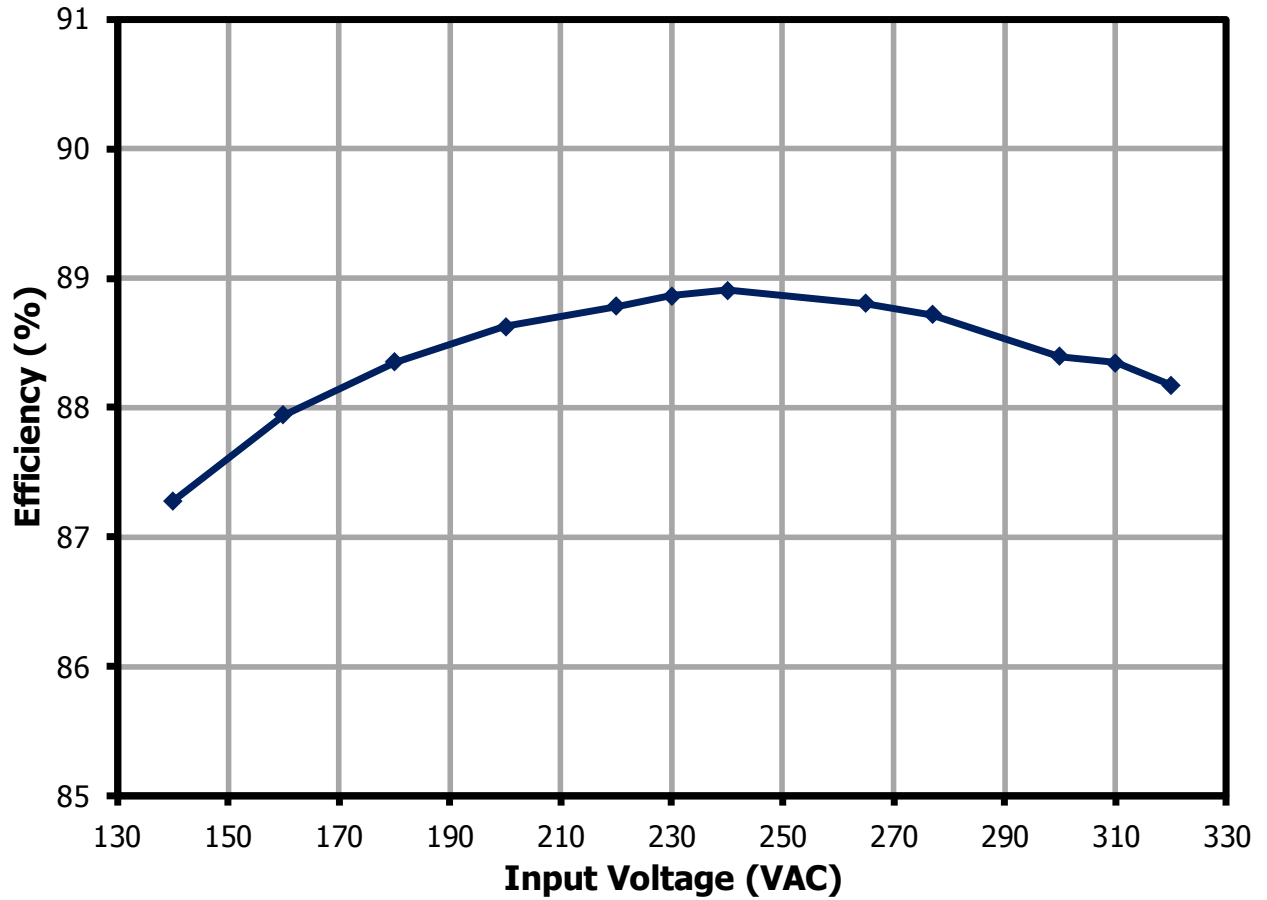


Figure 12 – Efficiency vs. Input Line Voltage.



10.3 Power Factor

Set-up: Open frame unit
Load: 2.92 A CC load
Ambient Temperature: 25 °C
Soak time: 180 seconds

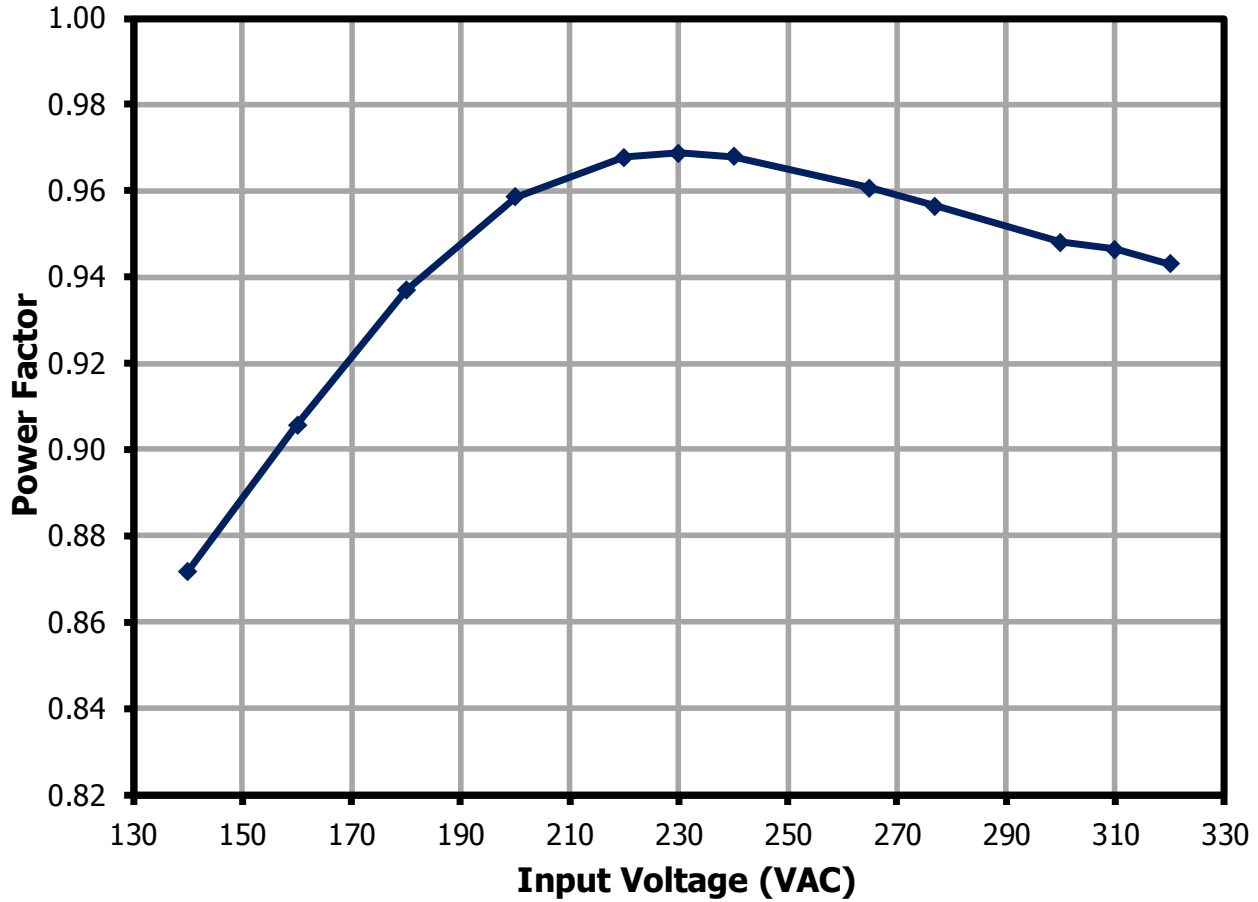


Figure 13 – Power Factor vs. Input Line Voltage.

10.4 %ATHD

Set-up: Open frame unit
Load: 2.92 A CC load
Ambient Temperature: 25 °C
Soak time: 180 seconds

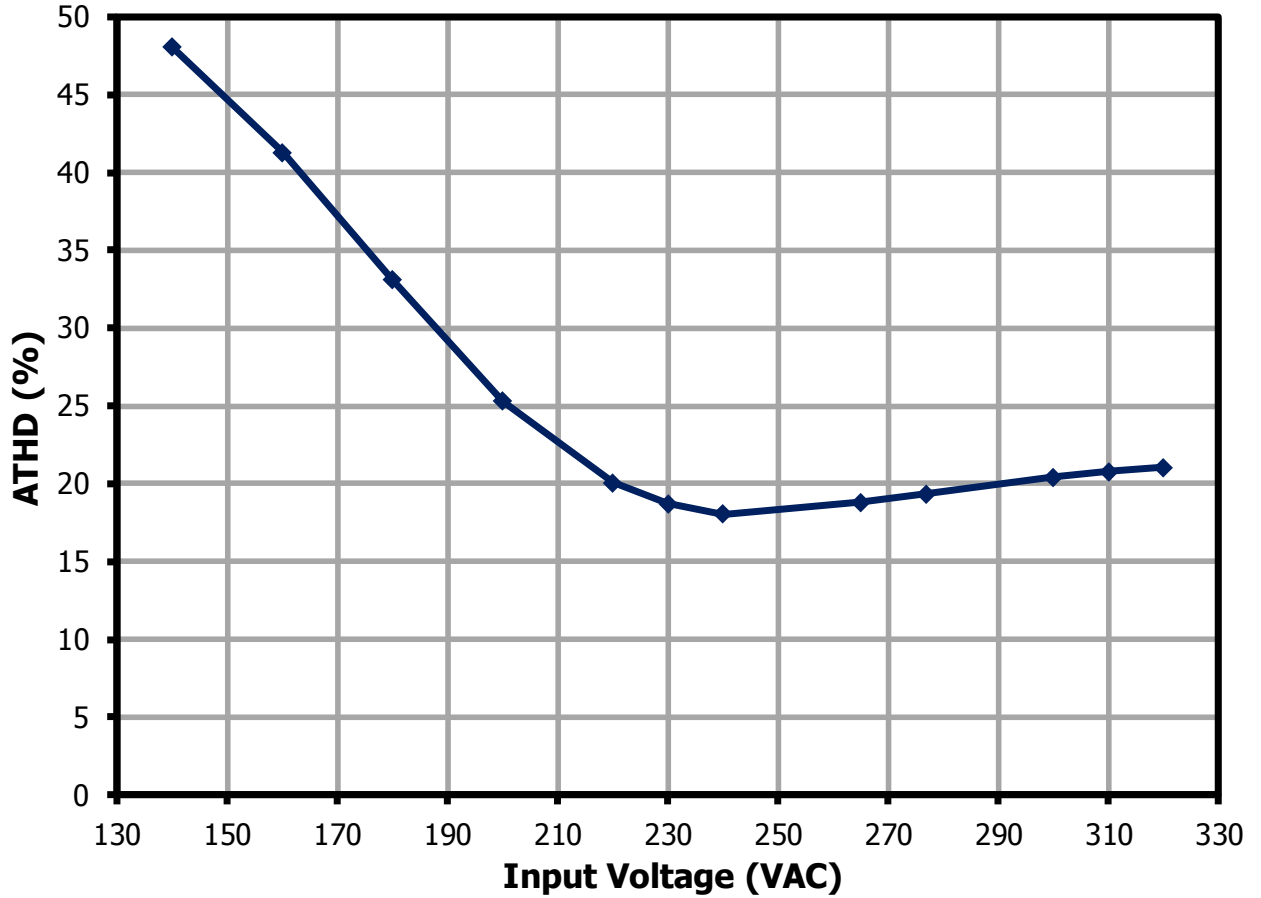


Figure 14 – %ATHD vs. Input Line Voltage.



10.5 **Individual Harmonics Content at Full Load**

Set-up: Open frame unit
Load: 2.92 A CC load
V_{IN}: 230 V 50 Hz
Ambient Temperature: 25 °C
Soak time: 180 seconds

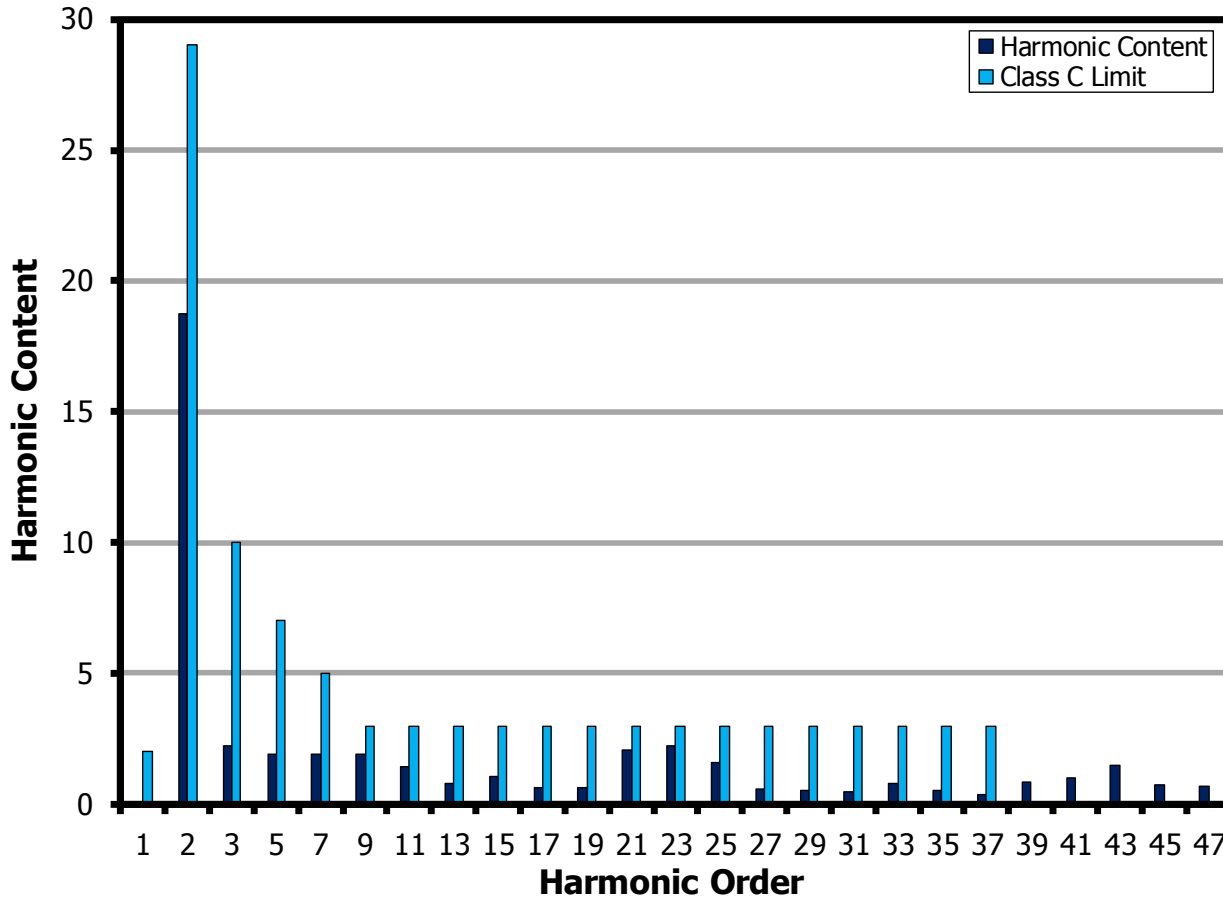


Figure 15 – Full Load Input Current Harmonics at 230 VAC 50 Hz.



Set-up: Open frame unit
Load: 2.92 A CC Load
V_{IN}: 277 V 50 Hz
Ambient Temperature: 25 °C
Soak time: 180 seconds

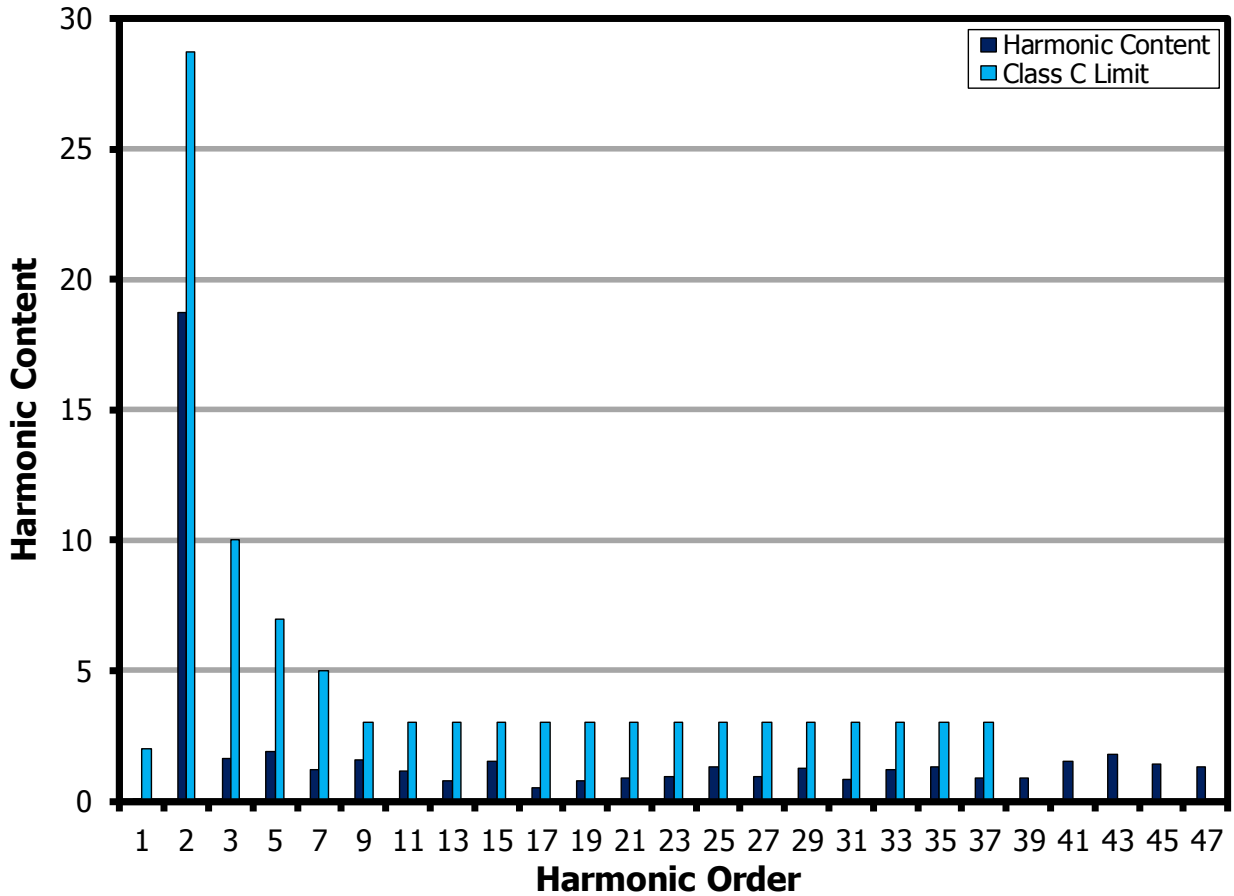


Figure 16 – Full Load Input Current Harmonics at 277 VAC 50 Hz.



10.6 *No-Load Input Power*

Set-up: Open frame unit
Load: Open load
Ambient Temperature: 25 °C
Soak time: 180 seconds

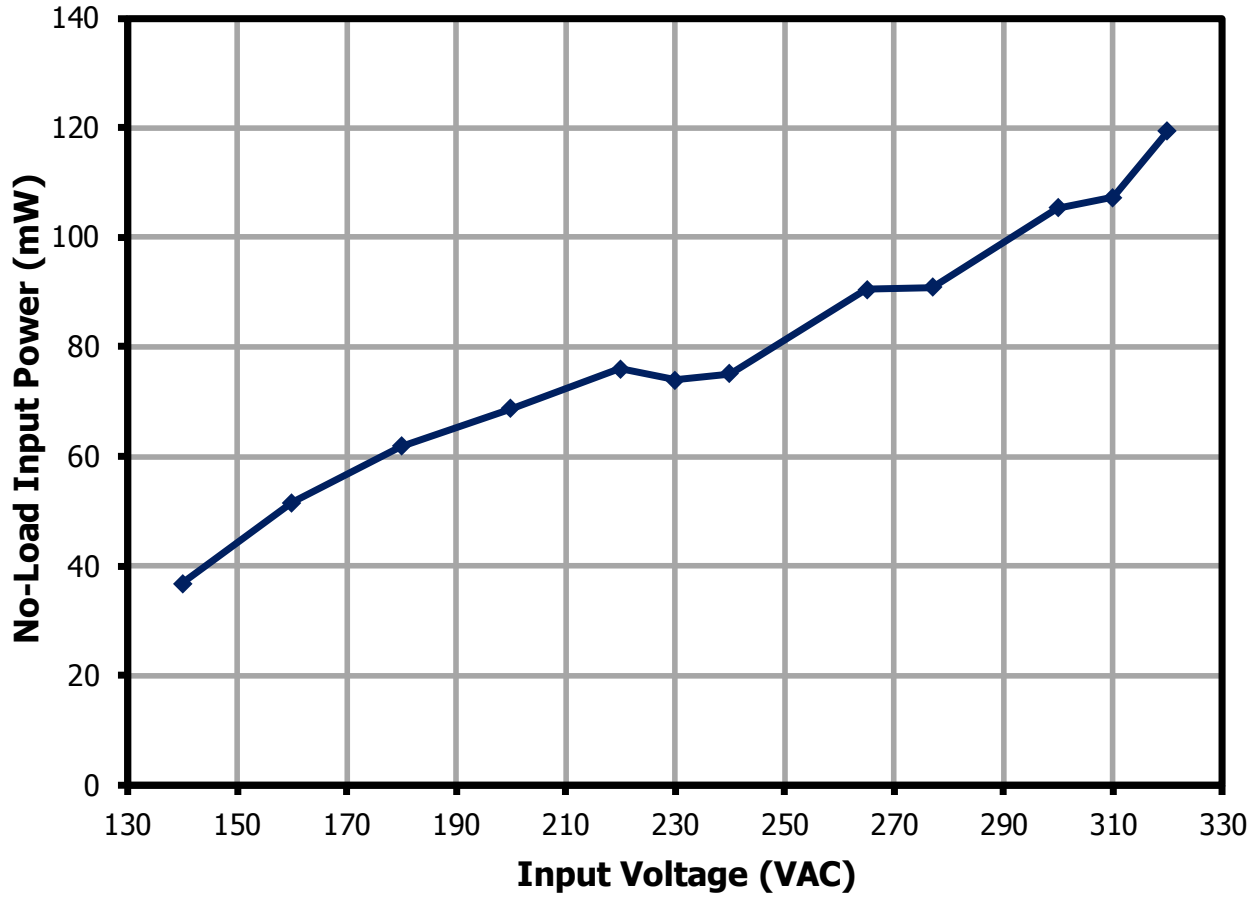


Figure 17 – No-Load Input Power vs. Input Line Voltage.

10.7 CV/CC Curve

Set-up: Open frame unit
Load: E-Load in CR mode
Ambient Temperature: 25 °C

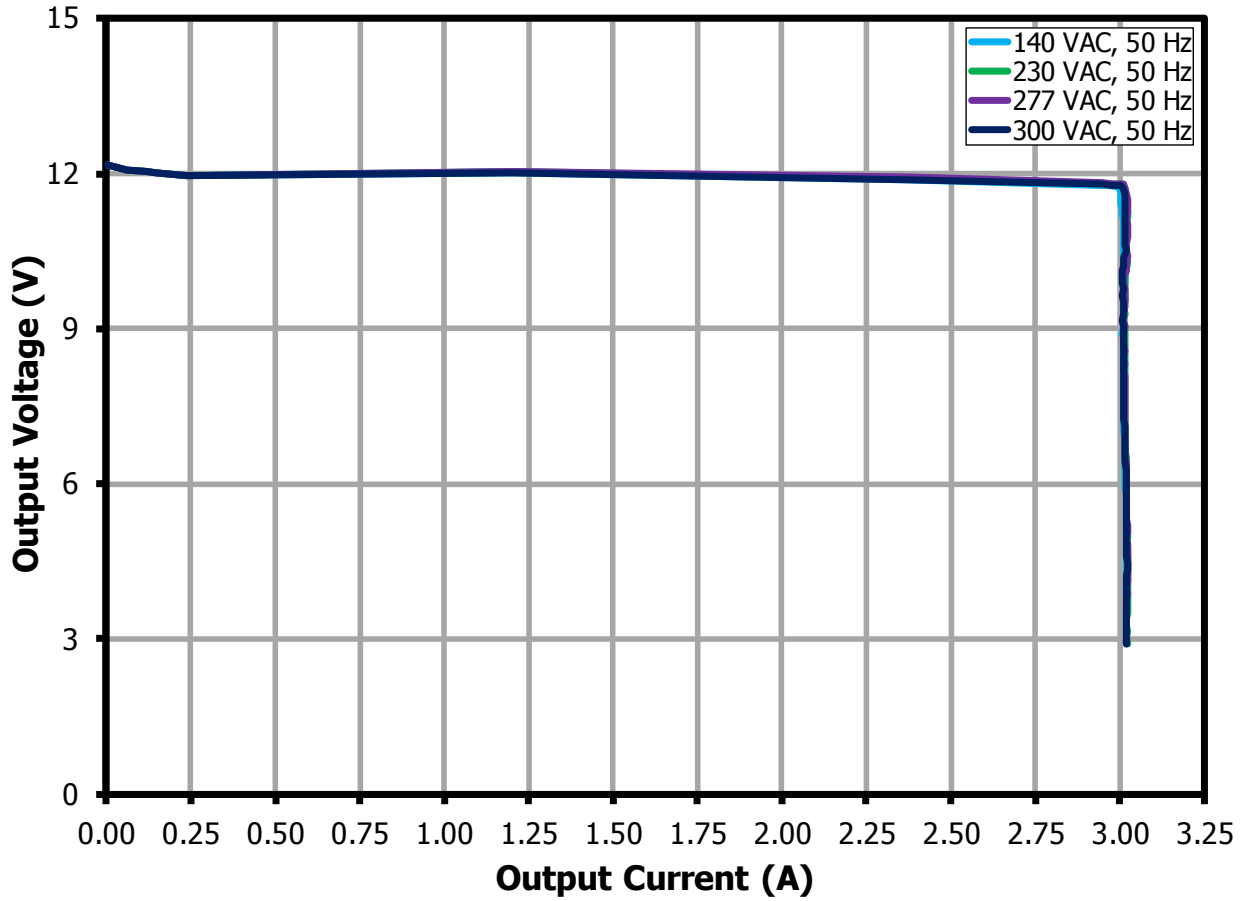


Figure 18 – CV/CC Curve.



11 Test Data

11.1 Test Data at Full Load

| Input | | Input Measurement | | | | | LED Load Measurement | | | Efficiency (%) |
|-------------------------|-----------|-------------------------------------|--------------------------------------|---------------------|-------|-------|-------------------------------------|--------------------------------------|----------------------|----------------|
| VAC (V _{RMS}) | Freq (Hz) | V _{IN} (V _{RMS}) | I _{IN} (mA _{RMS}) | P _{IN} (W) | PF | %ATHD | V _{OUT} (V _{DC}) | I _{OUT} (mA _{DC}) | P _{OUT} (W) | |
| 140 | 50 | 139.96 | 330.37 | 40.31 | 0.872 | 48.04 | 12.05 | 2919.80 | 35.18 | 87.27 |
| 160 | 50 | 159.92 | 276.59 | 40.06 | 0.906 | 41.28 | 12.07 | 2919.80 | 35.23 | 87.95 |
| 180 | 50 | 179.97 | 236.51 | 39.88 | 0.937 | 33.09 | 12.07 | 2919.80 | 35.23 | 88.35 |
| 200 | 50 | 199.92 | 207.49 | 39.76 | 0.959 | 25.31 | 12.07 | 2919.80 | 35.24 | 88.63 |
| 220 | 50 | 219.96 | 186.47 | 39.69 | 0.968 | 20.08 | 12.07 | 2919.80 | 35.24 | 88.78 |
| 230 | 50 | 229.99 | 177.99 | 39.65 | 0.969 | 18.74 | 12.07 | 2919.70 | 35.23 | 88.86 |
| 240 | 50 | 240.01 | 170.58 | 39.63 | 0.968 | 18.05 | 12.07 | 2919.70 | 35.23 | 88.90 |
| 265 | 50 | 265.03 | 155.84 | 39.68 | 0.961 | 18.83 | 12.07 | 2919.70 | 35.24 | 88.80 |
| 277 | 50 | 277.02 | 149.89 | 39.72 | 0.957 | 19.35 | 12.07 | 2919.80 | 35.24 | 88.72 |
| 300 | 50 | 300.07 | 140.13 | 39.86 | 0.948 | 20.42 | 12.07 | 2919.70 | 35.23 | 88.39 |
| 310 | 50 | 309.84 | 136.14 | 39.92 | 0.947 | 20.79 | 12.08 | 2919.80 | 35.27 | 88.35 |
| 320 | 50 | 319.75 | 132.56 | 39.97 | 0.943 | 21.04 | 12.07 | 2919.70 | 35.24 | 88.17 |

11.2 Test Data at No-Load

| Input | | Input Measurement | | | | | Output Measurement |
|-------------------------|-----------|-------------------------------------|--------------------------------------|---------------------|-------|-------|-------------------------------------|
| VAC (V _{RMS}) | Freq (Hz) | V _{IN} (V _{RMS}) | I _{IN} (mA _{RMS}) | P _{IN} (W) | PF | %ATHD | V _{OUT} (V _{DC}) |
| 140 | 50 | 140.03 | 10.29 | 0.037 | 0.026 | 48.28 | 12.19 |
| 160 | 50 | 159.98 | 10.51 | 0.052 | 0.031 | 14.79 | 12.19 |
| 180 | 50 | 180.02 | 10.82 | 0.062 | 0.032 | 34.03 | 12.19 |
| 200 | 50 | 199.97 | 11.30 | 0.069 | 0.030 | 28.46 | 12.19 |
| 220 | 50 | 220.00 | 12.03 | 0.076 | 0.029 | 11.69 | 12.19 |
| 230 | 50 | 230.02 | 12.46 | 0.074 | 0.026 | 21.99 | 12.19 |
| 240 | 50 | 240.04 | 12.92 | 0.075 | 0.024 | 20.81 | 12.19 |
| 265 | 50 | 265.07 | 14.01 | 0.091 | 0.024 | 20.94 | 12.19 |
| 277 | 50 | 277.06 | 14.45 | 0.091 | 0.023 | 8.78 | 12.19 |
| 300 | 50 | 300.10 | 15.13 | 0.105 | 0.023 | 20.94 | 12.19 |
| 310 | 50 | 310.32 | 12.57 | 0.107 | 0.028 | 5.44 | 12.19 |
| 320 | 50 | 320.22 | 12.98 | 0.119 | 0.029 | 6.13 | 12.19 |

11.3 **Individual Harmonic Content at 230 VAC 50 Hz and Full Load**

| V | Freq | I_{IN} (mA _{RMS}) | P | PF | %THD |
|-----------|------------|----------------------------------|----------------|---------------|---------|
| 230 | 50.00 | 179.08 | 39.870 | 0.968 | 19.466 |
| nth Order | mA Content | % Content | mA Limit <25 W | % Limit >25 W | Remarks |
| 1 | 175.32 | | | | |
| 2 | 0.09 | 0.05% | | 2.00% | Pass |
| 3 | 32.83 | 18.73% | 135.56 | 29.04% | Pass |
| 5 | 3.91 | 2.23% | 75.75 | 10.00% | Pass |
| 7 | 3.35 | 1.91% | 39.87 | 7.00% | Pass |
| 9 | 3.33 | 1.90% | 19.94 | 5.00% | Pass |
| 11 | 3.34 | 1.91% | 13.95 | 3.00% | Pass |
| 13 | 2.52 | 1.44% | 11.81 | 3.00% | Pass |
| 15 | 1.41 | 0.80% | 10.23 | 3.00% | Pass |
| 17 | 1.81 | 1.03% | 9.03 | 3.00% | Pass |
| 19 | 1.10 | 0.63% | 8.08 | 3.00% | Pass |
| 21 | 1.11 | 0.63% | 7.31 | 3.00% | Pass |
| 23 | 3.66 | 2.09% | 6.67 | 3.00% | Pass |
| 25 | 3.86 | 2.20% | 6.14 | 3.00% | Pass |
| 27 | 2.77 | 1.58% | 5.69 | 3.00% | Pass |
| 29 | 1.05 | 0.60% | 5.29 | 3.00% | Pass |
| 31 | 0.93 | 0.53% | 4.95 | 3.00% | Pass |
| 33 | 0.81 | 0.46% | 4.65 | 3.00% | Pass |
| 35 | 1.36 | 0.78% | 4.39 | 3.00% | Pass |
| 37 | 0.93 | 0.53% | 4.15 | 3.00% | Pass |
| 39 | 0.65 | 0.37% | 3.94 | 3.00% | Pass |
| 41 | 1.47 | 0.84% | | | |
| 43 | 1.74 | 0.99% | | | |
| 45 | 2.56 | 1.46% | | | |
| 47 | 1.27 | 0.72% | | | |
| 49 | 1.15 | 0.66% | | | |

11.4 **Individual Harmonic Content at 277 VAC 50 Hz and Full Load**

| V | Freq | I_{IN} (mA _{RMS}) | P | PF | %THD |
|-----------|------------|----------------------------------|----------------|---------------|---------|
| 277 | 50.00 | 150.53 | 39.920 | 0.957 | 19.508 |
| nth Order | mA Content | % Content | mA Limit <25 W | % Limit >25 W | Remarks |
| 1 | 146.61 | | | | |
| 2 | 0.15 | 0.10% | | 2.00% | Pass |
| 3 | 27.44 | 18.72% | 135.66 | 28.72% | Pass |
| 5 | 2.37 | 1.62% | 75.81 | 10.00% | Pass |
| 7 | 2.78 | 1.90% | 39.90 | 7.00% | Pass |
| 9 | 1.74 | 1.19% | 19.95 | 5.00% | Pass |
| 11 | 2.30 | 1.57% | 13.97 | 3.00% | Pass |
| 13 | 1.65 | 1.13% | 11.82 | 3.00% | Pass |
| 15 | 1.17 | 0.80% | 10.24 | 3.00% | Pass |
| 17 | 2.26 | 1.54% | 9.04 | 3.00% | Pass |
| 19 | 0.73 | 0.50% | 8.09 | 3.00% | Pass |
| 21 | 1.13 | 0.77% | 7.32 | 3.00% | Pass |
| 23 | 1.28 | 0.87% | 6.68 | 3.00% | Pass |
| 25 | 1.39 | 0.95% | 6.14 | 3.00% | Pass |
| 27 | 1.96 | 1.34% | 5.69 | 3.00% | Pass |
| 29 | 1.41 | 0.96% | 5.30 | 3.00% | Pass |
| 31 | 1.84 | 1.26% | 4.96 | 3.00% | Pass |
| 33 | 1.23 | 0.84% | 4.66 | 3.00% | Pass |
| 35 | 1.75 | 1.19% | 4.39 | 3.00% | Pass |
| 37 | 1.96 | 1.34% | 4.15 | 3.00% | Pass |
| 39 | 1.28 | 0.87% | 3.94 | 3.00% | Pass |
| 41 | 1.27 | 0.87% | | | |
| 43 | 2.22 | 1.51% | | | |
| 45 | 2.60 | 1.77% | | | |
| 47 | 2.10 | 1.43% | | | |
| 49 | 1.94 | 1.32% | | | |

12 Load Regulation Performance

Set-up: Open frame unit
Ambient Temperature: 25 °C (Room Temp)

12.1 Output Voltage Load Regulation

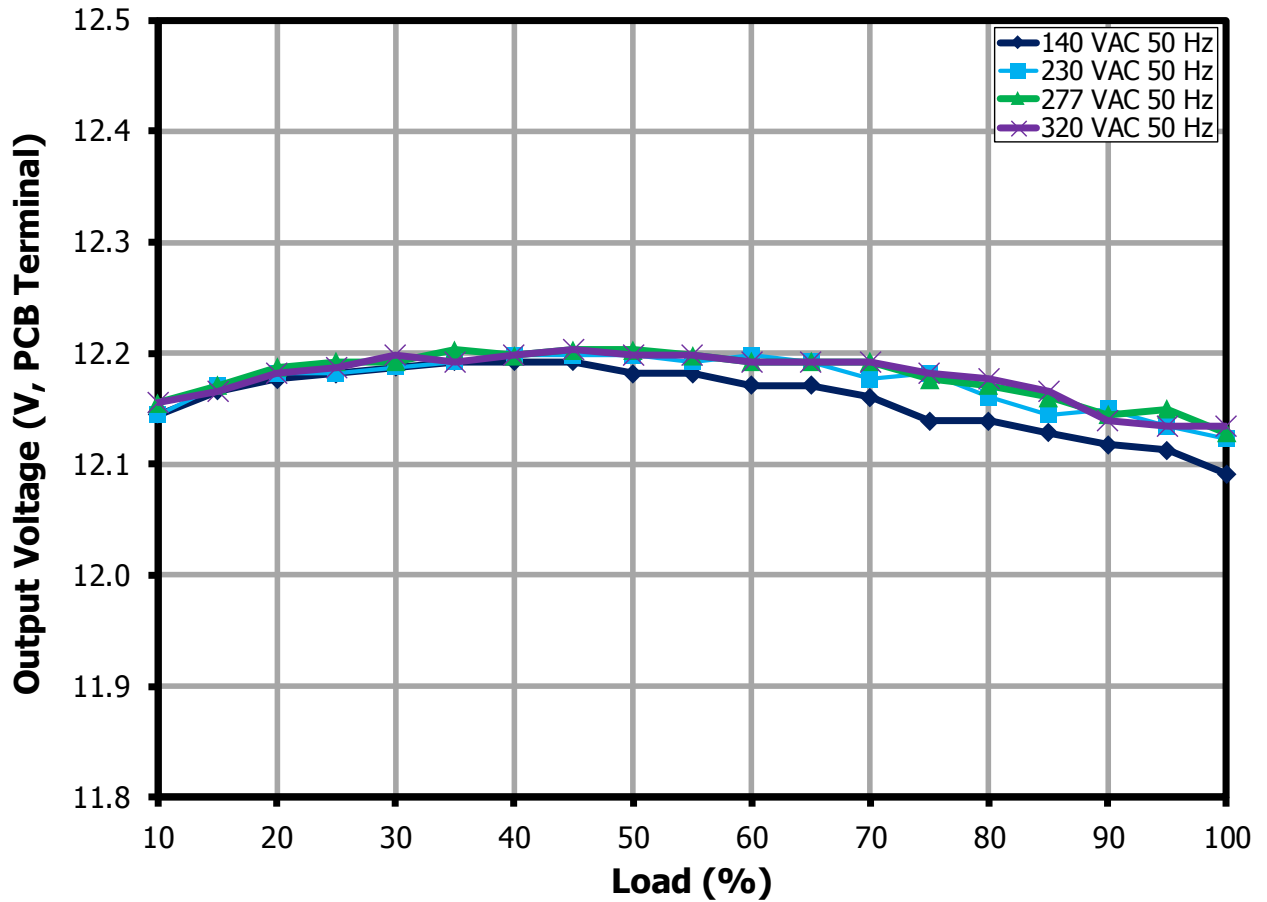


Figure 19 – Output Voltage vs. Load.



12.2 Efficiency vs. Load

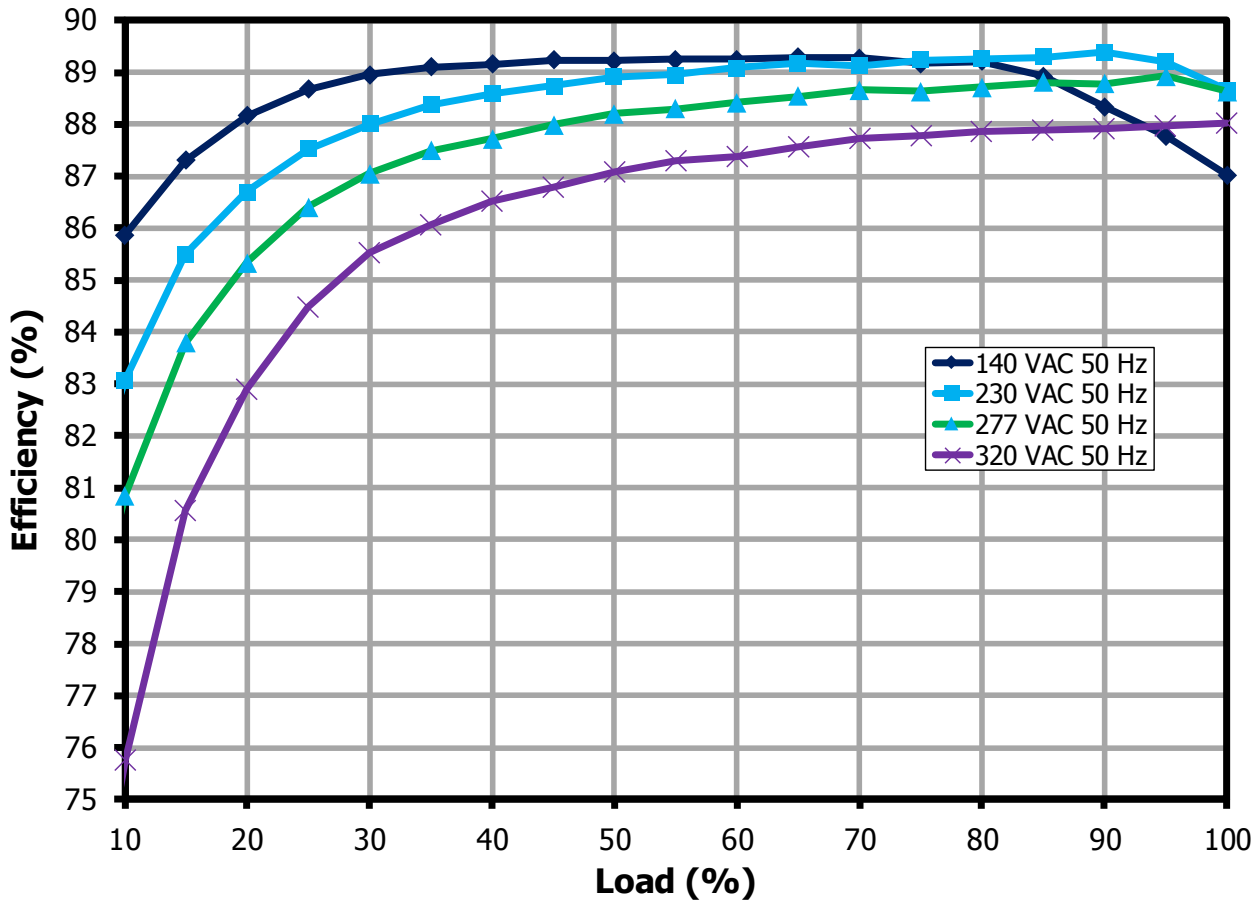


Figure 20 – Efficiency vs Load.

12.3 Average Efficiency

12.3.1 Average Efficiency Measurement

| %Load | Efficiency (%) | |
|---------------------------|----------------|---------------|
| | 230 V / 50 Hz | 277 V / 50 Hz |
| 100% | 88.66 | 88.64 |
| 75% | 89.24 | 88.64 |
| 50% | 88.91 | 88.20 |
| 25% | 87.53 | 86.41 |
| Average Efficiency | 88.59 | 87.97 |
| DOE Level VI Limit | 80.93 | |



12.4 **Power Factor vs. Load**

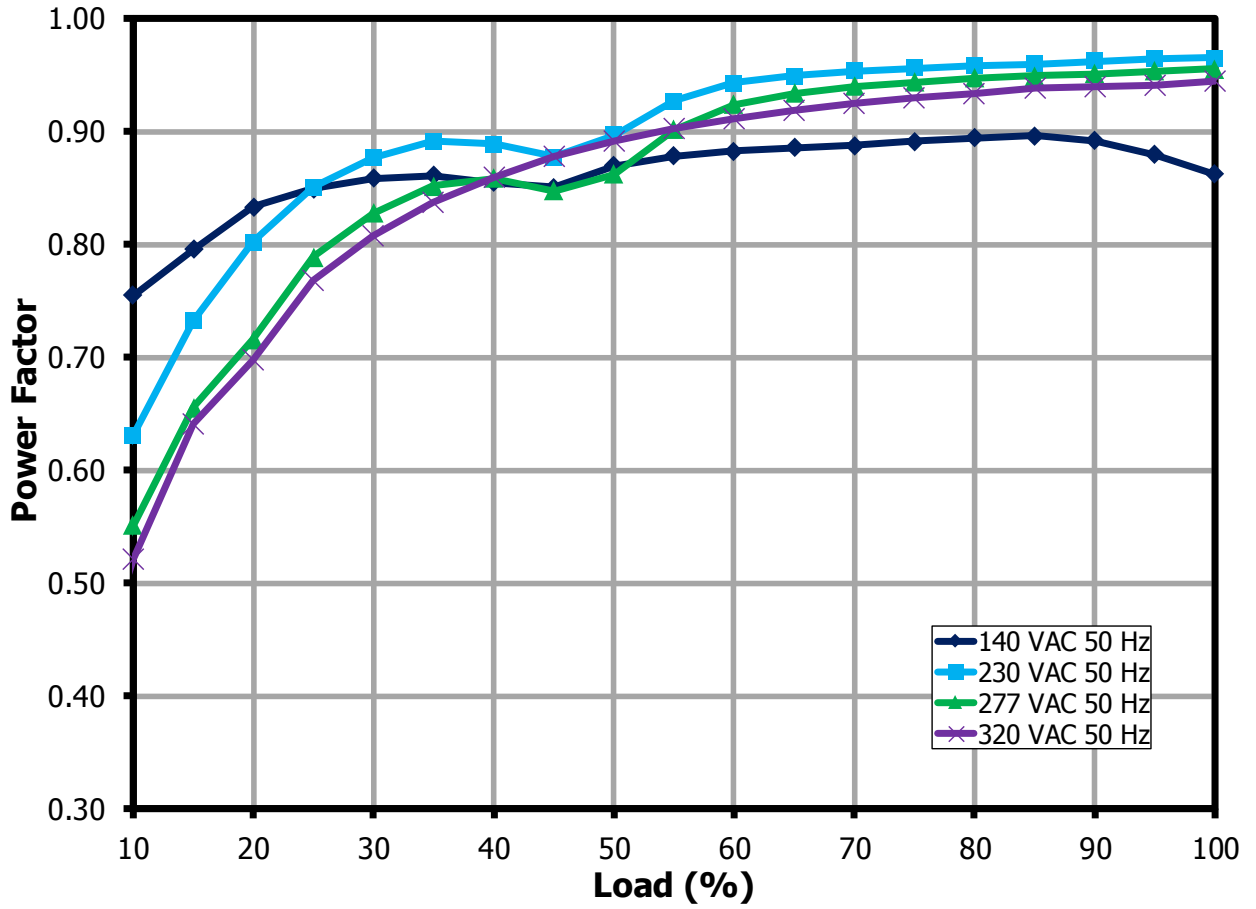


Figure 21 – Power Factor vs Load.



12.5 %ATHD vs. Load

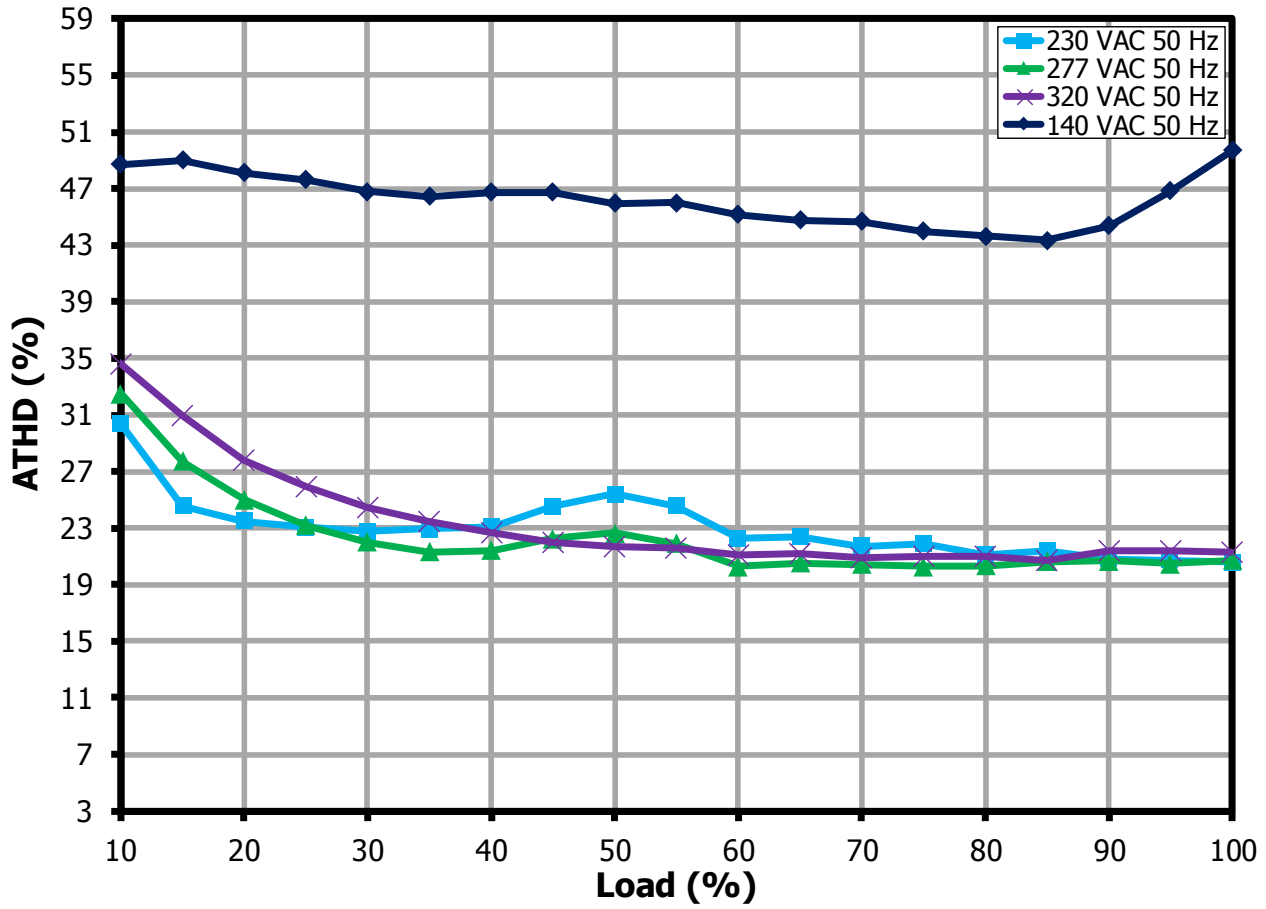


Figure 22 – %ATHD vs Load.

13 Thermal Performance

13.1 Thermal Measurements at Room Temp Ambient

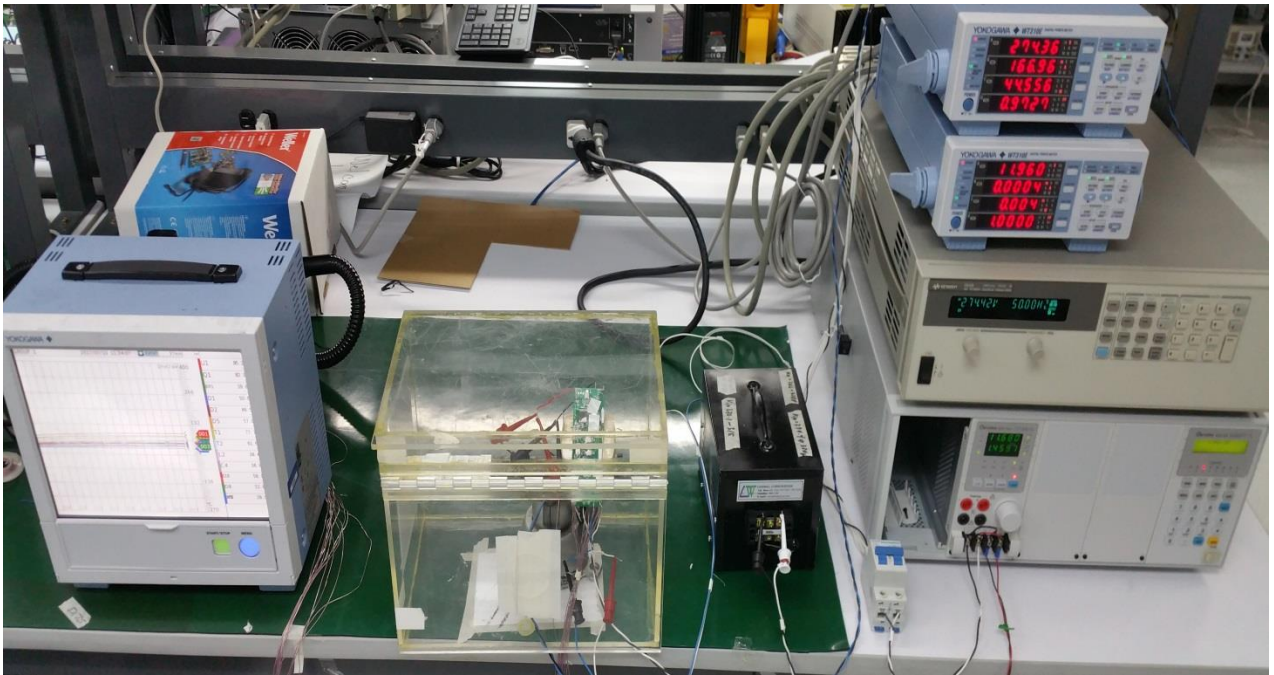


Figure 23 – Test Set-up Picture - Open Frame.

Unit in Open Frame was placed inside the acrylic enclosure to prevent airflow that might affect the thermal measurements. Temperature was measured using T-type thermocouple.

Equipment used:

1. KEYSIGHT 6812B AC Power Source/Analyzer
2. Chroma 6314A DC Electronic Load Mainframe and Chroma 63110A DC Electronic Load
3. Yokogawa GP20 Data Logger
4. Yokogawa WT310E Digital Power Meter
5. CADWILL Step-up Transformer (for Inputs >300Vac)

| Ckt. Code | Description | Thermal Reading at Room Temperature | | | |
|-----------------|---------------------------------|-------------------------------------|---------|---------|---------|
| | | 140 VAC | 230 VAC | 277 VAC | 320 VAC |
| U1 | LYTSwitch-6 IC | 83.1 | 80 | 84.4 | 89.9 |
| D4 | Primary Snubber Diode | 86.9 | 78.9 | 80.8 | 82.9 |
| VR1 | Primary Snubber Zener | 78.1 | 69.6 | 70.8 | 72.5 |
| Q1 | SR FET | 79.6 | 77.9 | 79.8 | 82.6 |
| T2 | PFC Inductor | 63.1 | 63.4 | 65.9 | 67.6 |
| T1 | DCDC TRF Primary | 82.1 | 81.3 | 84.3 | 86.5 |
| L3 | Bead on Secondary | 78.5 | 76.1 | 78.2 | 81.4 |
| D1 | PFC Diode | 54.2 | 50.5 | 50.2 | 49.5 |
| D5 | PFC Diode | 60.4 | 56.3 | 56.8 | 56.8 |
| BR1 | Bridge Diode | 52.4 | 43.9 | 42.5 | 41.8 |
| R2 / R15 | Primary Snubber Series Resistor | 78.8 | 72 | 73.1 | 75 |
| R7 | Secondary Snubber Resistor | 77.5 | 76.4 | 78.7 | 80.9 |
| C4 | Bulk Capacitor | 48.2 | 43.8 | 44.2 | 44.2 |
| C10 | Output Capacitor | 62.3 | 62.3 | 63.6 | 65.3 |
| AMBIENT | | 27.2 | 28.6 | 28.7 | 28.4 |

13.2 Thermal Performance at High Temp Ambient



Figure 24 – Test Set-up Picture Thermal at 60 °C Ambient - Open Frame.

Open frame unit was placed inside the enclosure to prevent airflow that may affect the thermal measurements. Ambient temperature inside enclosure is set at 60 °C. Temperature was measured using T-type thermocouple. Soak time at full load is more than 1 hour.

Equipment used:

1. KEYSIGHT 6812B AC Power Source/Analyzer
2. Chroma 6314A DC Electronic Load Mainframe and Chroma 63110A DC Electronic Load
3. Yokogawa GP20 Data Logger
4. Yokogawa WT310E Digital Power Meter
5. SPX Tenney TUJR Thermal Chamber
6. CADWILL Step-up Transformer (for Inputs >300Vac)

| Ckt. Code | Description | Thermal Reading at High Temperature | | | |
|-----------------|---------------------------------|-------------------------------------|---------|---------|---------|
| | | 140 VAC | 230 VAC | 277 VAC | 320 VAC |
| U1 | LYTSwitch-6 IC | 116.6 | 112.2 | 116.9 | 123.4 |
| D4 | Primary Snubber Diode | 117.1 | 110 | 111.5 | 114.5 |
| VR1 | Primary Snubber Zener | 106.2 | 98.8 | 99.6 | 101.4 |
| Q1 | SR FET | 112.3 | 110.4 | 112.6 | 114.6 |
| T2 | PFC Inductor | 94.2 | 93.7 | 96.1 | 98.6 |
| T1 | DCDC TRF Primary | 114.1 | 113.1 | 115.2 | 118.7 |
| L3 | Bead on Secondary | 110.5 | 108.1 | 110.4 | 112.7 |
| D1 | PFC Diode | 86.7 | 81.1 | 80.8 | 80.9 |
| D5 | PFC Diode | 91.7 | 87.4 | 87.1 | 88.4 |
| BR1 | Bridge Diode | 83.8 | 75.7 | 74.4 | 73.8 |
| R2 / R15 | Primary Snubber Series Resistor | 108.7 | 102.2 | 103.5 | 105.5 |
| R7 | Secondary Snubber Resistor | 110 | 108.5 | 110.5 | 113 |
| C4 | Bulk Capacitor | 79.6 | 75.6 | 75.5 | 75.9 |
| C10 | Output Capacitor | 95 | 93.7 | 95.2 | 96.7 |
| AMBIENT | | 62.4 | 61.9 | 62.1 | 62.1 |

14 Waveforms

Waveforms were taken at room temperature (25 °C).

14.1 Input Voltage and Input Current at Full Load

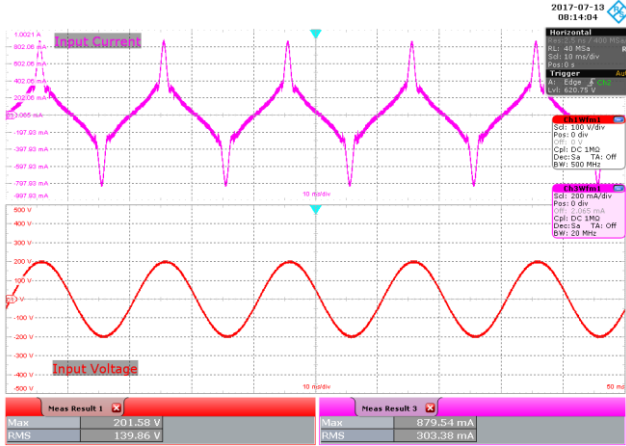


Figure 25 – 140 VAC 50 Hz, Full Load.
Upper: I_{IN} , 200 mA / div.
Lower: V_{IN} , 100 V / div., 10 ms / div.

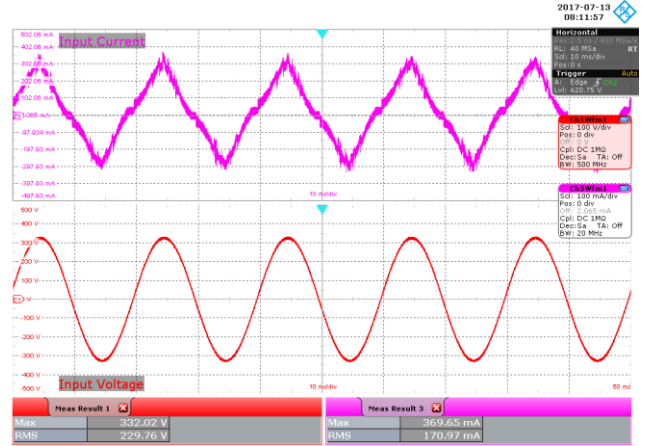


Figure 26 – 230 VAC 50 Hz, Full Load.
Upper: I_{IN} , 100 mA / div.
Lower: V_{IN} , 100 V / div., 10 ms / div.

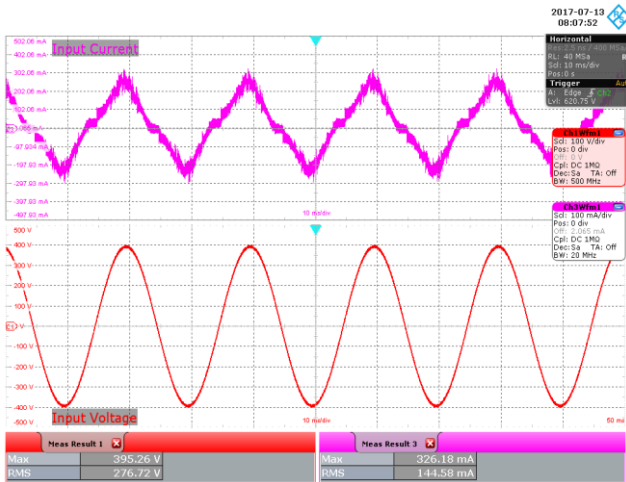


Figure 27 – 277 VAC 50 Hz, Full Load.
Upper: I_{IN} , 100 mA / div.
Lower: V_{IN} , 100 V / div., 10 ms / div.

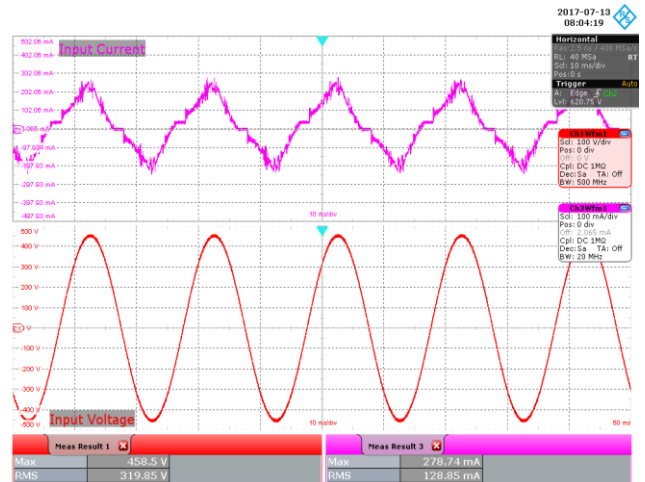


Figure 28 – 320 VAC 50 Hz, Full Load.
Upper: I_{IN} , 100 mA / div.
Lower: V_{IN} , 100 V / div., 10 ms / div.

14.2 **Start-up Profile at Full Load**

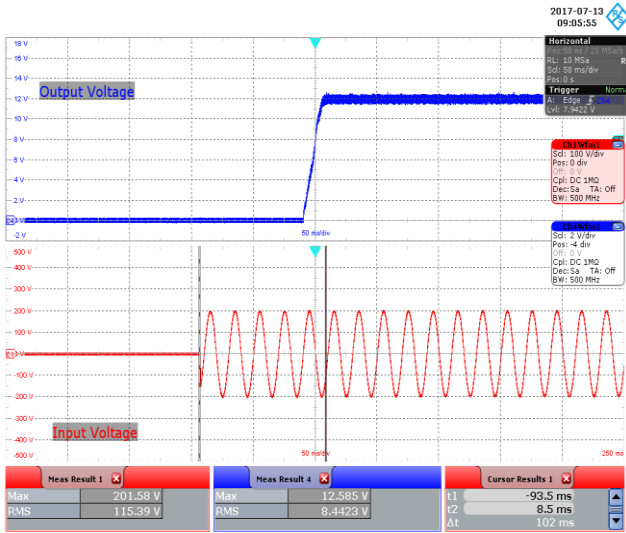


Figure 29 – 140 VAC 50 Hz, Full Load Start-up.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Turn on Time: 102 ms.

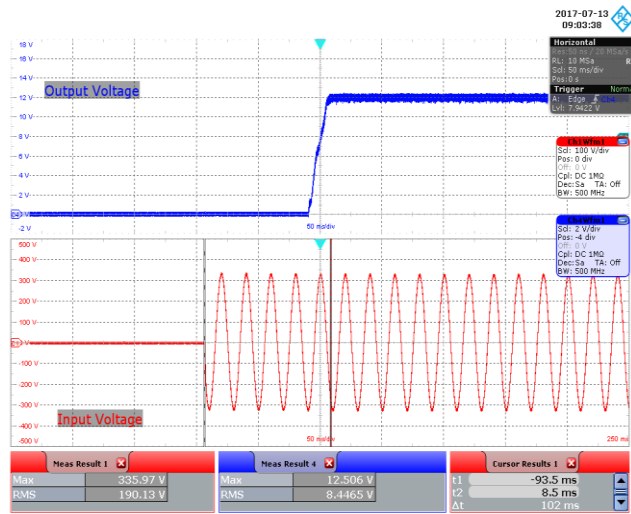


Figure 30 – 230 VAC 50 Hz, Full Load Start-up.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Turn on Time: 102 ms.

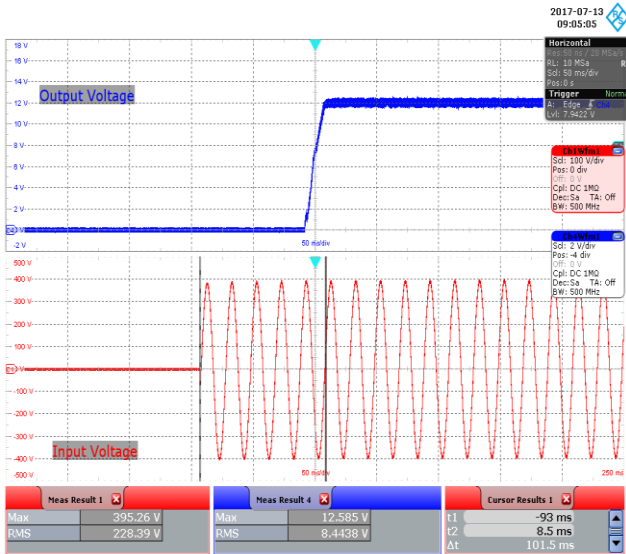


Figure 31 – 277 VAC 50 Hz, Full Load Start-up.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Turn on Time: 101.5 ms.

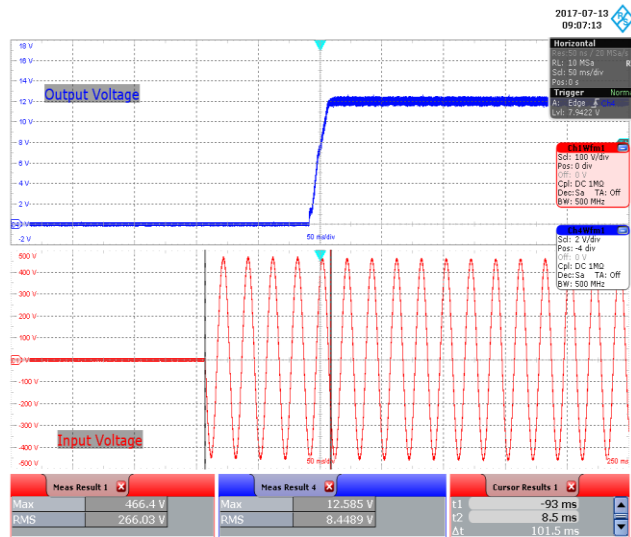


Figure 32 – 320 VAC 50 Hz, Full Load Start-up.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Turn on Time: 101.5 ms.

14.3 **Output Voltage Fall**

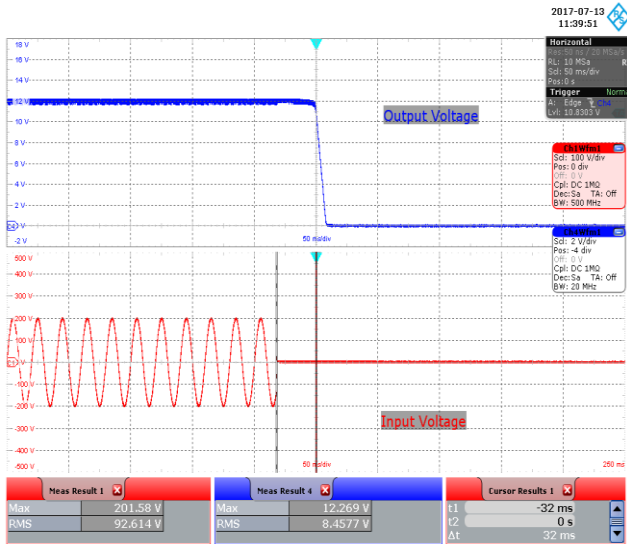


Figure 33 – 140 VAC 50 Hz, Full Load, Output Fall.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Hold Up Time: 32 ms.

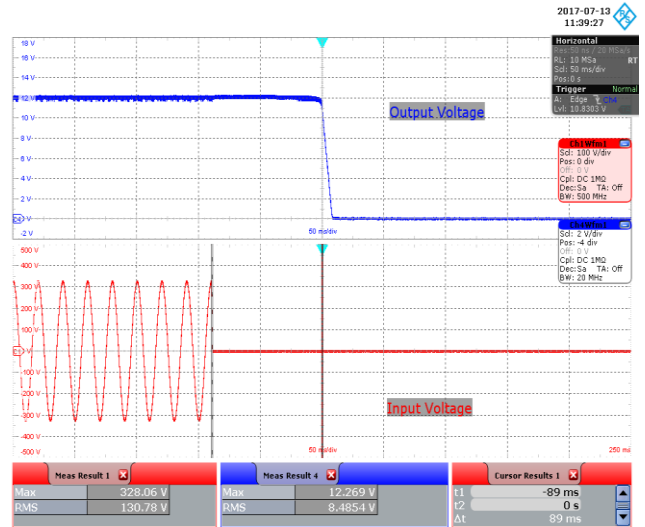


Figure 34 – 230 VAC 50 Hz, Full Load, Output Fall.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Hold Up Time: 89 ms.

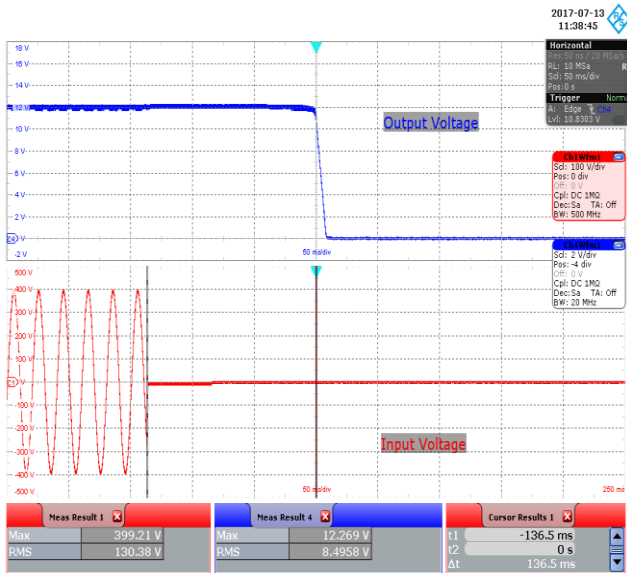


Figure 35 – 277 VAC 50 Hz, Full Load, Output Fall.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Hold Up Time: 136.5 ms.

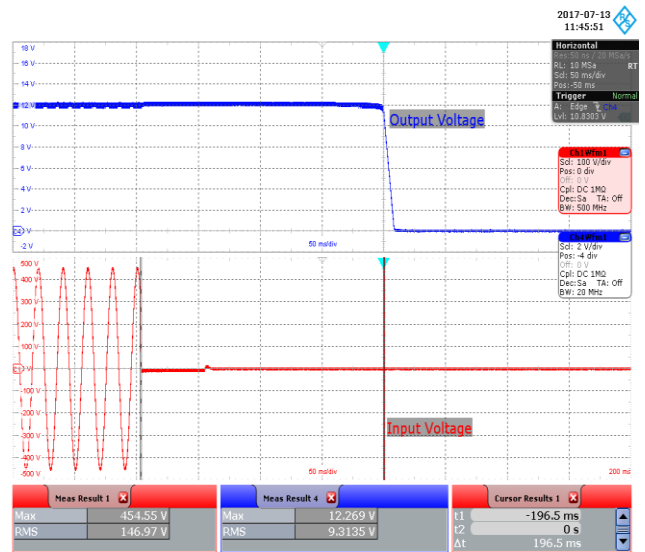


Figure 36 – 320 VAC 50 Hz, Full Load, Output Fall.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 50 ms / div.
 Hold Up Time: 196.5 ms.



14.4 Power Cycling

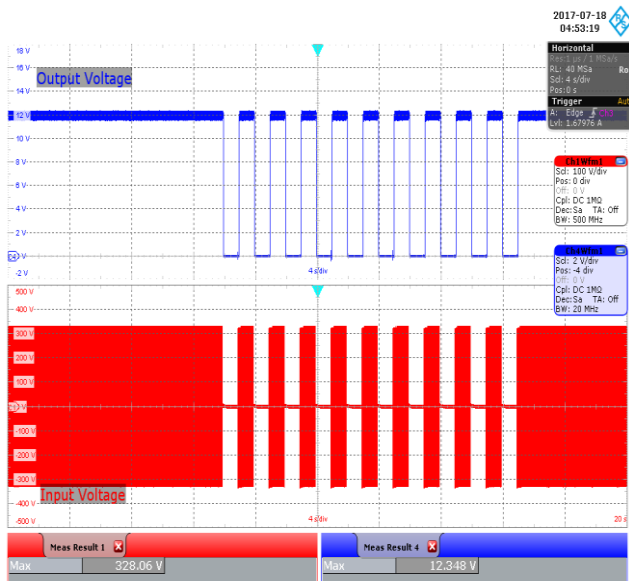


Figure 37 – 230 VAC 50 Hz, Full Load.
 1 s Off, 1 s On.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 4 s / div.

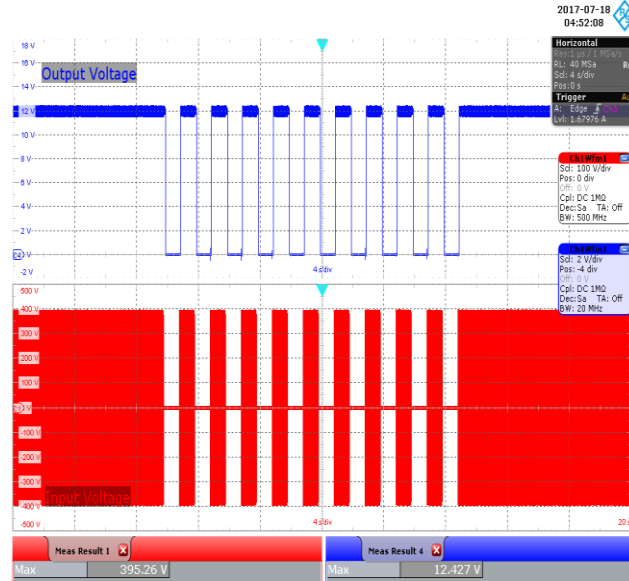


Figure 38 – 277 VAC 50 Hz, Full Load.
 1 s Off, 1 s On.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 4 s / div.

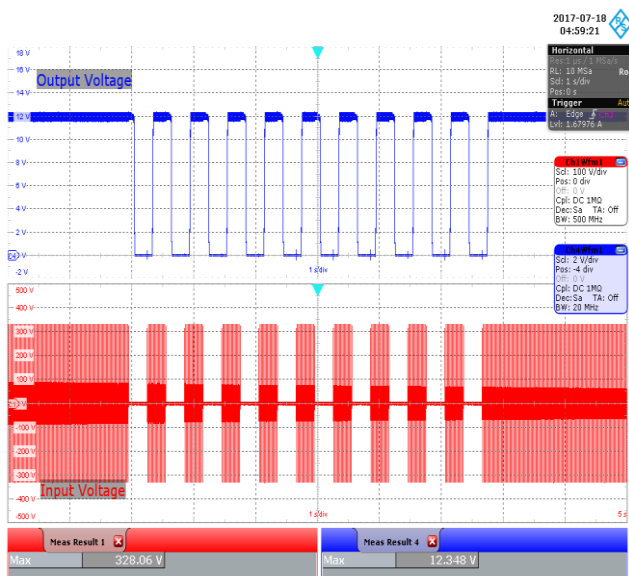


Figure 39 – 230 VAC 50 Hz, Full Load.
 0.3 s Off, 0.3 s On.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 1 s / div.

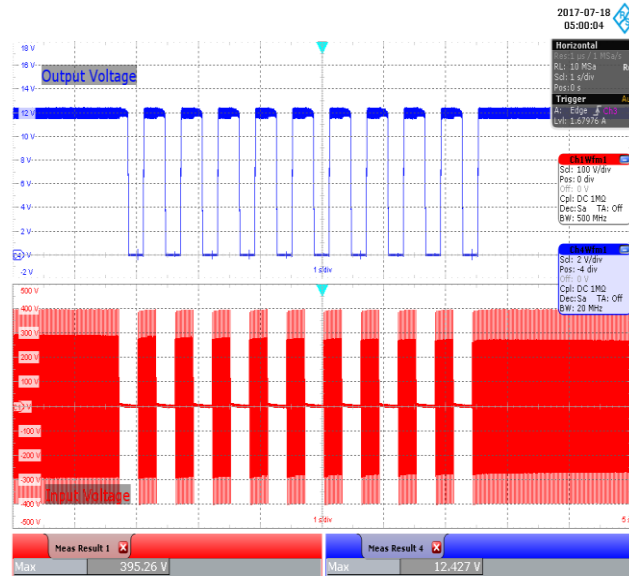


Figure 40 – 277 VAC 50 Hz, Full Load.
 0.3 s Off, 0.3 s On.
 Upper: V_{OUT} , 2 V / div.
 Lower: V_{IN} , 100 V / div., 1 s / div.



14.5 Load Transient Response 3 Hz

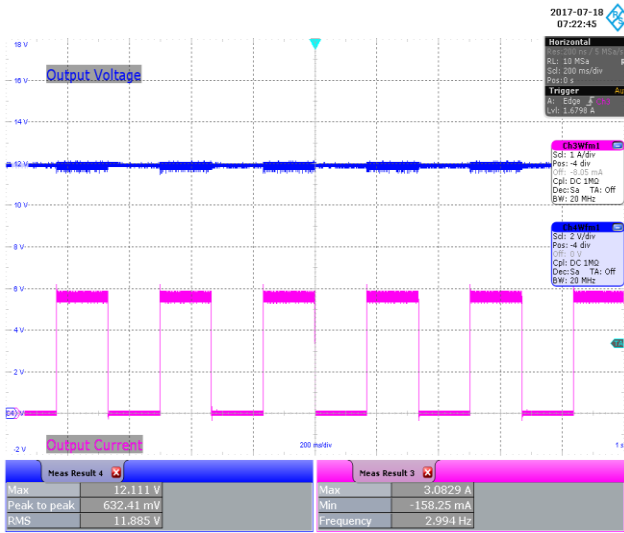


Figure 41 – 230 VAC 50 Hz.
 0% to 100% Load Change.
 3 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 200 ms / div.
 Lower: I_{OUT} , 1 A / div.

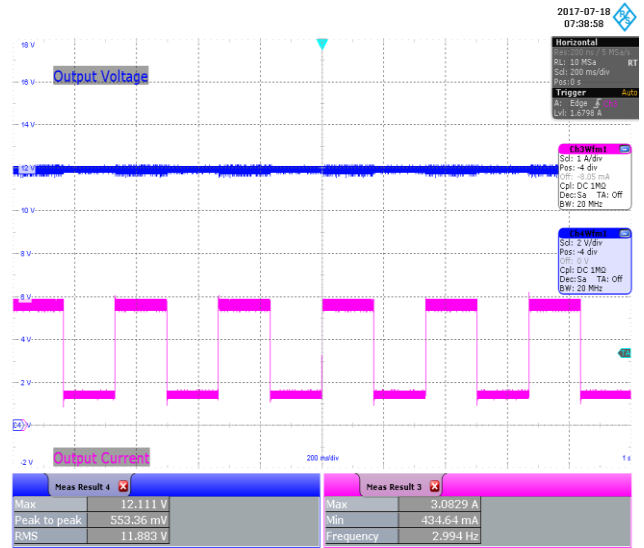


Figure 42 – 230 VAC 50 Hz.
 25% to 100% Load Change.
 3 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 200 ms / div.
 Lower: I_{OUT} , 1 A / div.

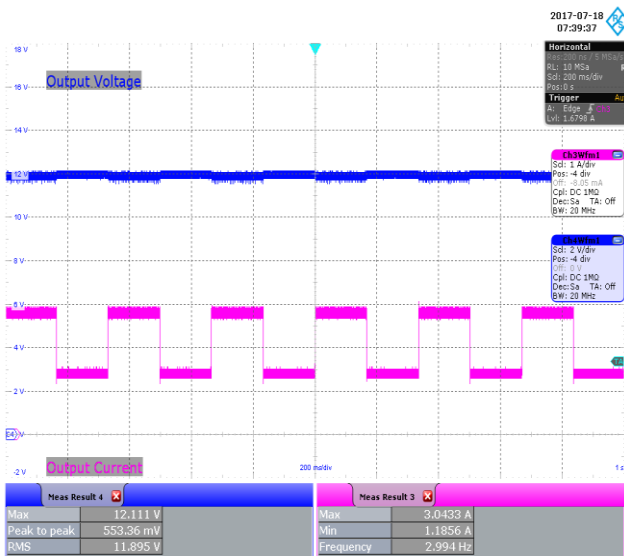


Figure 43 – 230 VAC 50 Hz.
 50% to 100% Load Change.
 3 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 200 ms / div.
 Lower: I_{OUT} , 1 A / div.

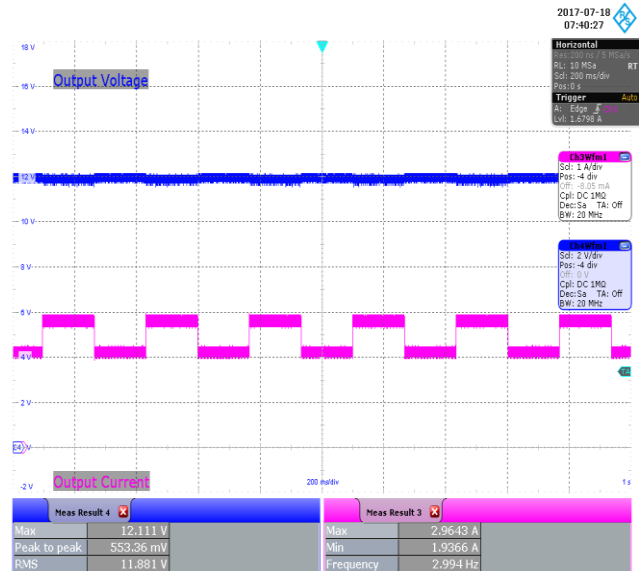


Figure 44 – 230 VAC 50 Hz.
 75% to 100% Load Change.
 3 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 200 ms / div.
 Lower: I_{OUT} , 1 A / div.



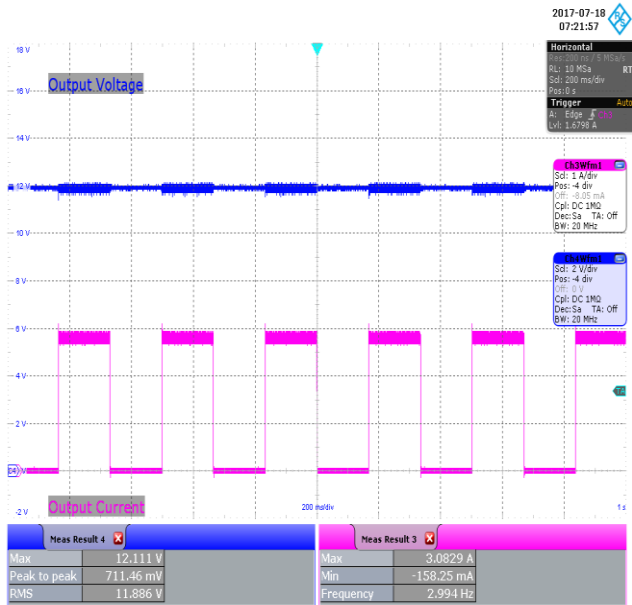


Figure 45 – 277 VAC 50 Hz.
0% to 100% Load Change.
3 Hz, 50% Duty Cycle.
Slew Rate: 800 mA / μ s.
Upper: V_{OUT} , 2 V / div., 200 ms / div.
Lower: I_{OUT} , 1 A / div.

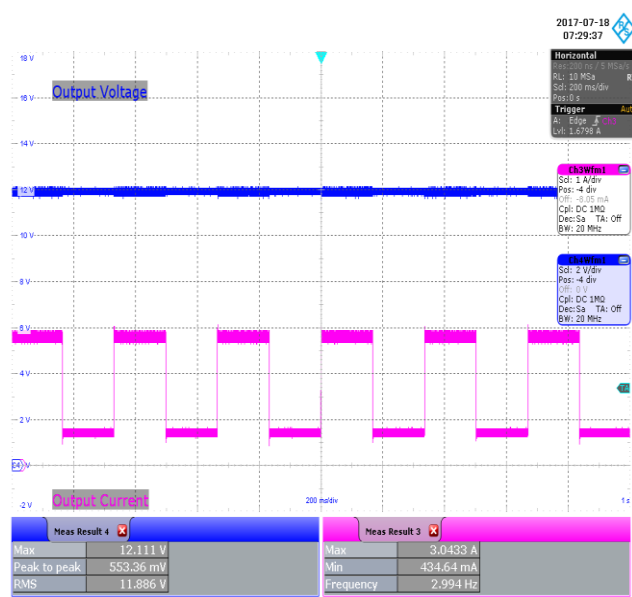


Figure 46 – 277 VAC 50 Hz.
25% to 100% Load Change.
3 Hz, 50% Duty Cycle.
Slew Rate: 800 mA / μ s.
Upper: V_{OUT} , 2 V / div., 200 ms / div.
Lower: I_{OUT} , 1 A / div.

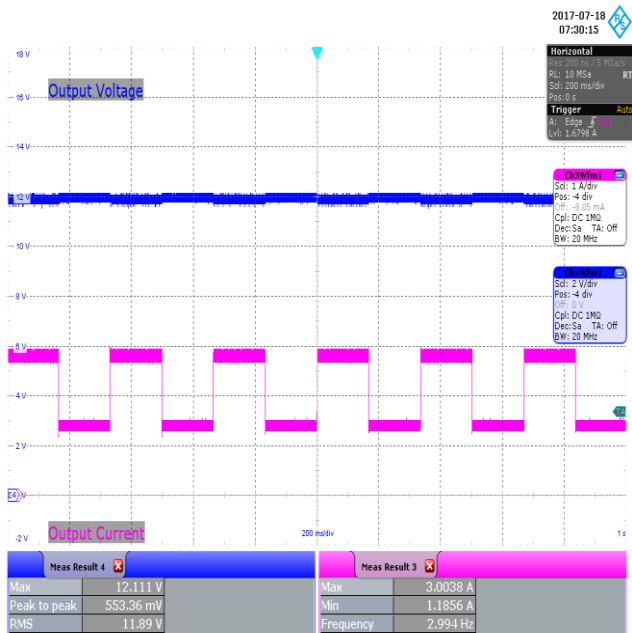


Figure 47 – 277 VAC 50 Hz.
50% to 100% Load Change.
3 Hz, 50% Duty Cycle.
Slew Rate: 800 mA / μ s.
Upper: V_{OUT} , 2 V / div., 200 ms / div.
Lower: I_{OUT} , 1 A / div.

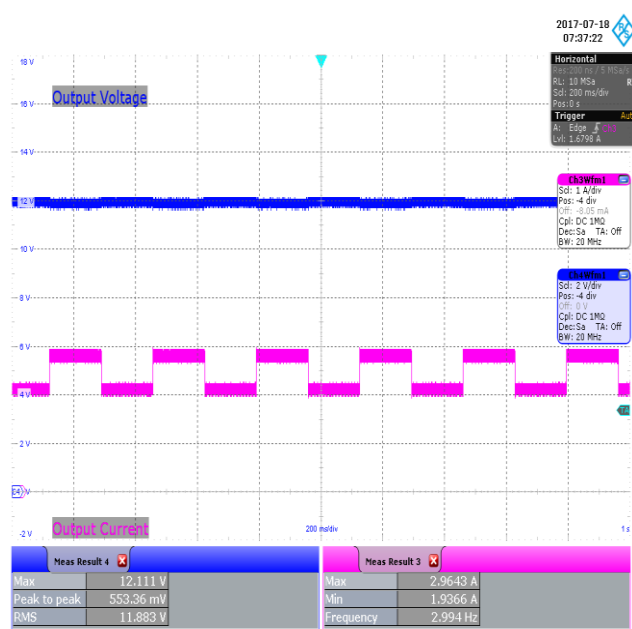


Figure 48 – 277 VAC 50 Hz.
75% to 100% Load Change.
3 Hz, 50% Duty Cycle.
Slew Rate: 800 mA / μ s.
Upper: V_{OUT} , 2 V / div., 200 ms / div.
Lower: I_{OUT} , 1 A / div.

14.6 **Load Transient Response 100 Hz**

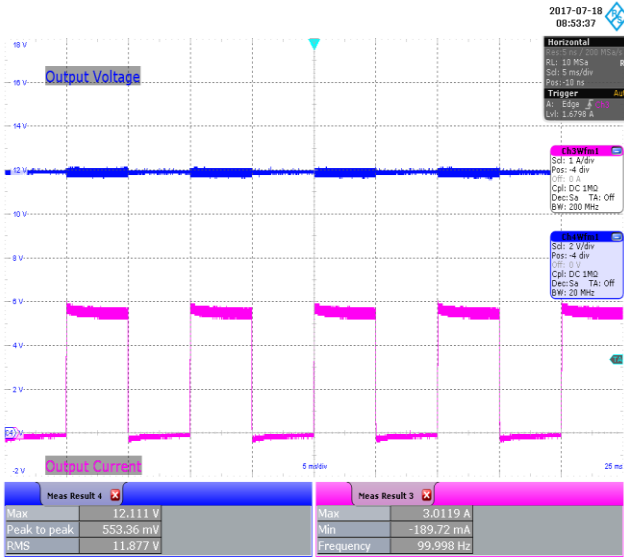


Figure 49 – 230 VAC 50 Hz.
 0% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

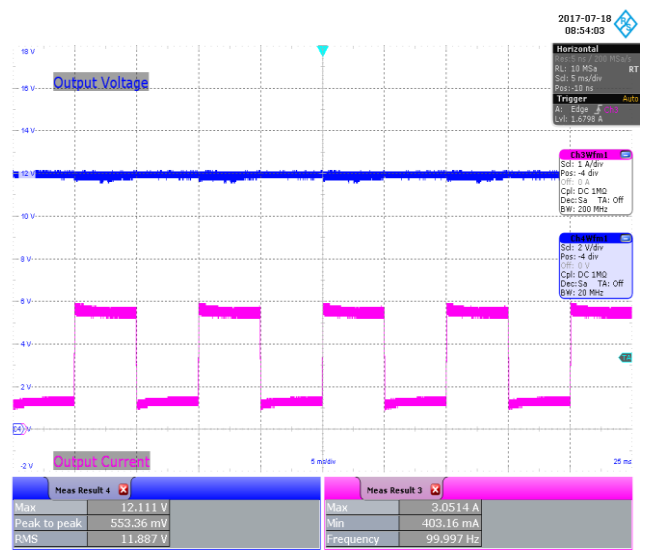


Figure 50 – 230 VAC 50 Hz.
 25% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

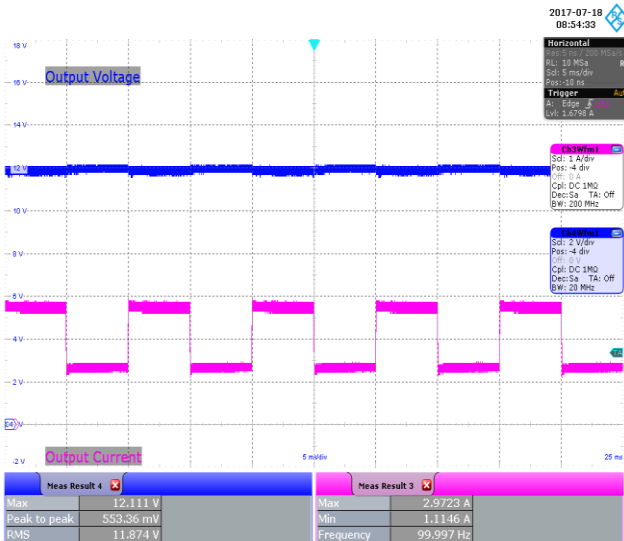


Figure 51 – 230 VAC 50 Hz.
 50% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

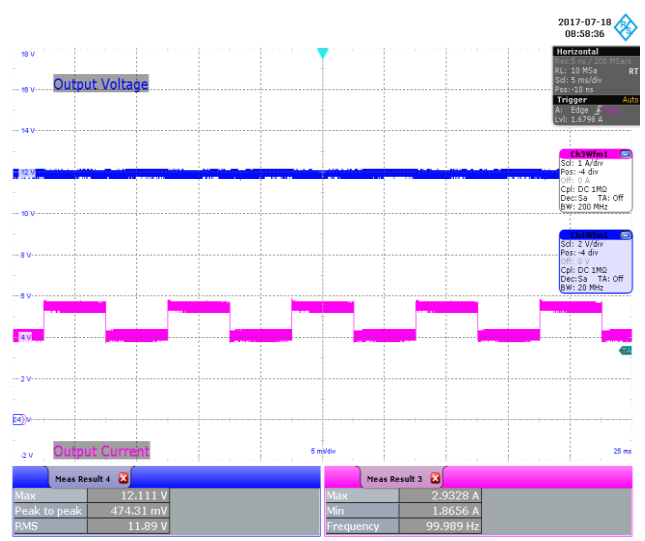


Figure 52 – 230 VAC 50 Hz.
 75% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.



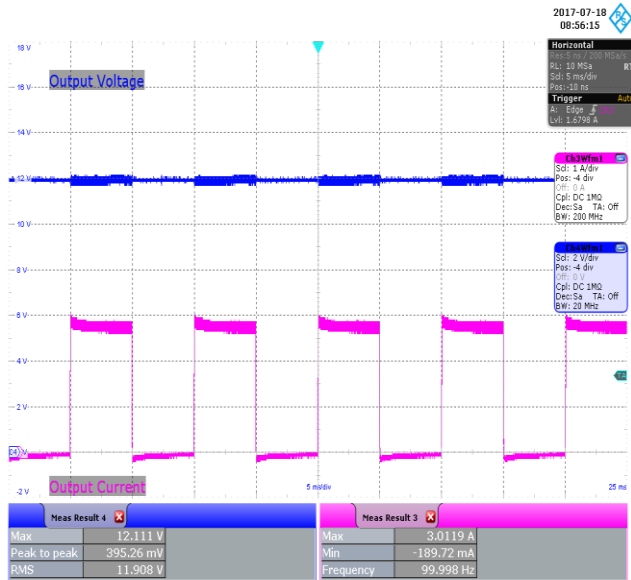


Figure 53 – 277 VAC 50 Hz.
 0% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

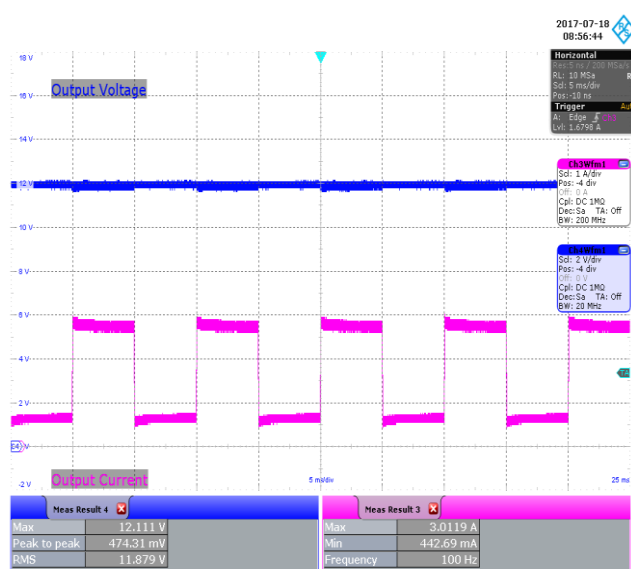


Figure 54 – 277 VAC 50 Hz.
 25% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

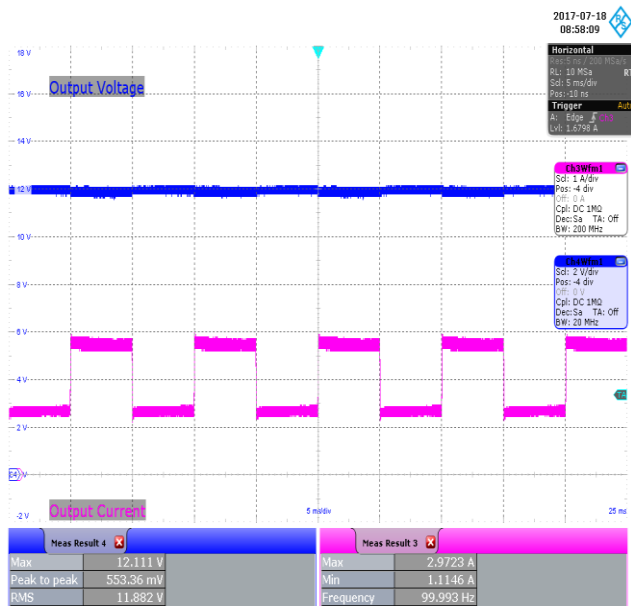


Figure 55 – 277 VAC 50 Hz.
 50% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

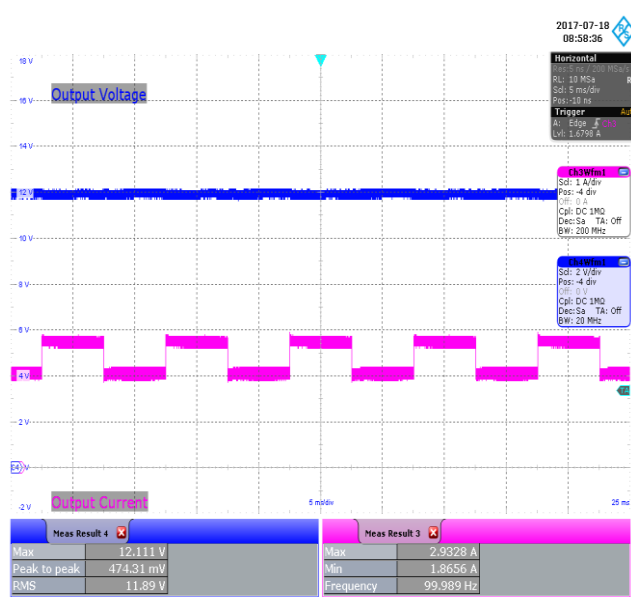


Figure 56 – 277 VAC 50 Hz.
 75% to 100% Load Change.
 100 Hz, 50% Duty Cycle.
 Slew Rate: 800 mA / μ s.
 Upper: V_{OUT} , 2 V / div., 5 ms / div.
 Lower: I_{OUT} , 1 A / div.

14.7 LYTSwitch-6 Drain Voltage and Current Waveforms at Normal Operation

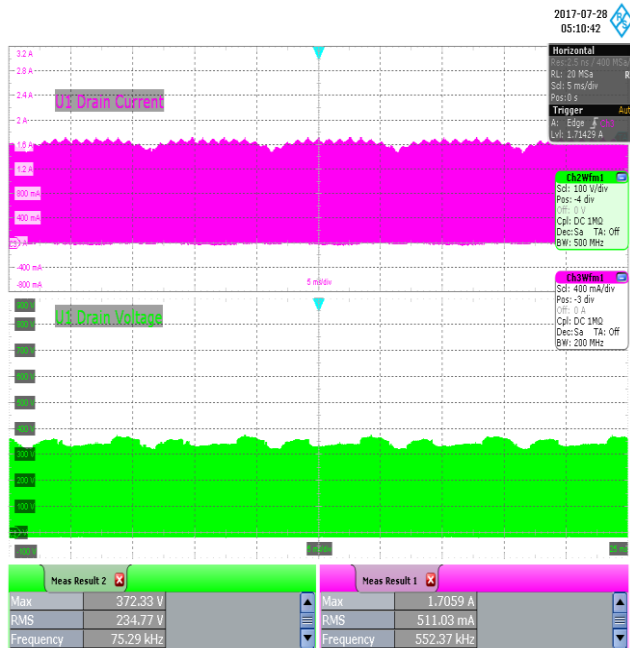


Figure 57 – 140 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 5 ms / div.

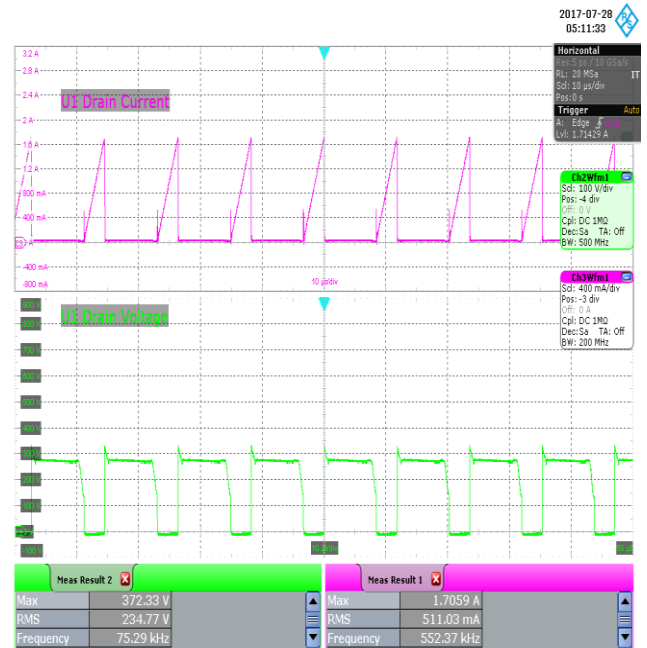


Figure 58 – 140 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 10 μ s / div.

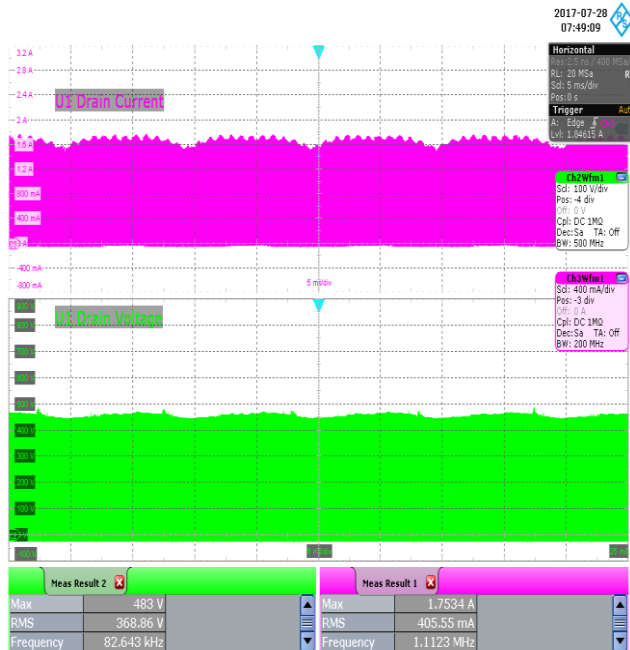


Figure 59 – 230 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 5 ms / div.

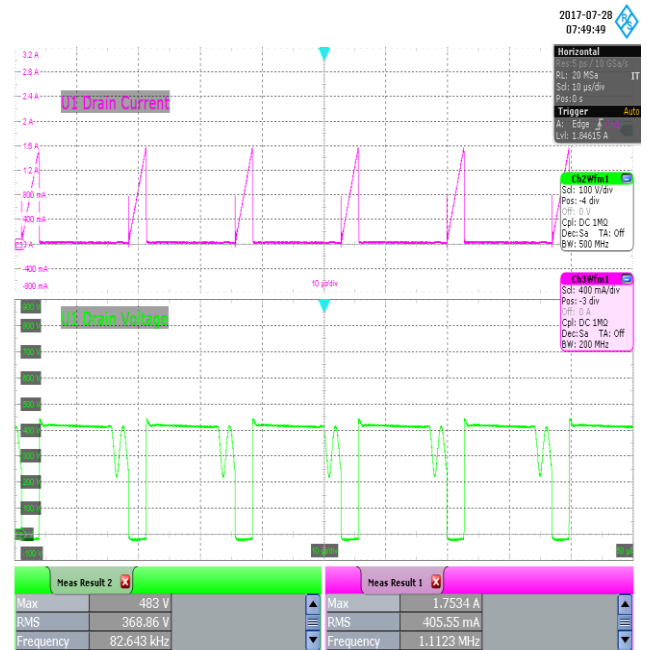


Figure 60 – 230 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 10 μ s / div.





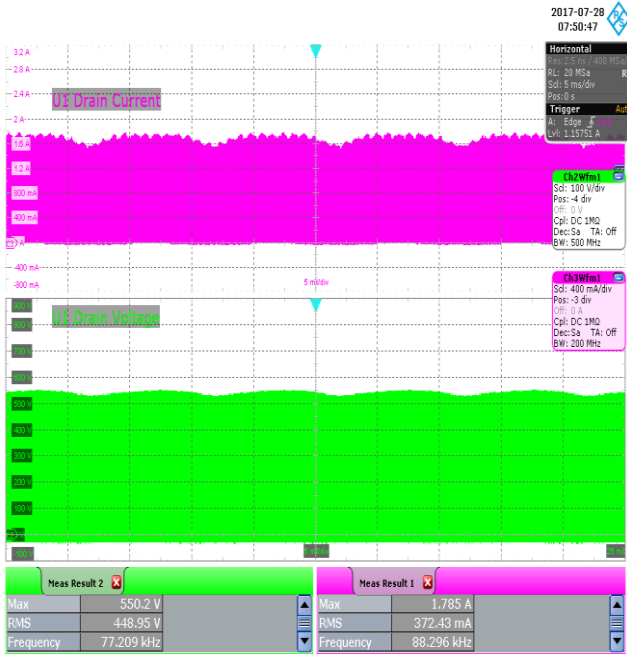


Figure 61 – 277 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 5 ms / div.

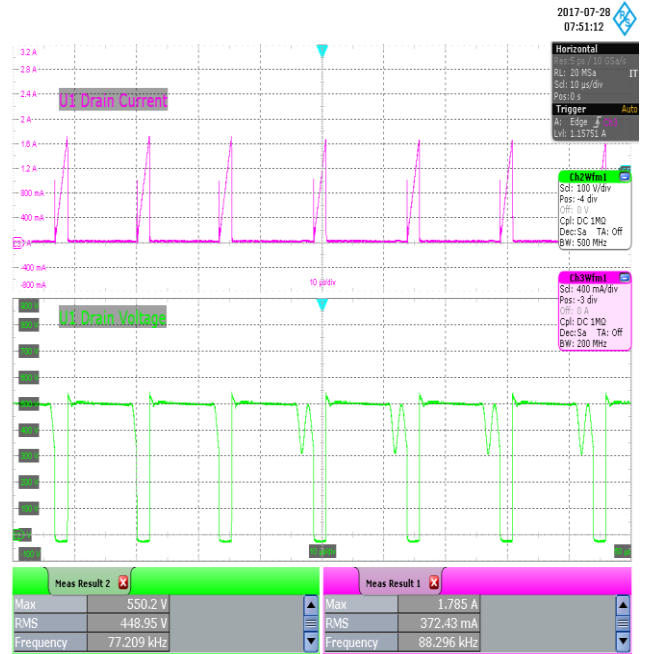


Figure 62 – 277 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 10 μ s / div.

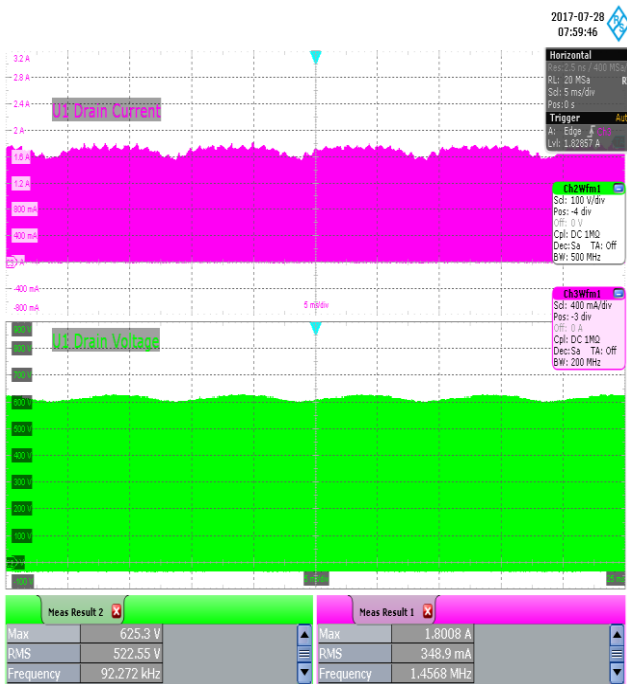


Figure 63 – 320 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 5 ms / div.

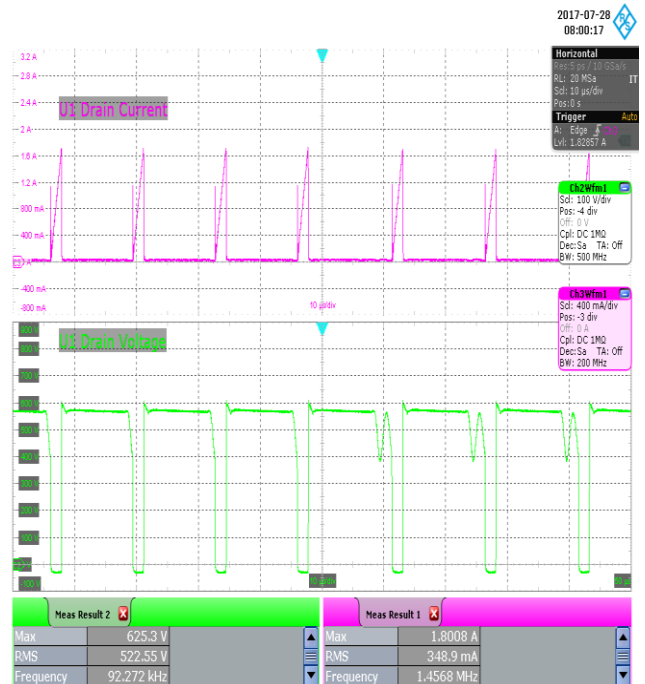


Figure 64 – 320 VAC 50 Hz, Full Load Normal.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 10 μ s / div.



14.8 **LYTSwitch-6 Drain Voltage and Current at Full Load Start-up**

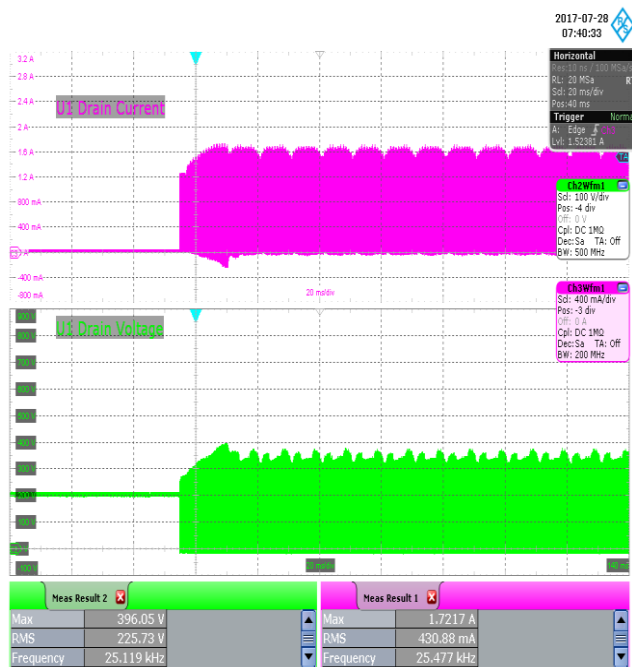


Figure 65 – 140 VAC 50 Hz, Full Load Start-up.
Upper: I_{DRAIN}, 400 mA / div.
Lower: V_{DRAIN}, 100 V / div., 20 ms / div.

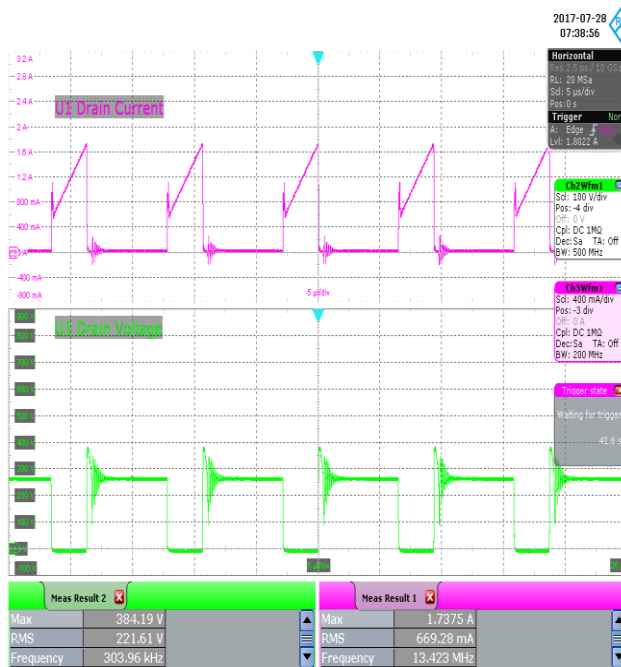


Figure 66 – 140 VAC 50 Hz, Full Load Start-up.
Upper: I_{DRAIN}, 400 mA / div.
Lower: V_{DRAIN}, 100 V / div., 5 μs / div.

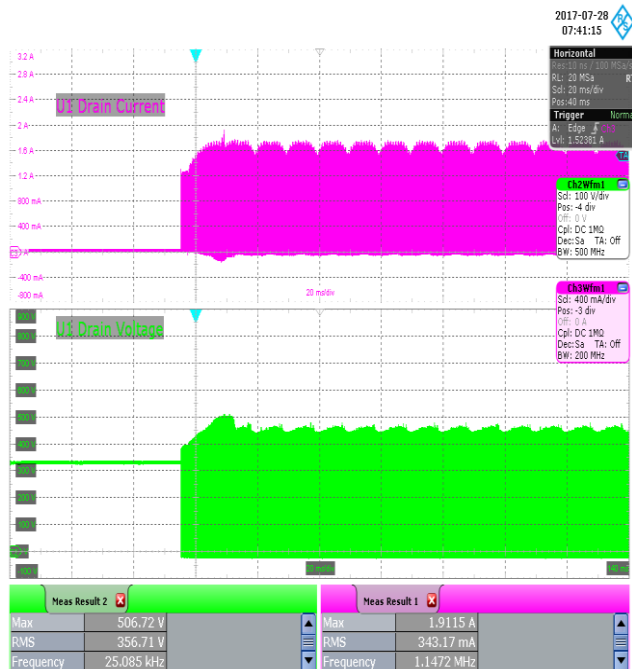


Figure 67 – 230 VAC, Full Load Start-up.
Upper: I_{DRAIN}, 400 mA / div.
Lower: V_{DRAIN}, 100 V / div., 20 ms / div.

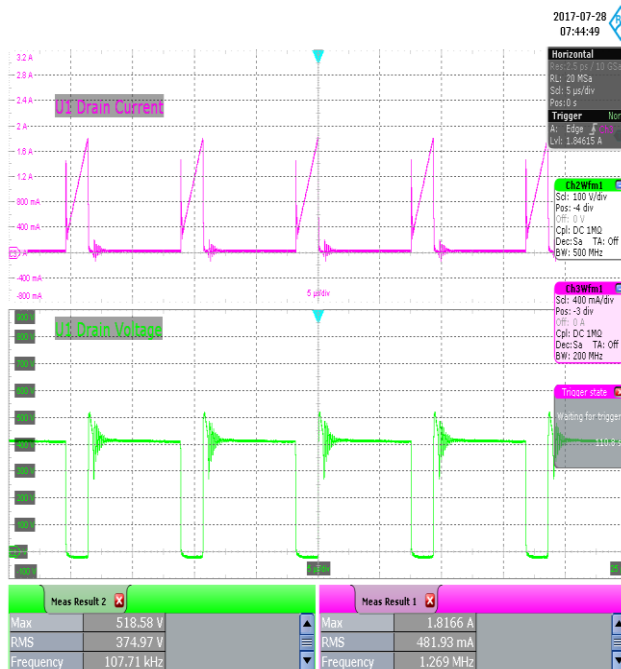


Figure 68 – 230 VAC, Full Load Start-up.
Upper: I_{DRAIN}, 400 mA / div.
Lower: V_{DRAIN}, 100 V / div., 5 μs / div.

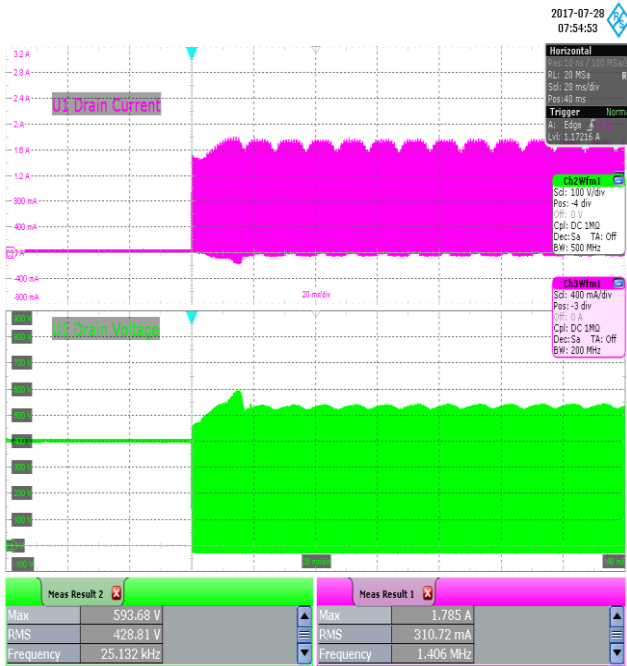


Figure 69 – 277 VAC 50 Hz, Full Load Start-up.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 20 ms / div.

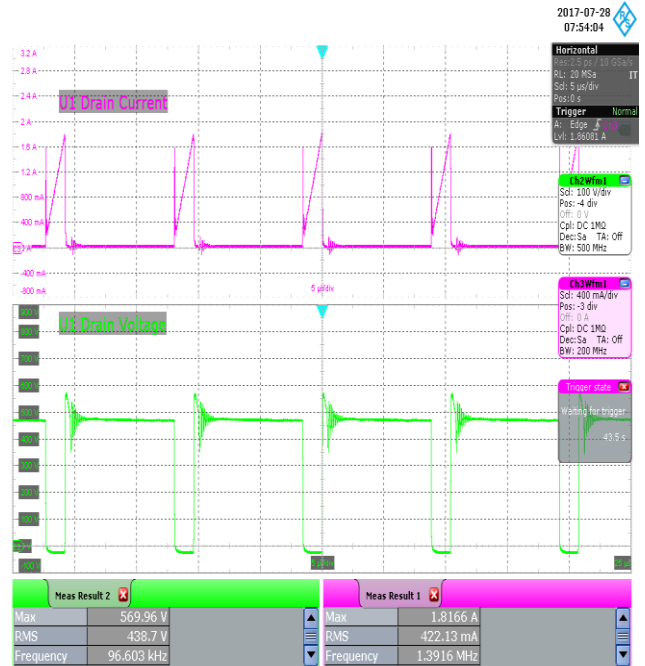


Figure 70 – 277 VAC 50 Hz, Full Load Start-up.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 5 μ s / div.

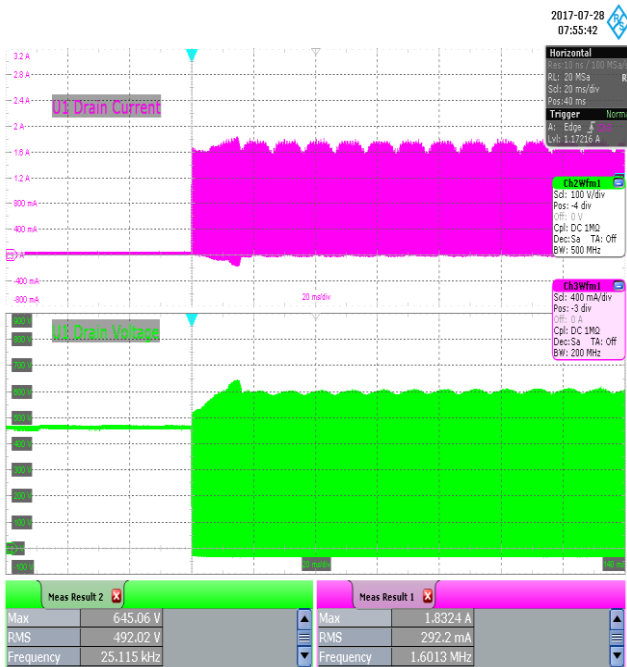


Figure 71 – 320 VAC, Full Load Start-up.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 20 ms / div.

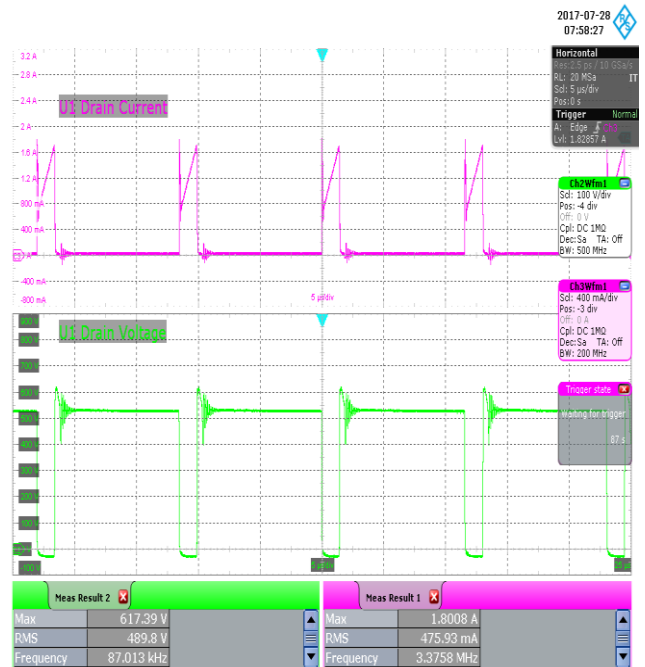


Figure 72 – 320 VAC, Full Load Start-up.
Upper: I_{DRAIN} , 400 mA / div.
Lower: V_{DRAIN} , 100 V / div., 5 μ s / div.



14.9 **LYTSwitch-6 Drain Voltage and Current during Output Short-Circuit**

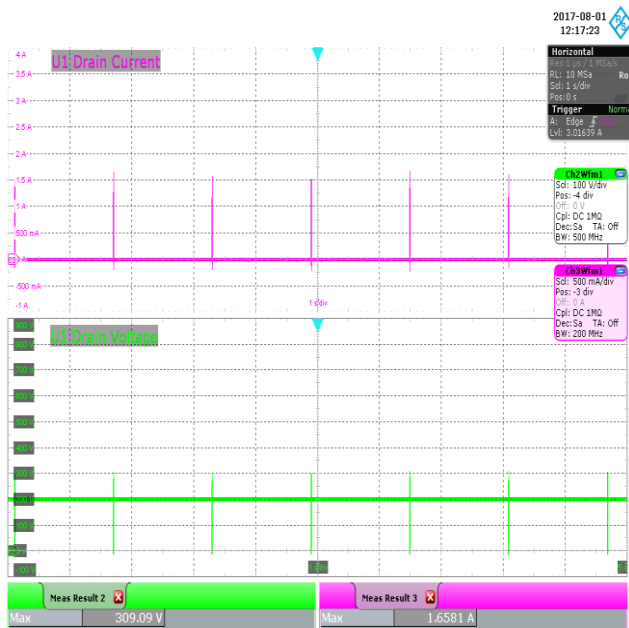


Figure 73 – 140 VAC 50 Hz, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 s / div.
 P_{IN} Average: 155.4 mW.

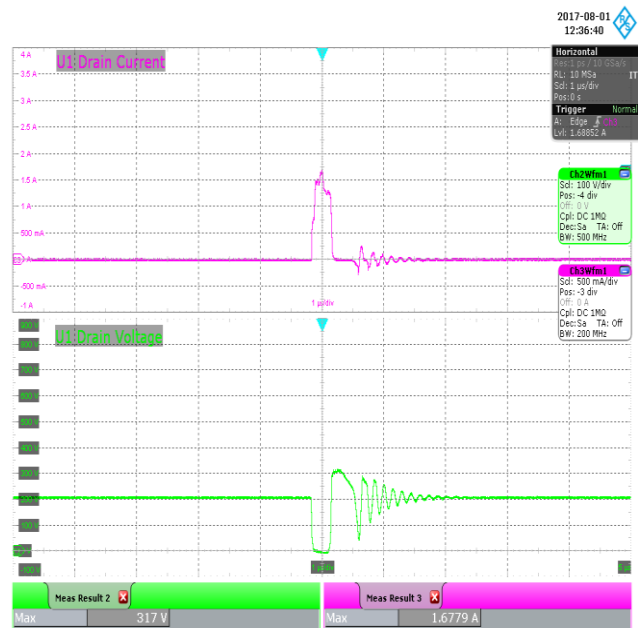


Figure 74 – 140 VAC 50 Hz, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 μs / div.

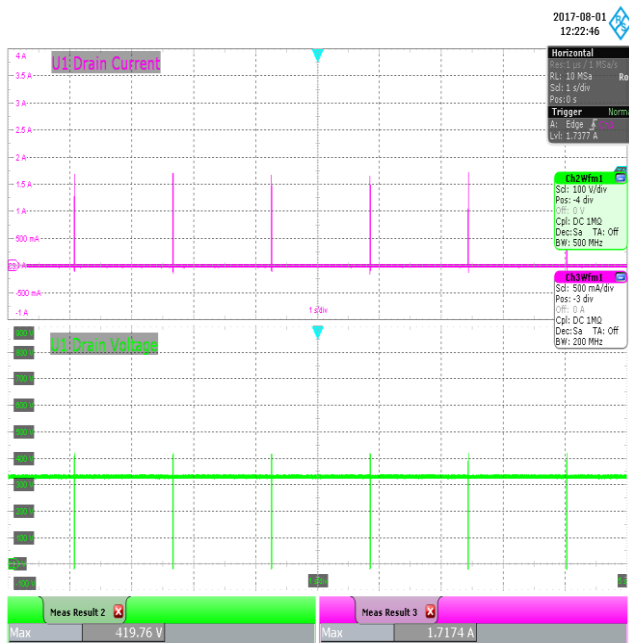


Figure 75 – 230 VAC, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 s / div.
 P_{IN} Average: 259.7 mW.

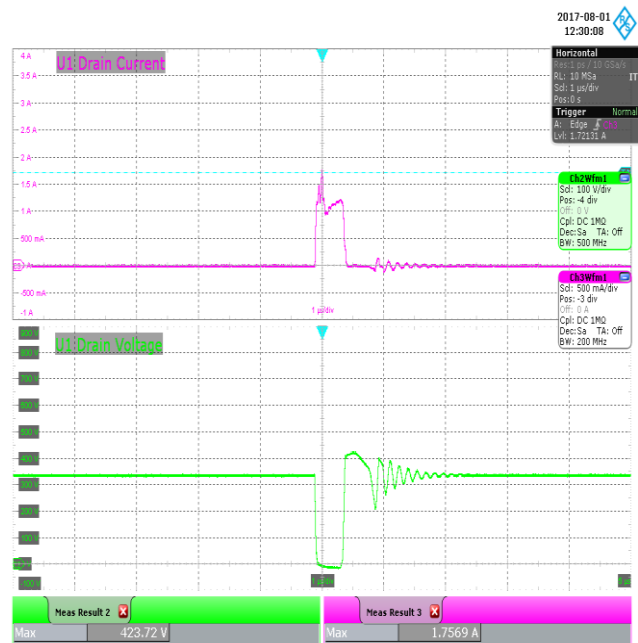


Figure 76 – 230 VAC, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 μs / div.

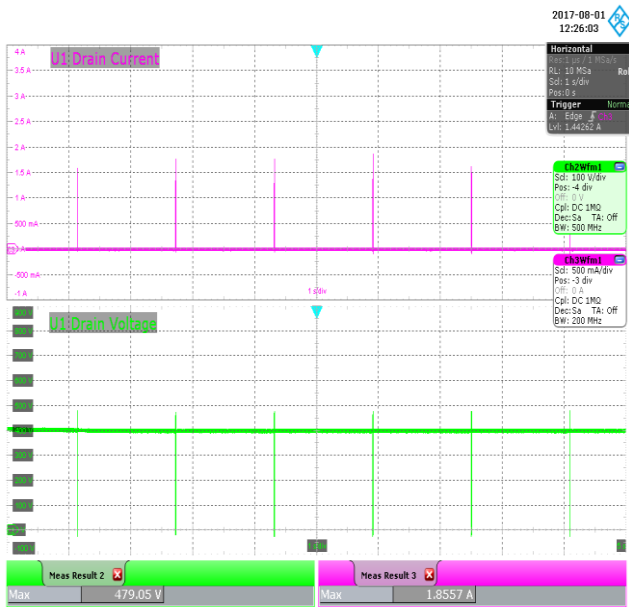


Figure 77 – 277 VAC 50 Hz, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 s / div.
 P_{IN} Average: 242.51 mW.

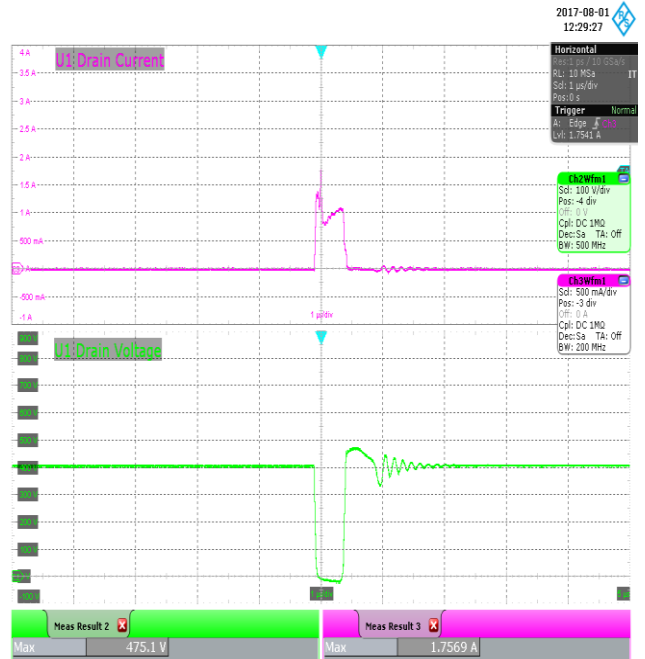


Figure 78 – 277 VAC 50 Hz, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 μ s / div.

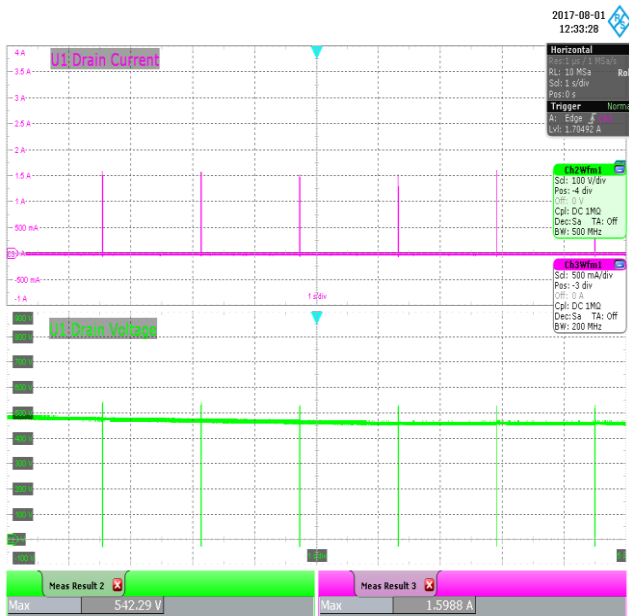


Figure 79 – 320 VAC, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 s / div.
 P_{IN} Average: 411.41 mW.

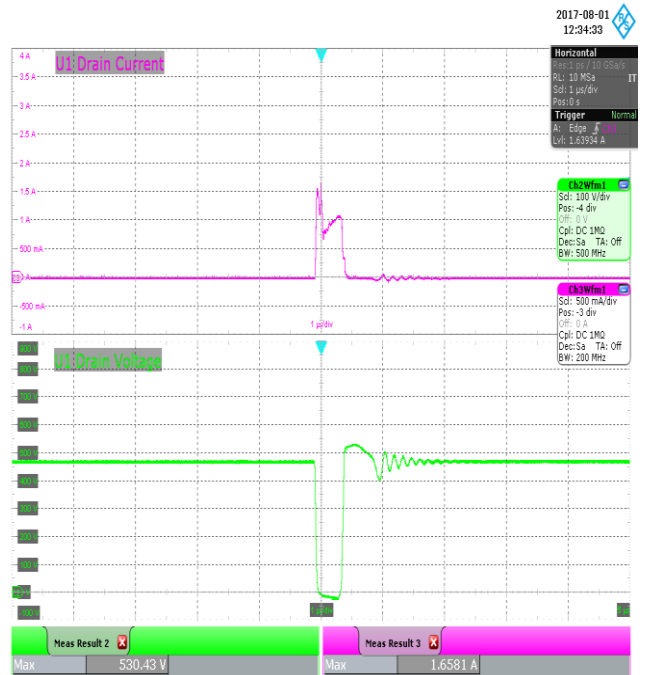


Figure 80 – 320 VAC, Output Shorted.
 Upper: I_{DRAIN} , 500 mA / div.
 Lower: V_{DRAIN} , 100 V / div., 1 μ s / div.



14.10 **PFC Diode Voltage and Current at Normal Operation**

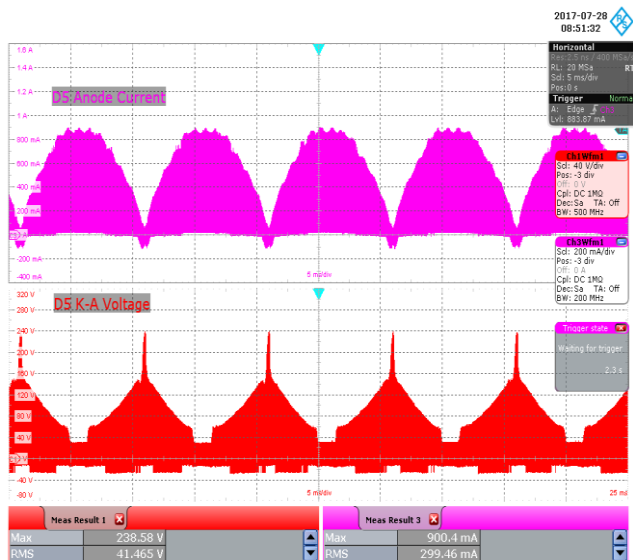


Figure 81 – 140 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 40 V / div.
 Horizontal: 5 ms / div.

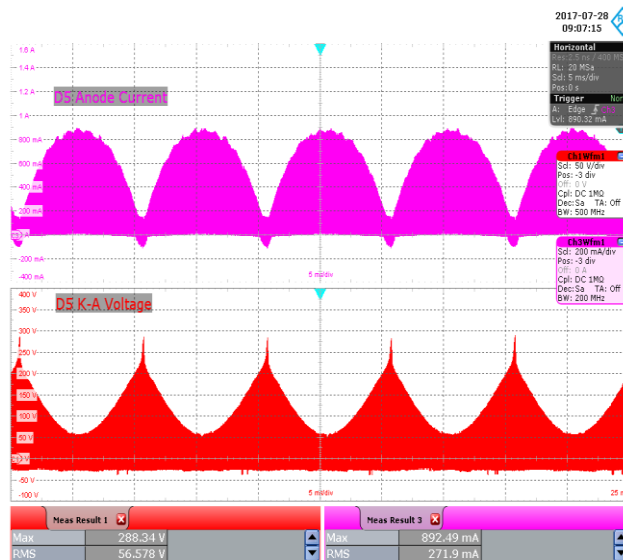


Figure 82 – 230 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 5 ms / div.

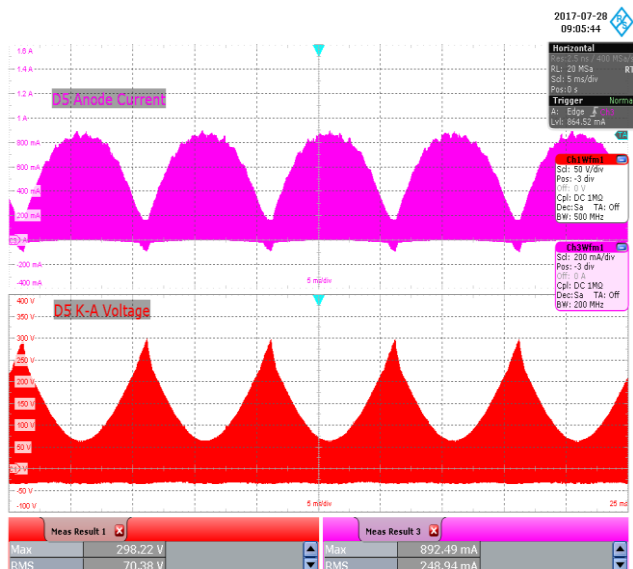


Figure 83 – 277 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 5 ms / div.

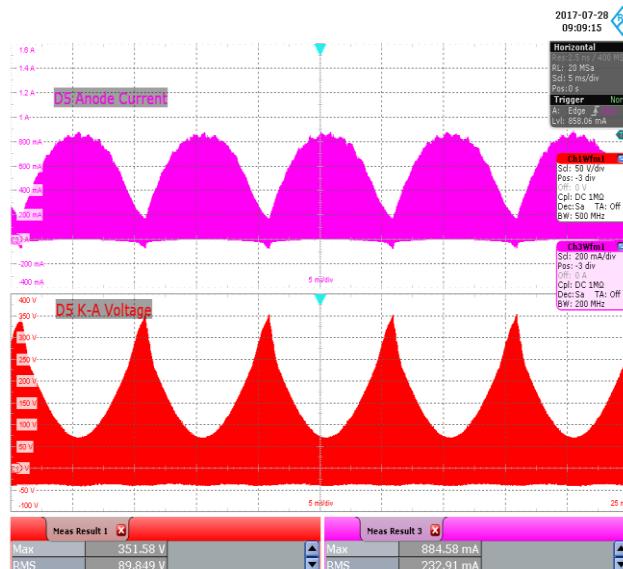


Figure 84 – 320 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 5 ms / div.

14.11 **PFC Diode Voltage and Current at Start-up Full Load**

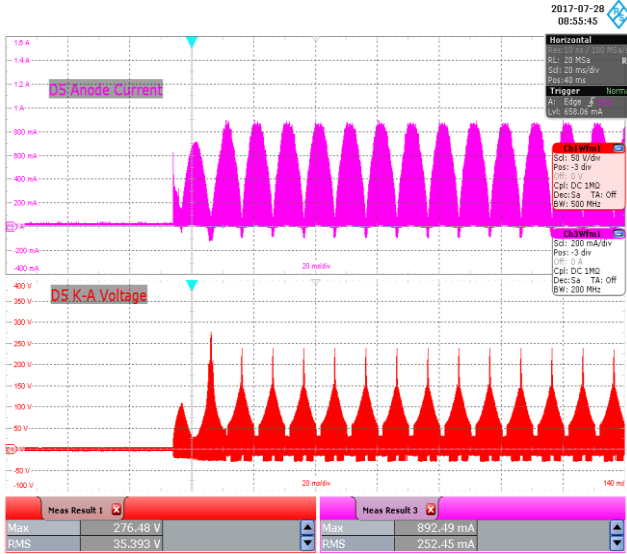


Figure 85 – 140 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 20 ms / div.

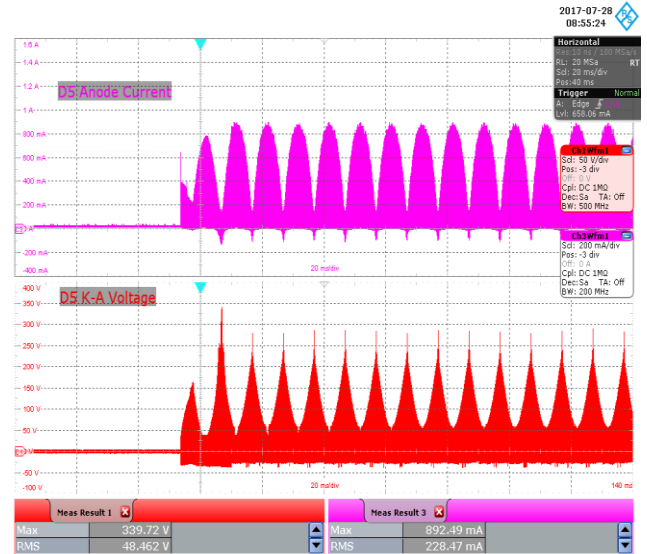


Figure 86 – 230 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 20 ms / div.

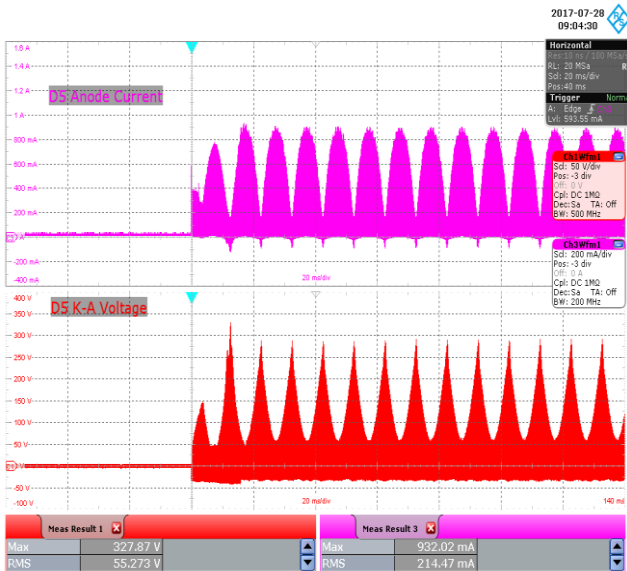


Figure 87 – 277 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 20 ms / div.

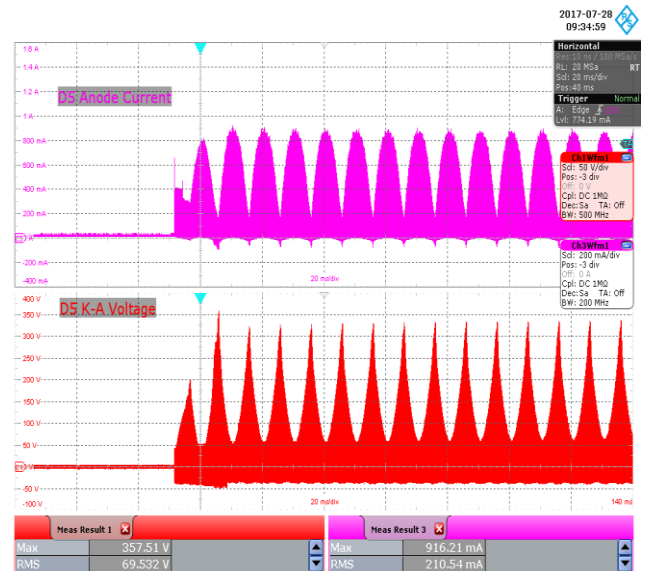


Figure 88 – 320 VAC 50 Hz, 2.92 A CC Load.
 Upper: 200 mA / div.
 Lower: 50 V / div.
 Horizontal: 20 ms / div.



14.12 **SR FET Drain Voltage and Current at Normal Operation**

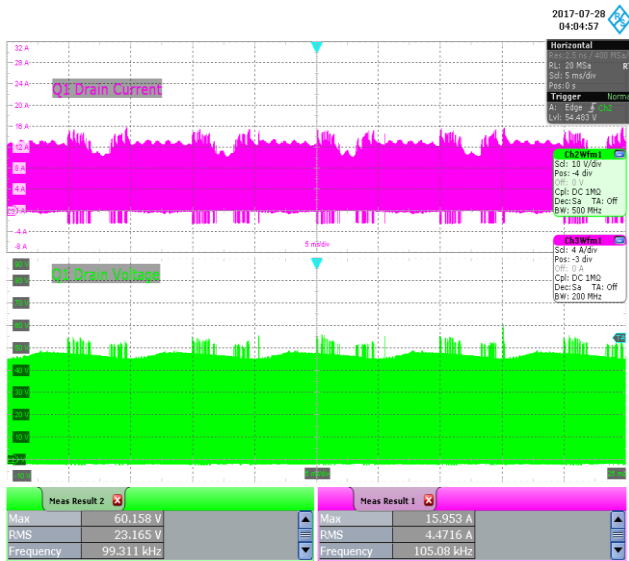


Figure 89 – 140 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 10 V / div.
 Horizontal: 5 ms / div.

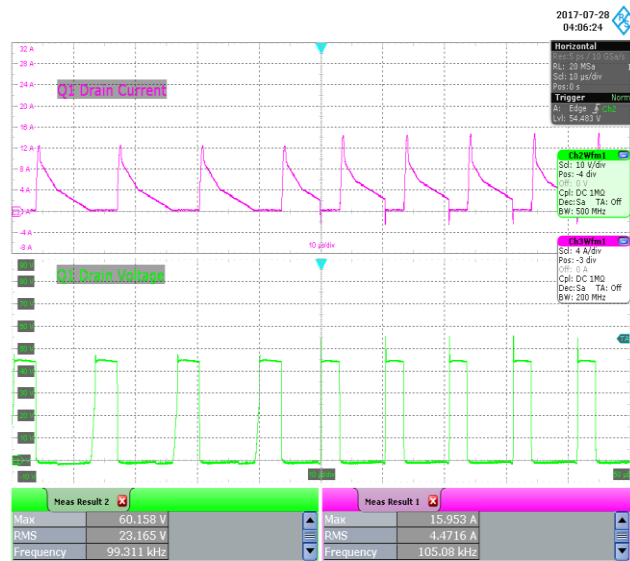


Figure 90 – 140 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 10 V / div.
 Horizontal: 10 μs / div.

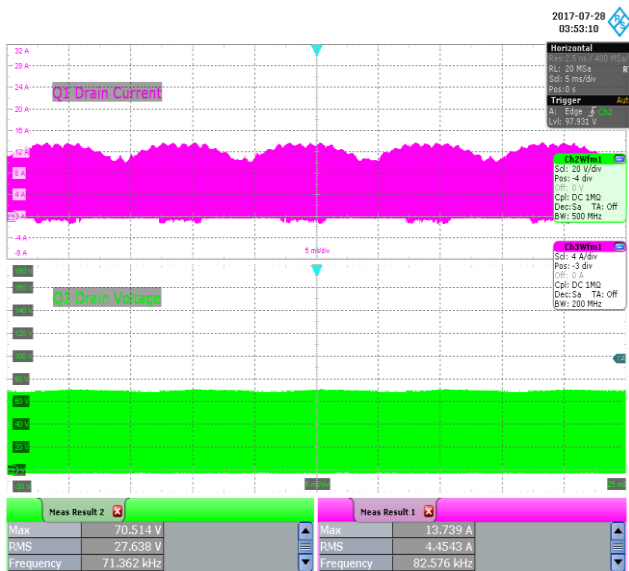


Figure 91 – 230 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 20 V / div.
 Horizontal: 5 ms / div.

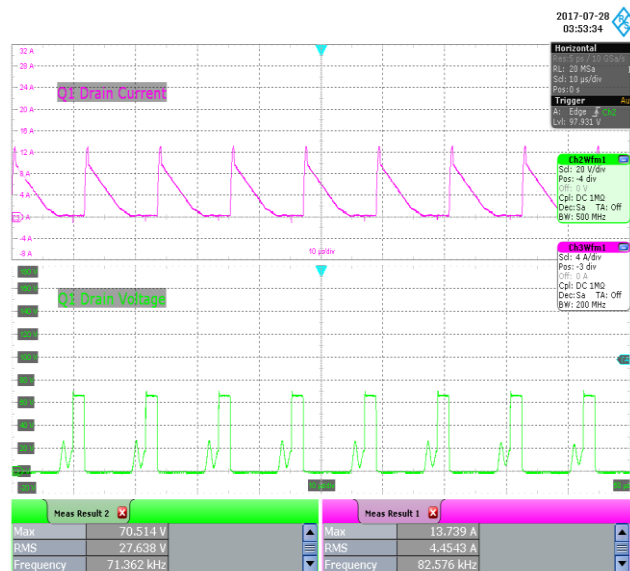


Figure 92 – 230 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 20 V / div.
 Horizontal: 10 μs / div.

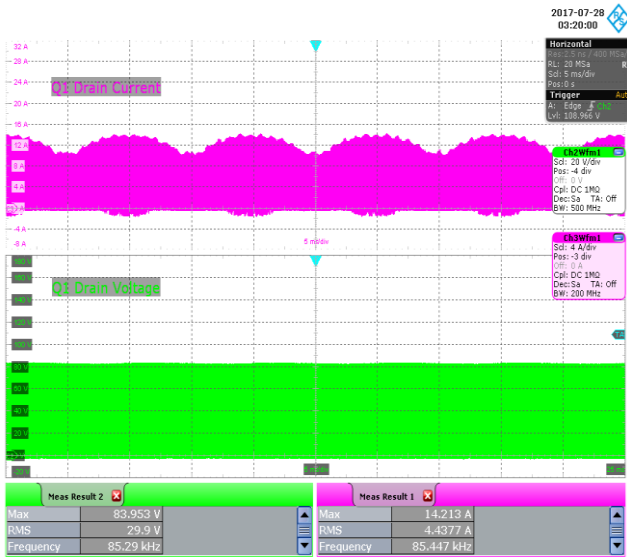


Figure 93 – 277 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 5 ms / div.

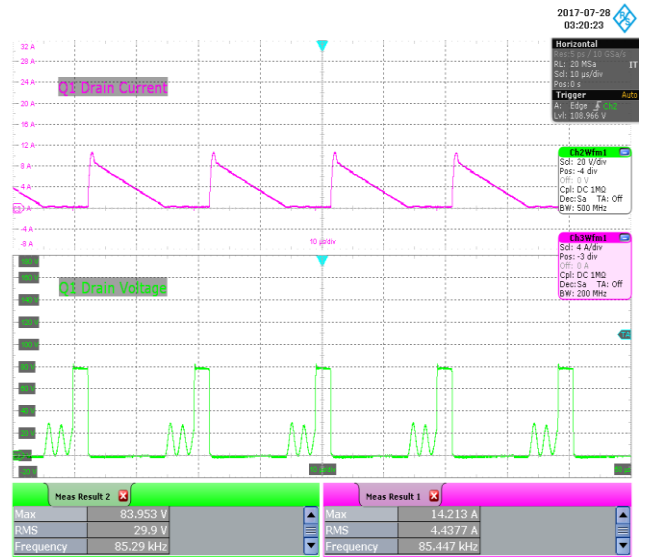


Figure 94 – 277 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 10 μs / div.

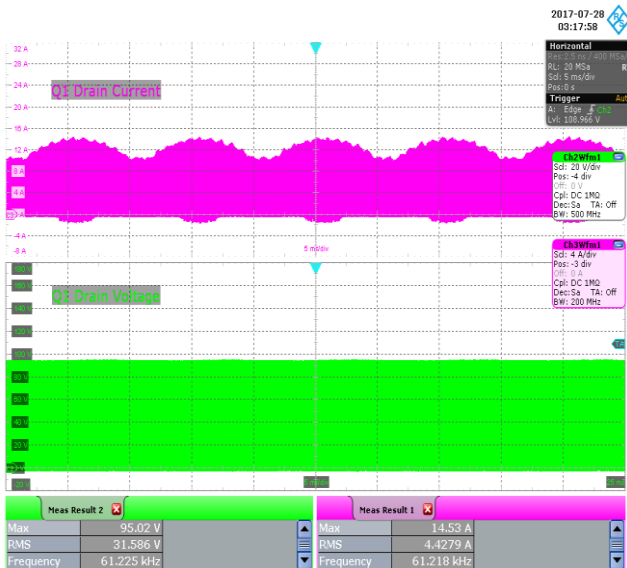


Figure 95 – 320 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 5 ms / div.

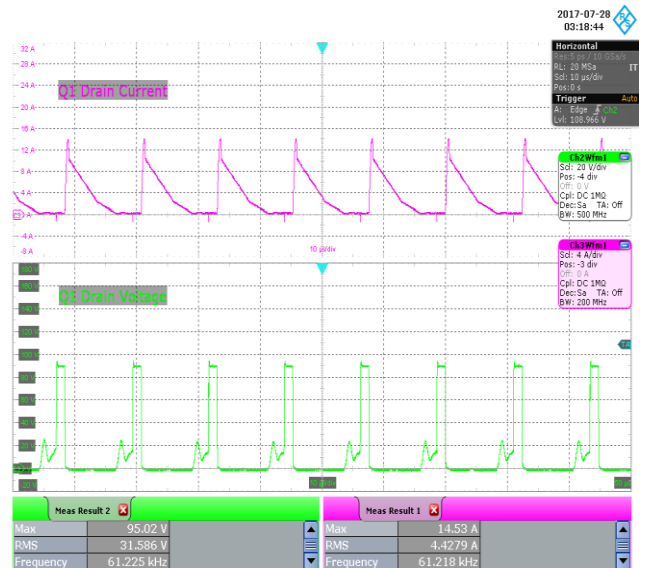


Figure 96 – 320 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 10 μs / div.



14.13 **SR FET Drain Voltage and Current at Full Load Start-up**

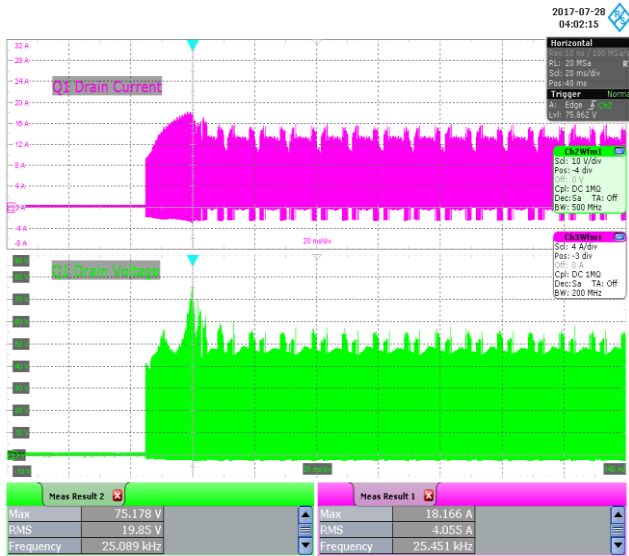


Figure 97 – 140 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 10 V / div.
 Horizontal: 20 ms / div.

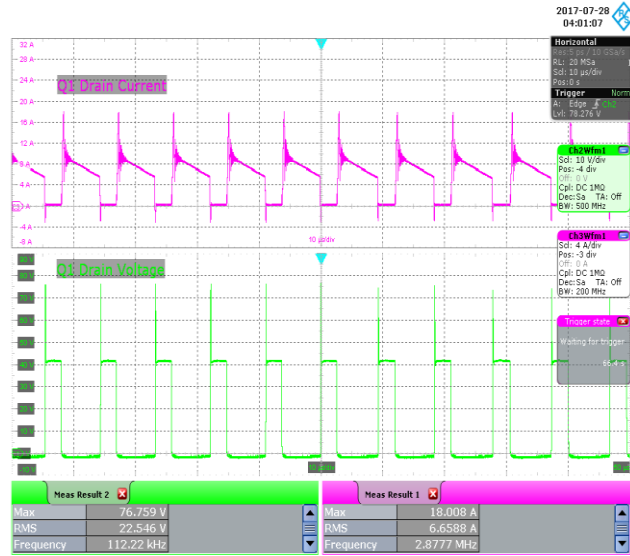


Figure 98 – 140 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 10 V / div.
 Horizontal: 10 μs / div.

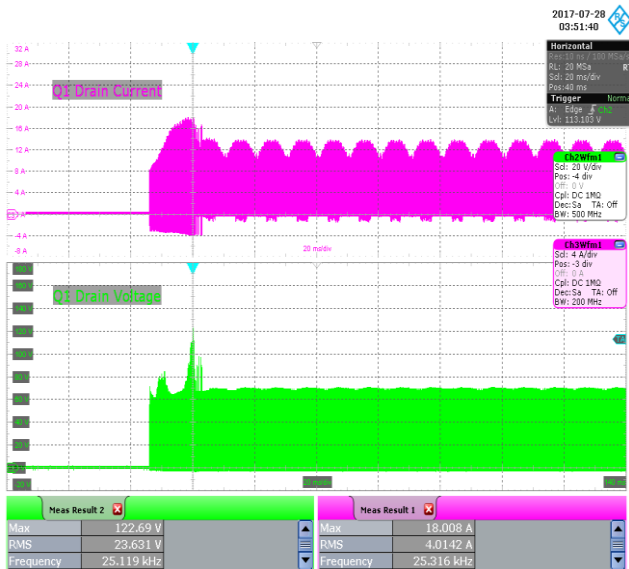


Figure 99 – 230 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 20 V / div.
 Horizontal: 20 ms / div.

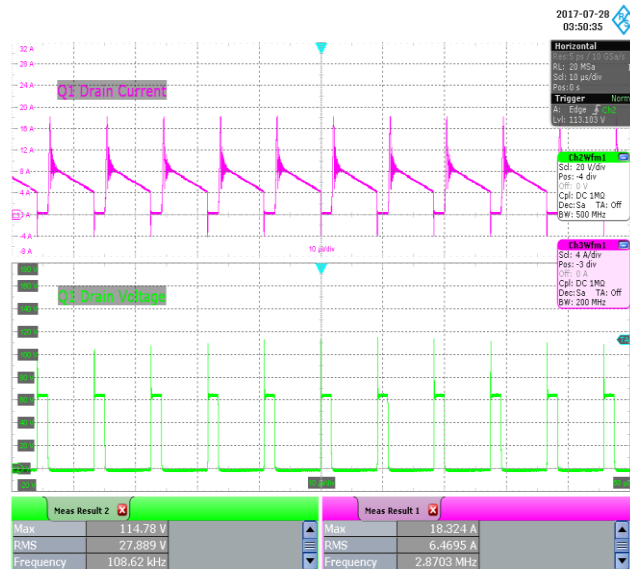


Figure 100 – 230 VAC 50 Hz, 2.92 A CC Load.
 Upper: 4 A / div.
 Lower: 20 V / div.
 Horizontal: 10 μs / div.

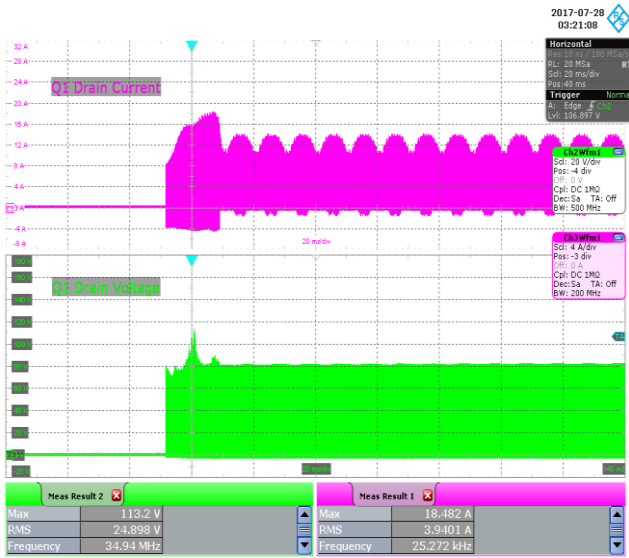


Figure 101 – 277 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 20 ms / div.

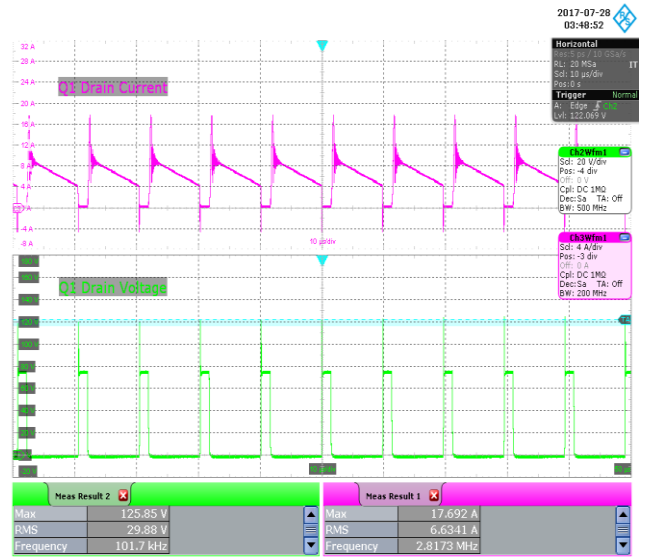


Figure 102 – 140 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 10 μs / div.

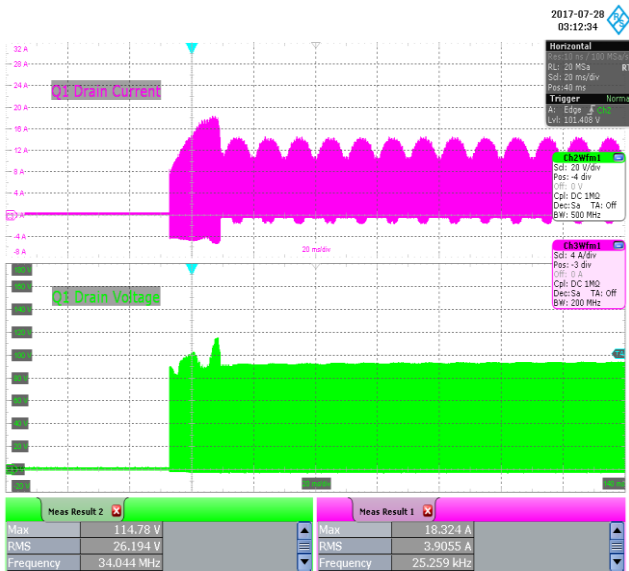


Figure 103 – 320 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 20 ms / div.

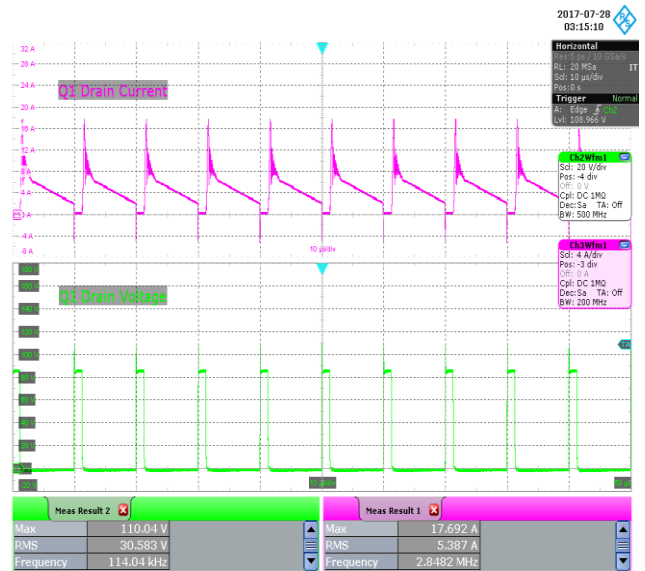


Figure 104 – 320 VAC 50 Hz, 2.92 A CC Load.
Upper: 4 A / div.
Lower: 20 V / div.
Horizontal: 10 μs / div.



14.14 **Output Voltage Ripple**

Figure 105 – Probe Set-up for Output Voltage Ripple Test.

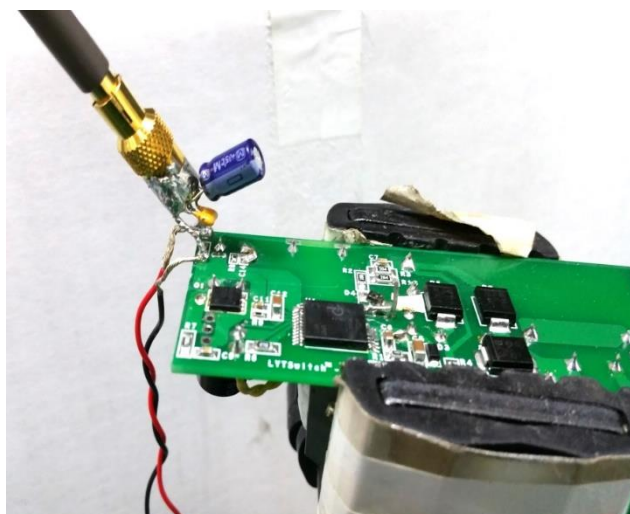


Figure 106 – Unit Set-up for Output Voltage Ripple Test.

Ripple voltage was taken using a X1 probe with 47 μF electrolytic capacitor and 0.1 μF ceramic capacitor connected in parallel across the probe.

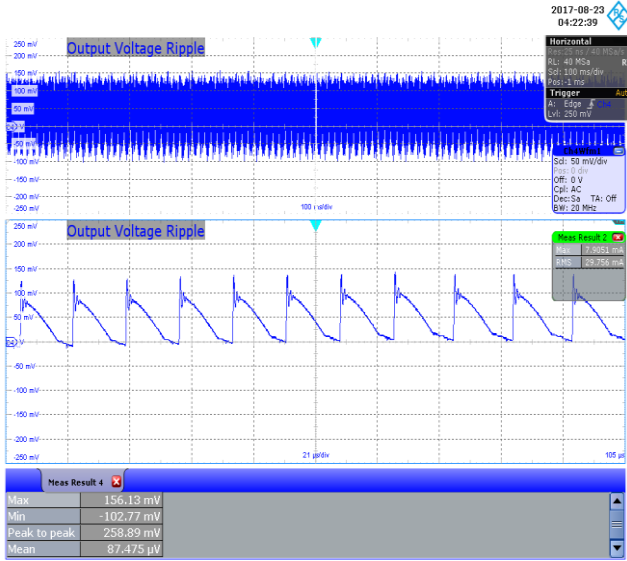


Figure 107 – 140 VAC 50 Hz, 2.92 A CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 50 mV / div., 100 ms / div.
Ripple Voltage: 258.89 mV_{PK-PK}.

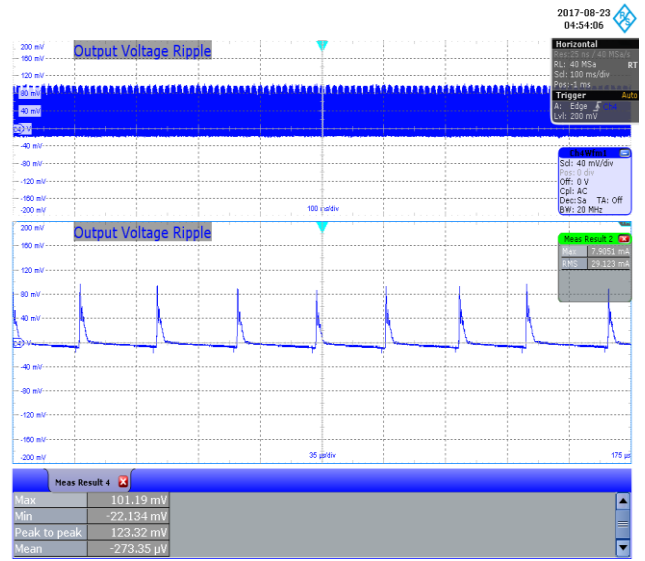


Figure 108 – 140 VAC 50 Hz, 300 mA CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 40 mV / div., 100 ms / div.
Ripple Voltage: 123.32 mV_{PK-PK}.

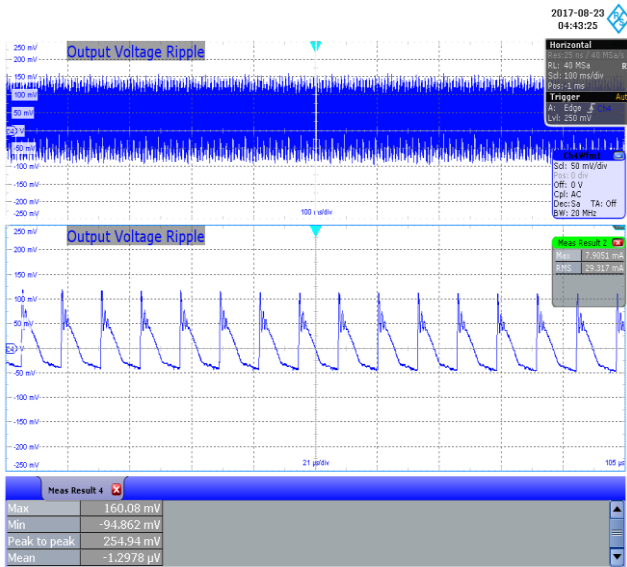


Figure 109 – 230 VAC 50 Hz, 2.92 A CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 50 mV / div., 100 ms / div.
Ripple Voltage: 254.94 mV_{PK-PK}.

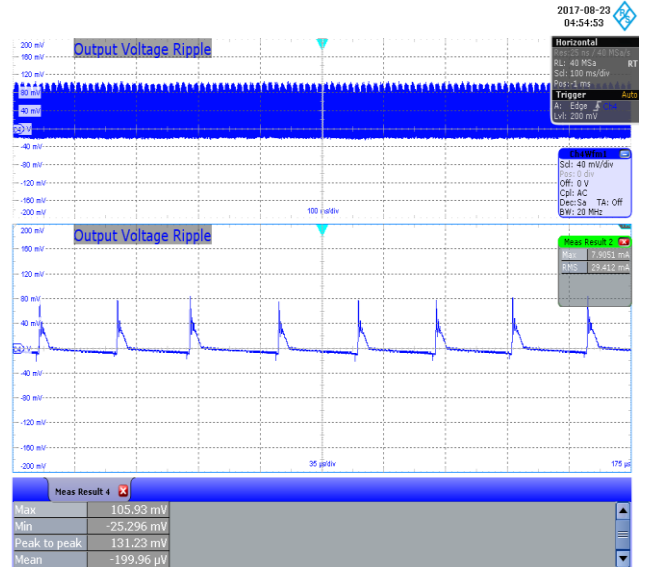


Figure 110 – 230 VAC 50 Hz, 300 mA CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 40 mV / div., 100 ms / div.
Ripple Voltage: 131.23 mV_{PK-PK}.



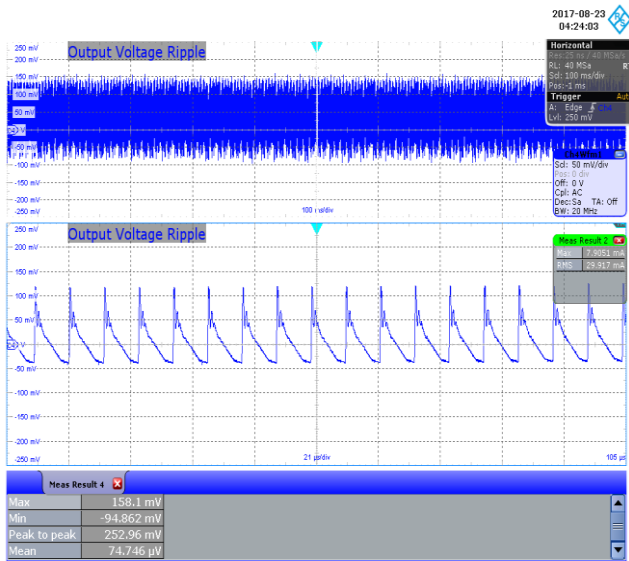


Figure 111 – 277 VAC 50 Hz, 2.92 A CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 50 mV / div., 100 ms / div.
Ripple Voltage: 252.96 mV_{PK-PK}.

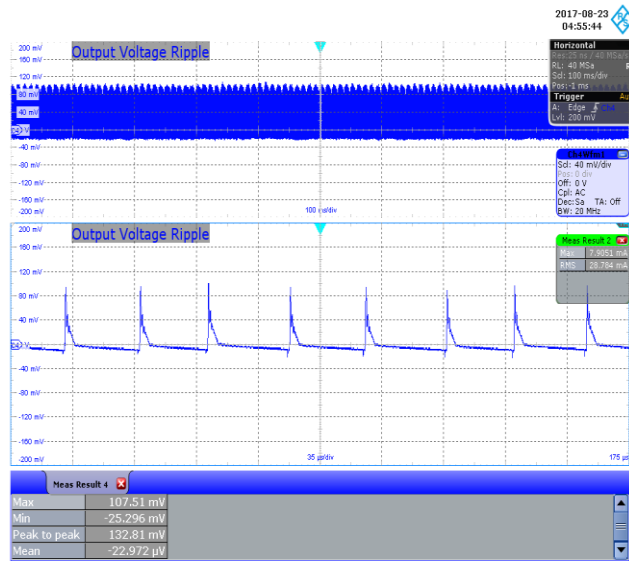


Figure 112 – 140 VAC 50 Hz, 300 mA CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 40 mV / div., 100 ms / div.
Ripple Voltage: 132.81 mV_{PK-PK}.

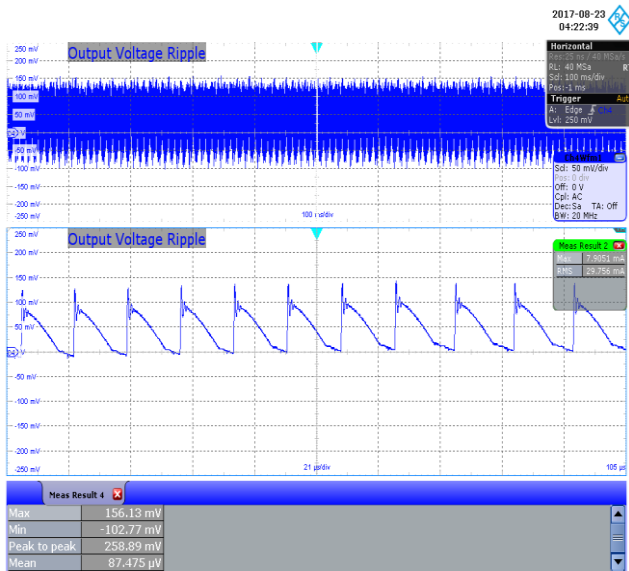


Figure 113 – 320 VAC 50 Hz, 2.92 A CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 50 mV / div., 100 ms / div.
Ripple Voltage: 258.89 mV_{PK-PK}.

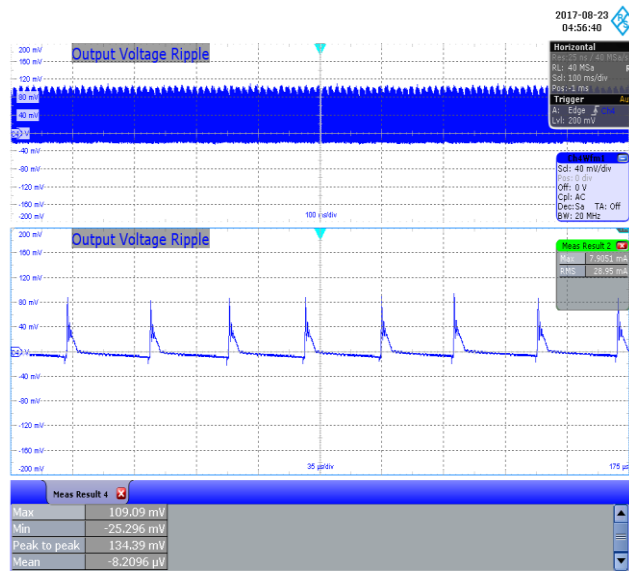


Figure 114 – 320 VAC 50 Hz, 300 mA CC Load.
AC Coupling, 20 MHz Bandwidth
 V_{OUT} , 40 mV / div., 100 ms / div.
Ripple Voltage: 134.39 mV_{PK-PK}.

14.15 **Output Current Ripple**

14.15.1 Equipment Used

1. Rohde & Schwarz RTO1004 Oscilloscope
2. Rohde & Schwarz RT-ZC20 Current Probe
3. Keysight 6812B AC Power Source / Analyzer
4. 12 V LED Load

14.15.2 Ripple Ratio and Flicker % Measurement

| V_{IN} (VAC) | I_{OUT(MAX)} (mA) | I_{OUT(MIN)} (mA) | I_{MEAN} (mA) | Ripple Ratio (I_{RP-P}/I_{MEAN}) | % Flicker 100 x (I_{RP-P} / I_{O(MAX)}+I_{O(MIN)}) |
|---------------------------------------|--|--|--|---|---|
| 140 | 3030.8 | 2801.6 | 2923.9 | 0.08 | 3.93 |
| 230 | 3026.9 | 2793.7 | 2927 | 0.08 | 4.01 |
| 277 | 3030.8 | 2793.7 | 2928.8 | 0.08 | 4.07 |
| 320 | 3038.7 | 2789.7 | 2932.7 | 0.08 | 4.27 |

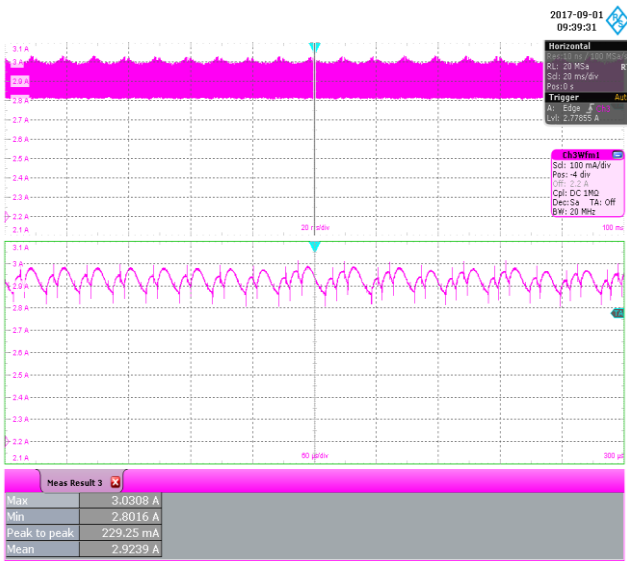


Figure 115 – 140 VAC 50 Hz, 2.98 A LED Load.
 20 MHz Bandwidth
 I_{OUT} , 100 mA / div., 20 ms / div.
 Ripple Current: 229.25 mA_{PK-PK}.

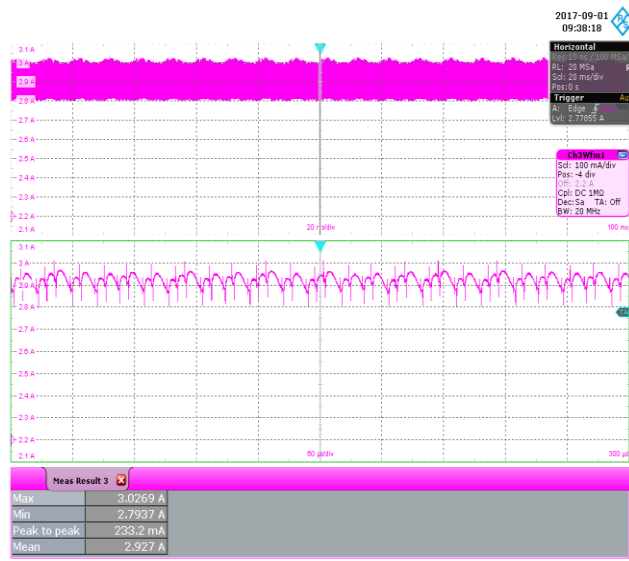


Figure 116 – 230 VAC 50 Hz, 2.98 A LED Load.
 20 MHz Bandwidth
 I_{OUT} , 100 mA / div., 20 ms / div.
 Ripple Current: 233.2 mA_{PK-PK}.

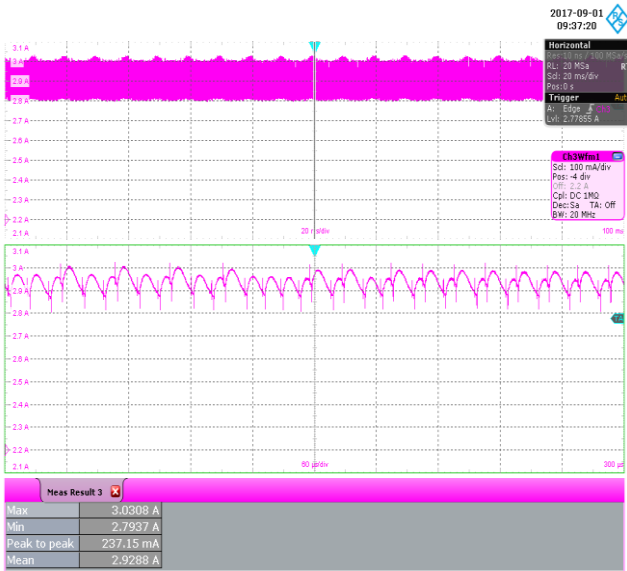


Figure 117 – 277 VAC 50 Hz, 2.98 A LED Load.
 20 MHz Bandwidth
 I_{OUT} , 100 mA / div., 20 ms / div.
 Ripple Current: 237.15 mA_{PK-PK}.

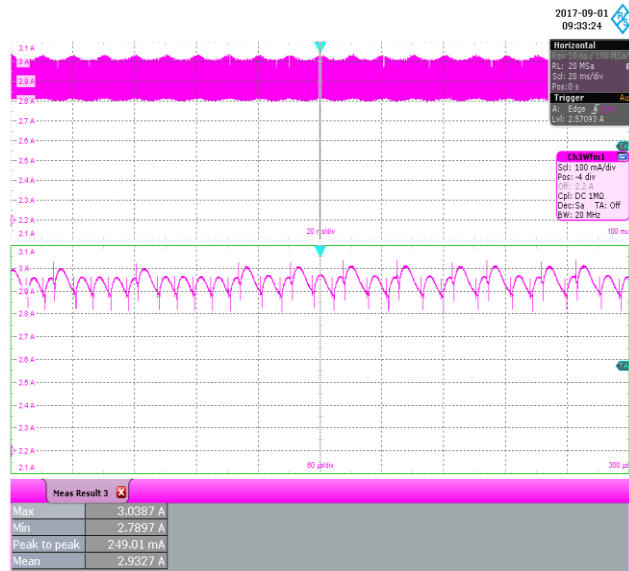


Figure 118 – 320 VAC 50 Hz, 2.98 A LED Load.
 20 MHz Bandwidth
 I_{OUT} , 100 mA / div., 20 ms / div.
 Ripple Voltage: 249.01 mA_{PK-PK}.

15 Conducted EMI

15.1 *Test Set-up*

15.1.1 Equipment and Load Used

1. Rohde and Schwarz ENV216 two line V-network
2. Rohde and Schwarz ESRP EMI test receiver
3. Hioki 3332 power hitester
4. Chroma Measurement Test Fixture model A662003
5. Resistive Load (set at Full Load)
6. HOSSONI TDGC2 VARIAC set at 230 VAC 60 Hz

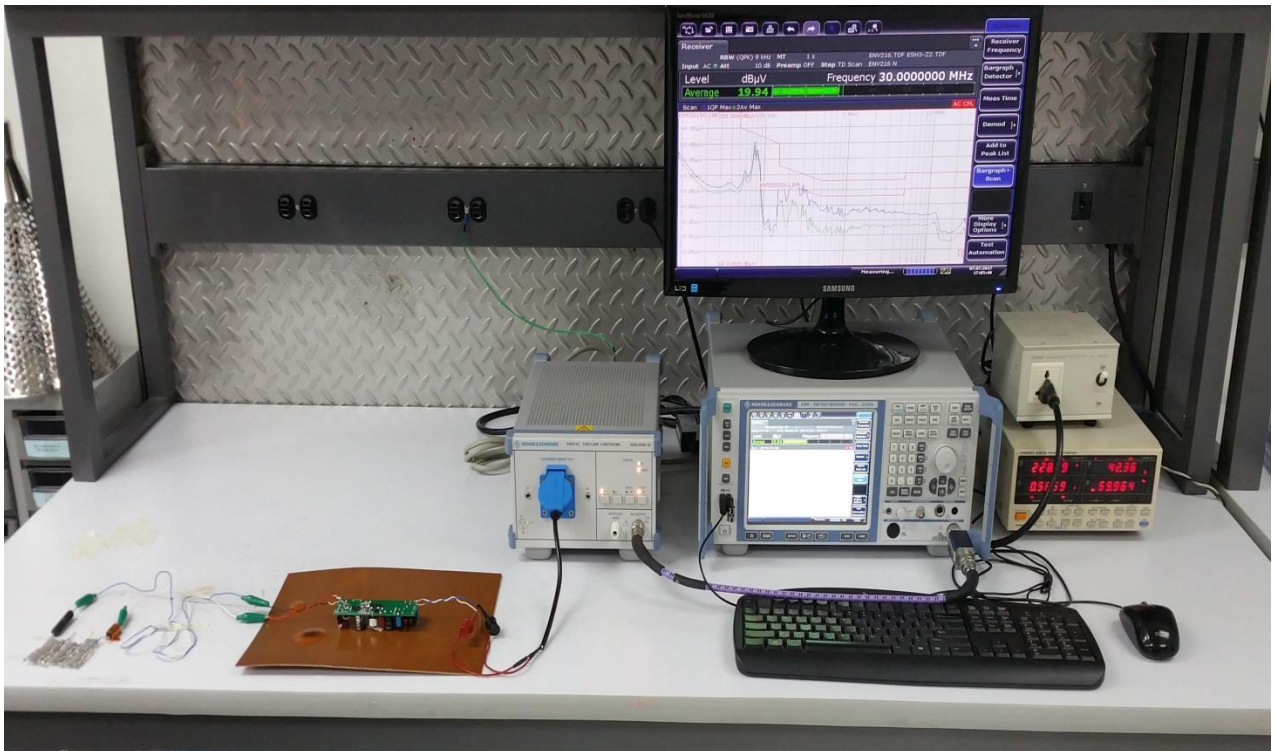
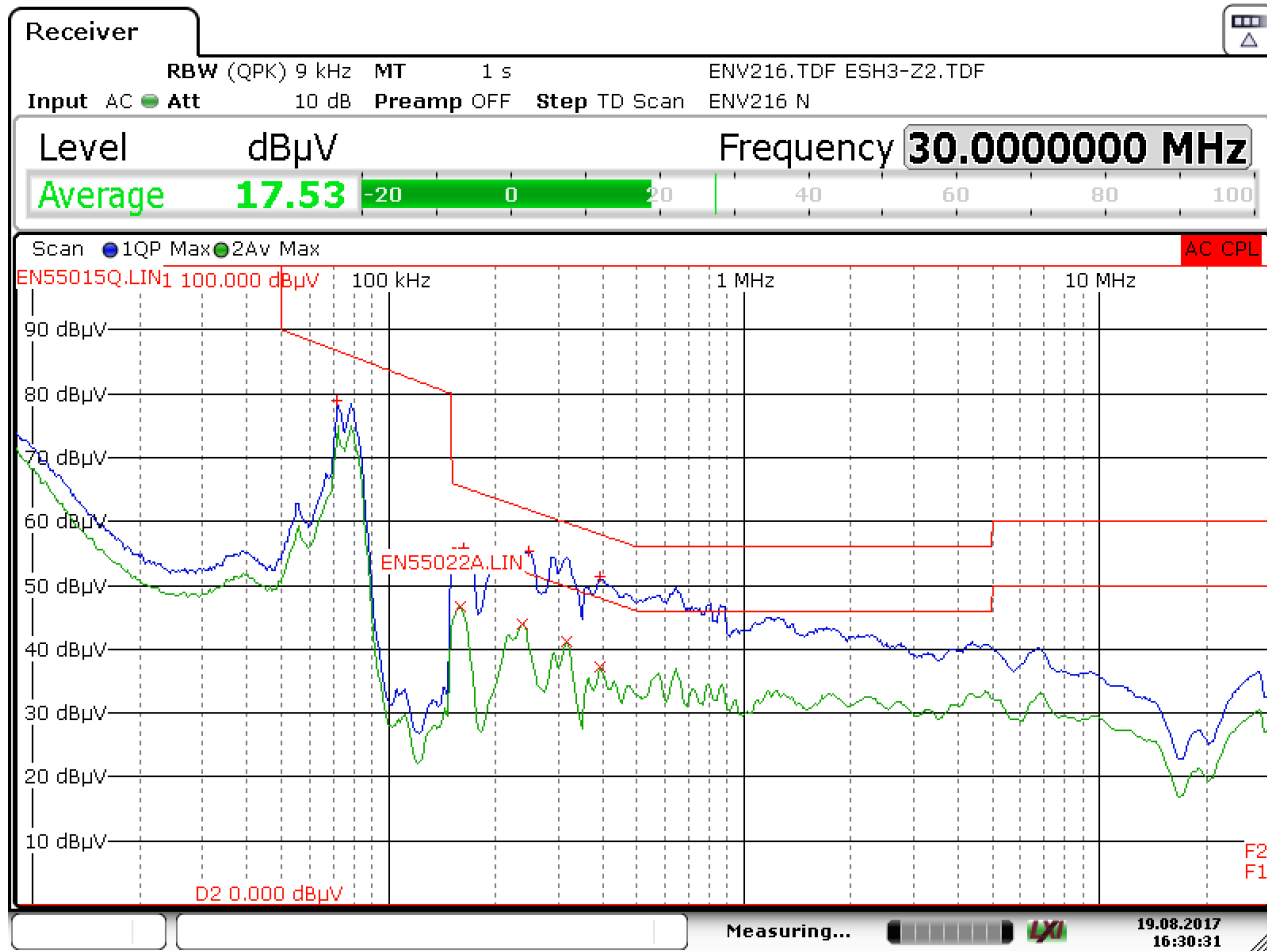


Figure 119 – Conducted EMI Test Set-up.

15.2 EMI Test Result



Date: 19.AUG.2017 16:30:31

Figure 120 – Conducted EMI QP Scan at Full Load, 230 VAC 60 Hz and EN55015 B Limits.

| Trace1: EN55015Q.LIN | | Trace2: EN55022A.LIN | |
|----------------------|--------------|----------------------|------------|
| Trace/Detector | Frequency | Level dB μ V | DeltaLimit |
| 1 Quasi Peak | 249.0000 kHz | 55.35 L1 | -6.44 dB |
| 1 Quasi Peak | 395.2500 kHz | 51.29 L1 | -6.66 dB |
| 1 Quasi Peak | 71.9500 kHz | 78.85 L1 | -7.84 dB |
| 2 Average | 237.7500 kHz | 43.93 N | -8.24 dB |
| 2 Average | 316.5000 kHz | 41.24 N | -8.56 dB |
| 2 Average | 159.0000 kHz | 46.61 L1 | -8.91 dB |
| 1 Quasi Peak | 163.5000 kHz | 55.79 L1 | -9.49 dB |
| 2 Average | 395.2500 kHz | 37.19 N | -10.76 dB |

Figure 121 – Conducted EMI Data at 230 VAC 60 Hz, Full Load

16 Line Surge

The unit was subjected to ± 2500 V, 100 kHz ring wave and ± 1000 V differential surge using 10 strikes at each condition. A test failure was defined as a non-recoverable interruption of output requiring repair or recycling of input voltage.

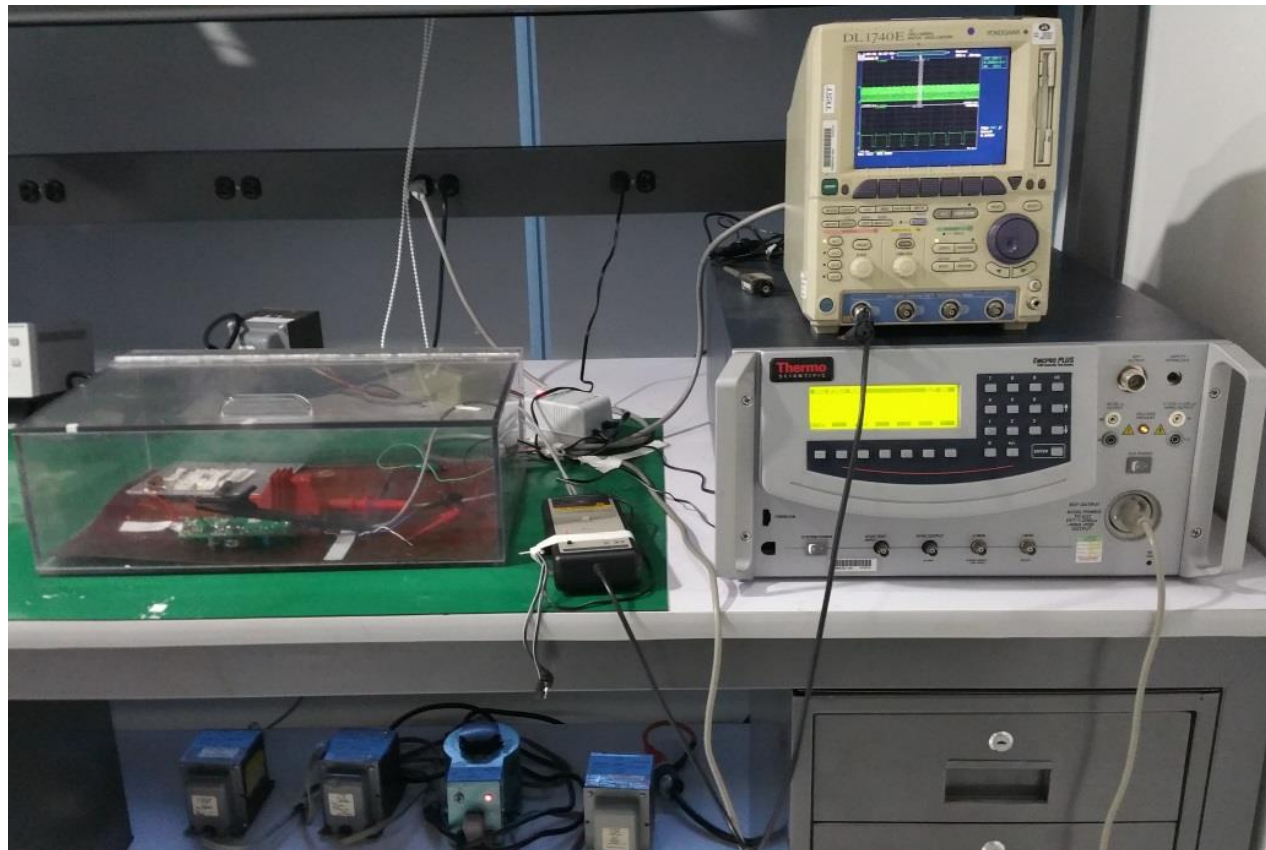


Figure 122 – Test Set-up for Line Surge Test.

16.1 **Differential Surge Test Results**

| Surge Level (V) | Input Voltage (VAC) | Injection Location | Injection Phase (°) | Test Result (Pass/Fail) |
|-----------------|---------------------|--------------------|---------------------|-------------------------|
| +1000 | 230 | L to N | 0 | Pass |
| -1000 | 230 | L to N | 0 | Pass |
| +1000 | 230 | L to N | 90 | Pass |
| -1000 | 230 | L to N | 90 | Pass |
| +1000 | 230 | L to N | 270 | Pass |
| -1000 | 230 | L to N | 270 | Pass |
| +1000 | 277 | L to N | 0 | Pass |
| -1000 | 277 | L to N | 0 | Pass |
| +1000 | 277 | L to N | 90 | Pass |
| -1000 | 277 | L to N | 90 | Pass |
| +1000 | 277 | L to N | 270 | Pass |
| -1000 | 277 | L to N | 270 | Pass |

16.2 **Ring Wave Surge Test Results**

| Surge Level (V) | Input Voltage (VAC) | Injection Location | Injection Phase (°) | Test Result (Pass/Fail) |
|-----------------|---------------------|--------------------|---------------------|-------------------------|
| +2500 | 230 | L to N | 0 | Pass |
| -2500 | 230 | L to N | 0 | Pass |
| +2500 | 230 | L to N | 90 | Pass |
| -2500 | 230 | L to N | 90 | Pass |
| +2500 | 230 | L to N | 270 | Pass |
| -2500 | 230 | L to N | 270 | Pass |
| +2500 | 277 | L to N | 0 | Pass |
| -2500 | 277 | L to N | 0 | Pass |
| +2500 | 277 | L to N | 90 | Pass |
| -2500 | 277 | L to N | 90 | Pass |
| +2500 | 277 | L to N | 270 | Pass |
| -2500 | 277 | L to N | 270 | Pass |

16.3 1 kV Differential Surge Test

The Drain voltage of U1-LYTSwitch-6 was measured during 1 kV differential surge test.



Figure 123 – (+)1 kV Differential Surge.
 90° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 595.833 V.

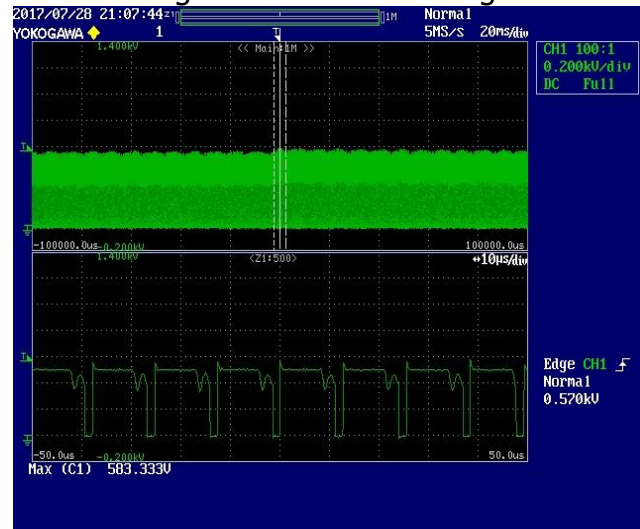


Figure 124 – (-)1 kV Differential Surge.
 90° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 583.333 V.

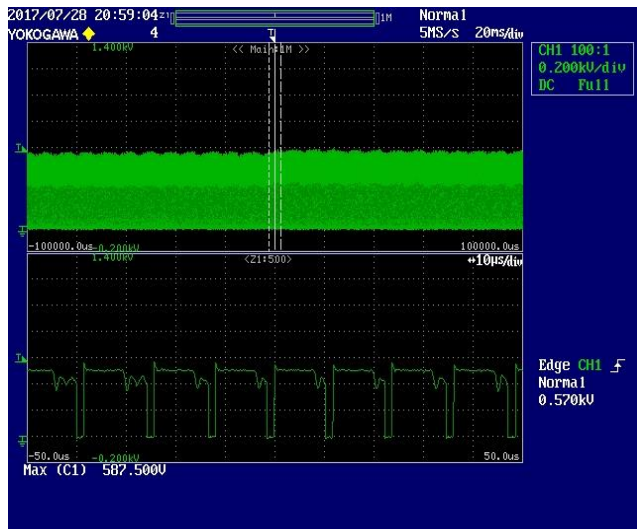


Figure 125 – (+)1 kV Differential Surge.
 270° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 587.5 V.

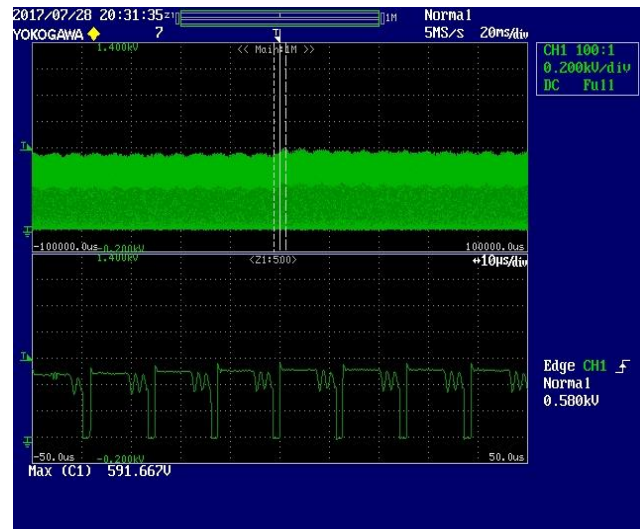


Figure 126 – (-)1 kV Differential Surge.
 270° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 591.667 V.

16.4 2.5 kV Ring Wave Surge Test

The Drain voltage of U1-LYTSwitch-6 was measured during 2 kV ring wave surge test.

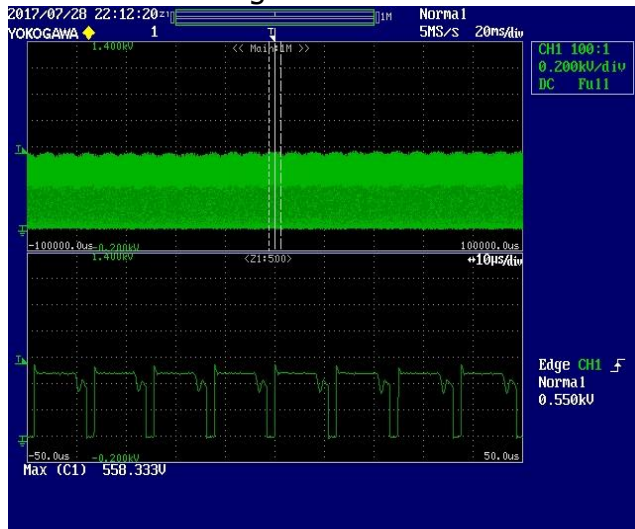


Figure 127 – (+) 2.5 kV Ring Wave Surge.
 90° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 558.333 V.

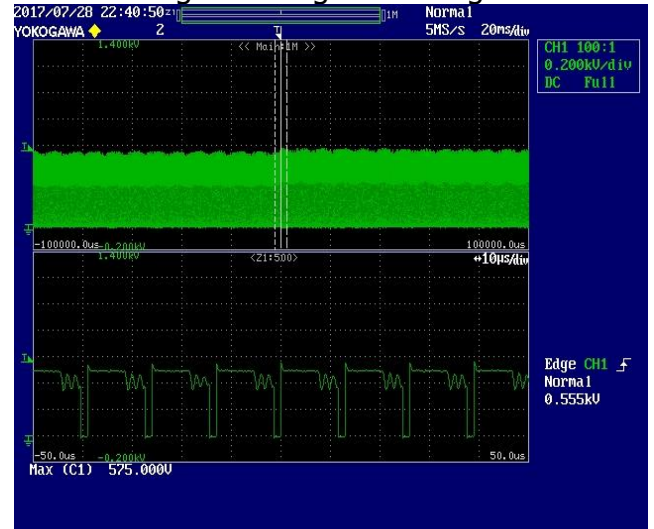


Figure 128 – (-) 2.5 kV Ring Wave Surge.
 90° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 575.0 V.

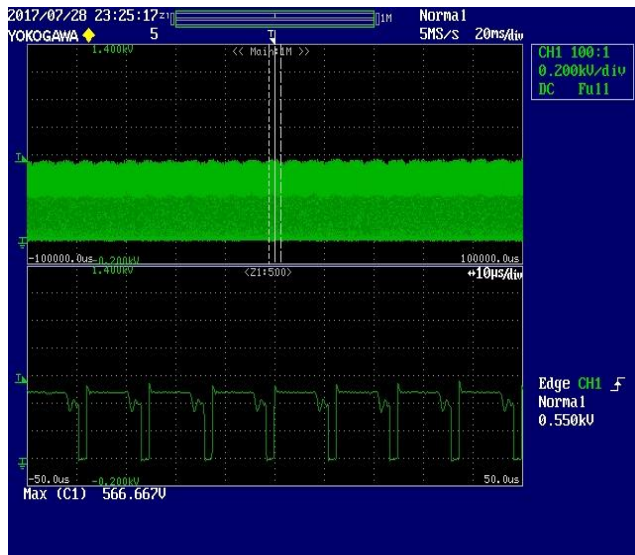


Figure 129 – (+) 2.5 kV Ring Wave Surge.
 270° Phase Angle, Input: 277 VAC.
 V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 566.667 V.

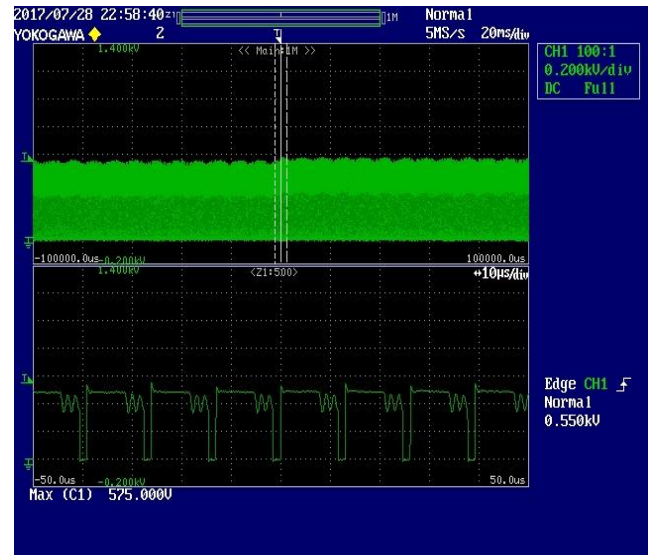


Figure 130 – (-) 2.5 kV Ring Wave Surge.
 270° Phase Angle, Input: 277 VAC.
 Lower: V_{DRAIN} , 200 V / div., 20 ms / div.
 Peak V_{DRAIN} : 575.0 V.



17 Brown-in / Brown-out Test

No abnormal overheating and nor voltage overshoot / undershoot was observed during and after 0.5 V / s brown-in and brown-out test.

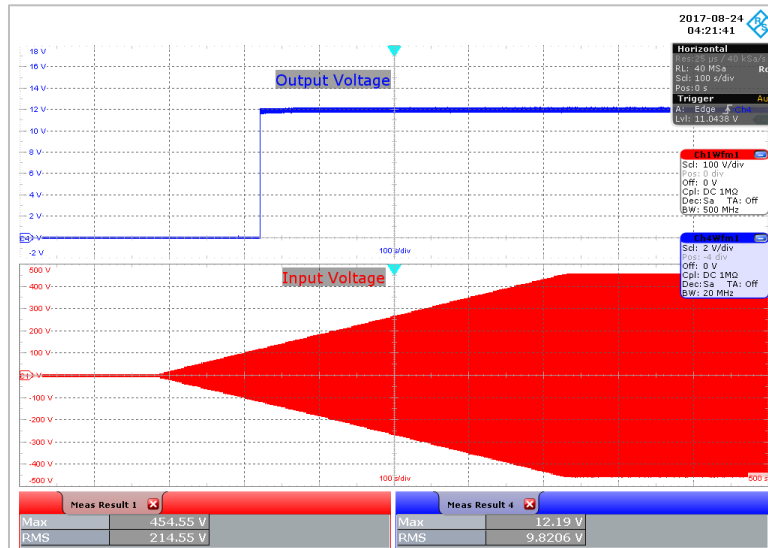


Figure 131 – Brown-in Test at 0.5 V / s.
 Time Scale: 100 s / div.
 Ch1: V_{OUT} , 2 V / div.
 Ch2: V_{IN} , 100 V / div.

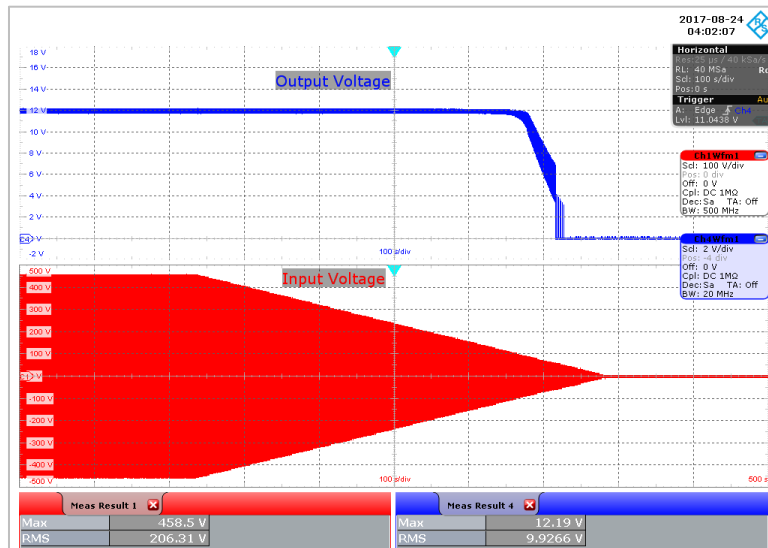


Figure 132 – Brown-out Test at 0.5 V / s.
 Time Scale: 100 s / div.
 Ch1: V_{OUT} , 2 V / div.
 Ch2: V_{IN} , 100 V / div.

18 Revision History

| Date | Author | Revision | Description and Changes | Reviewed |
|-----------|--------|----------|--|-------------|
| 23-Jan-18 | EDdL | 1.0 | Initial Release. | Apps & Mktg |
| 16-Feb-18 | EDdL | 1.1 | Minor Text Updates. PCB Images Updated. | |
| 21-Feb-18 | EDdl | 1.2 | Added PIXls Spreadsheet. | |
| 26-Mar-18 | EDdl | 1.3 | Updated Power Supply Specification, Section 2.0. | |
| 23-Apr-18 | KCM | 1.4 | Updated Figure 4 Schematic. | |

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